

LIQUID CRYSTAL FLAT PANEL DISPLAYS

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# LIQUID CRYSTAL FLAT PANEL DISPLAYS

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### WILLIAM C. O'MARA



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### INTRODUCTION

We live in the silicon age, and the quintessential item that defines our world is the computer. Silicon chips power the computer as well as many other products for work and leisure, such as calculators, radios, and televisions. In the forty years since the transistor was invented, the solid state revolution has affected the lives of almost everyone in the world. Based on silicon, solid state devices and integrated circuits have revolutionized electronics, data processing, communications, and the like. The computer, especially the personal computer, would be impossible without silicon devices. Only one computer was ever built using vacuum tubes, and the tubes had to be constantly replaced because they generated too much heat and burned out. Silicon devices allowed for reliable switching operations in arrays of hundreds and thousands of discrete devices. As a result, the very substantial industrial base that existed for producing vacuum tubes disappeared - with one exception. That exception is, of course, the CRT, which is evident in televisions, computer displays, and a host of other information display terminals. Until recently, there was nothing that could take its place, and it seemed that the CRT would remain as the electronic medium for all except the simplest displays.

The CRT is about to go the way of the other vacuum tubes. It's dead, but doesn't know it yet. Just like the transistor revolution, it will be a few decades before you need to go to a museum to see this other kind of vacuum tube, but the end is coming. The instrument of the CRT's demise is again the silicon transistor, in a new, thin film form. In this form, thousands of transistors can act as a switch array for liquid crystal displays, LCDs, providing picture quality equal to that of the CRT. Liquid crystal displays have been with us for more than 20 years, for watches, calculators, and other small displays. But the technology for large displays with high information content is quite recent. There are various kinds of display technologies besides LCDs, and various kinds of switching schemes besides the silicon transistor. However, this combination of liquid crystal and thin film transistor, termed active matrix liquid crystal displays for computer and other applications.

The silicon materials technology for the AMLCD thin film transistor actually had its beginnings in the solar cell investigations of 1975-1980. While the US and

#### INTRODUCTION

### LIQUID CRYSTAL FLAT PANEL DISPLAYS

Europe poured millions of dollars into crystalline silicon for solar cells, the Japanese developed amorphous silicon deposited by chemical vapor deposition. While the US sponsors of solar research thought about paving Arizona with solar cells for power generation, the Japanese made small cells, put them in calculators, and threw away the wet-cell battery. That same silicon technology is now used for thin film silicon transistors, hundreds of thousands on a glass plate, that replace the scanning electron beam of the CRT.

This book describes the construction, operation, and manufacturing of flat panel displays, emphasizing the AMLCD type. Many of the manufacturing processes are akin to integrated circuit processes, and will be familiar to IC process engineers. These are described in some detail as well as the other operations for display manufacturing. Emphasis is on current manufacturing practice and trends in manufacturing that will impact the equipment and materials. Separate chapters are devoted to the manufacturing equipment and to the materials.

This book concentrates on large liquid crystal displays to the exclusion of other types. These other types include electroluminescent displays, plasma displays, vacuum fluorescent displays and electrochromic displays. Their manufacturing technologies and applications are certainly interesting, but someone else will have to do them justice. In terms of their applications, these latter displays are mainly for niche applications. The LCD display is the mainstream.

The emerging AMLCD industry has the look of inevitability about it, something that is going to happen sooner or later. Of course, lots of people are going to speed lots of time, money and brainpower making it happen. Some of us worry that the engineering and manufacturing won't happen in the US, and therefore won't provide jobs for those of us who are looking for work. Unfortunately, it isn't clear how to correct this situation, or even that things would be much better if it could be corrected. Hopefully, motivated people and organizations will find useful information here if they do decide to build a factory.

What is striking about the new technology is how nicely it fits the bill for the next advance in computing, the portable, and assists in the proliferation of that device. Probably we need more computers and other electronic devices, and we do love our gadgets. But, in the end, what we seem to be pointed towards is just more and different and better kinds of television. Is this progress?

#### INTRODUCTION

### LIQUID CRYSTAL FLAT PANEL DISPLAYS

It is a pleasure to acknowledge the assistance of many of the people at the Semiconductor Equipment and Materials International (SEMI) trade organization in gathering the data for this book. In particular, the people who assisted in every way during my three month stay in the SEMI office in Tokyo, Japan, were very helpful. These include George Moore, Steve Nakayama, Yoshi Kohuo and many others. It was a pleasure to work in their company.

Palo Alto, California

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### LARGE AREA LIQUID CRYSTAL DISPLAYS

## 1.0

Liquid crystal displays (LCDs) have been commercially available for more than 20 years, but until recently have been restricted to relatively small size. Such displays are ubiquitous in watches, calculators, radios, and other products requiring indicators and three or four alphanumeric characters. Recently, improvements in the liquid crystal materials have occurred, allowing large displays to be manufactured. These have achieved widespread acceptance in portable computers, very light laptop computers, and dedicated word processors. Other products include flat screen and projection television systems. Additional improvements in the technology have led to full color displays, now entering production. These improvements include the addition of an active switch to control the action of the liquid crystal at each picture element or pixel. The active switch can be a thin film diode or a thin film transistor, and, for large displays, the number of active elements approaches the number of transistors in a dynamic memory.

This chapter describes some of the new display products, and provides a description of the basic technology involved. Computer displays seem to be the most important single product category at the moment, in terms of projected manufacturing volume. The portability of laptop and notebook computers has created what is in effect a new tool. The true power of computing is just beginning to be realized, now that it is portable. Initially a highly legible portable display was possible only with plasma discharge, which glowed a characteristic orange color. In addition, yellow electroluminescent displays can be built with adequately low power consumption. However, a true black and white display, not to mention full color, is unavailable with these technologies. NEC, one of the pioneers of plasma discharge technology, has closed its manufacturing line. In Japan, only Sharp maintains a small electroluminescent display manufacturing capability. Liquid crystal displays satisfy both the technical and economic requirements for this new era of computing.

This is not to imply that liquid crystal displays are without their problems. The low power black and white displays must be made to exacting tolerances. Adding a color filter array and an active matrix of hundreds of thousands of pixels creates a manufacturing nightmare. The complexity of such displays negates the low power consumption inherent in the technology. For example, the transmission

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of light by a full color display may be less than 5%. The bright backlight required for illumination and the power required to operate the active matrix switches limit battery life in a portable computer to less than 30 minutes.

In spite of this, the technology brings computing power to the point of use. Especially combined with the pen or stylus computer for filling in forms, the display becomes a natural and essential component of "computerless computing". This comes close to freeing the user from the complexities of the computer, making it almost as easy to use as a telephone or other artifact of modern life. The computing power of portable instruments is great enough that almost any "desktop" task can be accomplished, including, for example, the writing of this document.

In the end, the full color active matrix liquid crystal display spells the end of the cathode ray tube, known affectionately as the CRT. For the laptop is only the beginning. A true laptop was really impossible with a CRT display in the first place. The analogy between the LCD display and the transistor is interesting here. The first "shirtpocket" portable radio was introduced in the mid 1950s using germanium transistors instead of vacuum tubes. A true "shirtpocket" radio would have been impossible with tubes. At the time, a table model tube radio sold for about \$15, but the transistor radio sold for \$65, quite a premium. Although pundits may have predicted a peaceful coexistence of transistor and tube, within thirty years, vacuum tubes had become a curiosity - except for the display.

Just like the transistor, the liquid crystal display is going to move onto the table top. It is going to take thirty years, but it <u>is</u> going to happen. All the reasons given for the continued peaceful coexistence of CRTs and LCDs ignore the history of solid state devices, especially if the active device is made of silicon. Germanium transistors are almost as hard to find today as vacuum tubes. They were quickly displaced by those made of silicon, with superior performance. Until silicon devices were available, the high reliability we associate with solid state components was unknown. Today, the liquid crystal display is in the "germanium" phase of development. The first silicon-based displays are just emerging from prototype manufacturing lines. Once these reach high volume, competitive cost with CRTs is inevitable. Whether the devices turn out to be thin film amorphous silicon or polysilicon remains to be seen. However, the outcome is no longer in doubt, the CRT is finished. Just like the rest of electronics, a law of Nature is at work here. *IF IT CAN BE DONE IN SILICON, IT* **WILL** *BE DONE IN SILICON*.

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### **Computer Displays**

### **1.1.1 DESKTOP COMPUTERS**

Computers have become more commonplace than typewriters, it seems. This has happened in less than 10 years, since the introduction of the Apple, then the IBM personal computer. Before this, computers were mysterious monsters tended by men in white coats, the men constantly spooling huge rolls of magnetic tape onto tape drives, the only visible parts of the monster. Since then, we have come to terms with the idea of a computer on our desk, and have even learned to make use of it. For many, this has spelled the demise of the secretary, as they learned to prepare their own memos. Progress is never easy. The quality of the display lagged behind the capability of the computer for a long time. IBM's decision to provide us with either green or amber-colored monitors made the box uglier and more forbidding than it had to be. For all the talk about the Macintosh computer's "intuitive" interface, it may be simply that the screen showed black letters on a white background, more or less like a piece of paper. It was only with the advent of a full color EGA display for the IBM three or four years ago that the same black and white display was possible for the more common IBM PC and clones.

The representation of things more or less the way we are used to seeing them is very important to ready acceptance of a new technology. Liquid crystal displays, with the new black on white representation of the last few years, have achieved the status of the ordinary, thereby guaranteeing their acceptance.

### **1.1.2 PORTABLE COMPUTERS**

Figure 1-1 shows the portable and laptop style computers familiar to most of us. The attraction of the portable computer is its battery operation, which means that it is available at any place, at any time. Technical developments have allowed the computing power of portables to increase dramatically. These include the low power 386 microprocessor chip, small hard disk drives, and the LCD VGA screen. Many lightweight portables are available at a weight of 7 pounds or less.

Figure 1-1 Portable and laptop computers.

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Approximately 650 types of portable computers are available, divided into desktops, laptops, and ultralight, specialized portables. Table 1-1 shows some of the features of these computers.

	Transportable	Laptop	Specialized
Weight	20-30 lbs	5-12 lbs	<5 lbs
CPU	386	80286/386SX	8088
Hard Disk	120MB	40MB	RAM Disk
Application	Full PC	Selected PC	Resident software,
Display	Plasma, Color LCD	B/W LCD backlit	B/W LCD
% w/ LCD Display	50%	80%	100%

**Table 1-1** Classification of Portable Computers

The "transportable" computers are heavy enough that moving them is not an easy task. However, they constitute a desktop system that has all the capabilities of the heavier fixed computing systems. They may allow battery operation, but are more typically used in satellite offices where power is available. Still, these computers typically have some kind of flat screen display, to make transporting them possible at all.

The laptop variety has many of the capabilities of the desktop, but some compromises have been made to minimize weight. The compromises are growing smaller in number each year, as high speed microprocessors, high capacity hard disks, and high information content displays become available.

The specialized computer is the truly innovative class of computer, and represents a revolution all by itself. Rather than try to do everything, this computer does only one thing well. It keeps schedules, it does simple word processing, it acts as a dictionary or translator. Computing has become cheap enough to allow single purpose machines. Now display technology is beginning to match the price of the integrated circuit chips.

Figure 1-2 shows the trends in active matrix liquid crystal display screen size during the last few years. A five year forecast of these trends is also shown on the

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chart. The active matrix is the array of transistors or other switches used to make the displays perform to their true capabilities. The details of the technology are explained further on.

Figure 1-2 Active matrix liquid crystal display screen size in recent years



**DISPLAY DIAGONAL (inch)** 

The figure shows that it is only in the last year or two that active matrix displays have reached a size suitable for computer use. Prior to 1990, the screen size was limited to portable TVs of 3-inch, 4-inch, and so on. The active matrix display size is increasing, at least to 14-15-inch diagonal size. Beyond this lie barriers that can be crossed only with very new and different technology. But for now, the way to 10-inch diagonal, full color, medium resolution computer displays is clear. The next step will be the higher resolution appropriate to engineering workstations.

Notice that the dotted curves on this figure refer to the projection displays coming into production in Japan. The display is actually a light valve that controls the projected image, and is much smaller in dimensions than direct-view displays.

As the size of the display increases, so often does the complexity. Figure 1-3

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shows the relation between the number of pixels (picture elements) as a function of display diagonal size for different kinds of displays. Trend lines are indicated for projection devices, computer displays, and TVs. A pixel or picture element is an individual point on the display that can be turned on and off. The information content that can be represented by the display is a function of the number of pixels. The corresponding term for integrated circuits is the number of bits of information processed or stored. Just as we are leaving the 1 megabit memory chip era, on our way to the 4 megabit era, we are entering the 1 megabit display era, in terms of the number of pixels on a flat panel display. It may be that the learning experience of making a million devices at a time on a silicon wafer was necessary before it could be done for displays.



Figure 1-3 Pixel count versus display diagonal size for flat panels

One million pixels is just the threshold for high information content displays. Figure 1-4 shows that one million buys a full color VGA computer display, with 640 horizontal lines, 480 vertical lines, and three colors. Each dot is 0.3-0.36mm on a side, and has three color elements. The display is 10-inch diagonal size. If they were available, they would cost about \$5000-7000 each. The manufacturing of these displays, with all the relevant information about yields, costs, equipment and so forth, is the subject of this report.

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### **1.1.3 ENGINEERING WORKSTATIONS**

The more complex displays of the future are also shown in the illustration. These include the XGA display, and engineering workstations of increasing complexity. The dot pitch decreases to 0.21-0.27mm at the same time that diagonal size is increasing to 16-18 inches. Pixel count grows to 4 million for the most complex displays. It is only a matter of time. However, the timing, also discussed in detail here, is a matter of intense speculation in the display community.

## **Figure 1-4** Number of pixels and display diagonal for high information content displays



### **1.1.4 COMPUTER DISPLAY SUMMARY**

Japanese suppliers are introducing many new full color displays each year. The actual volume of the displays is somewhat limited, as suppliers learn the ropes of high volume, high yield manufacturing. The complexity and display capabilities of these new products is impressive, and with improvements in manufacturing, the cost will soon be acceptable for standard computer products.

Table 1-2 shows examples of large size flat panel displays from various suppliers

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Firm	Size	Display Type	rows x columns x
	(inches)		colors / grey scale
NEC	9.3	TFT color LCD	640x400x8
Matsushita	9.8	STN color LCD	640x400x16
Seiko Epson	9.8	MIM color LCD	640x480x4096
Sharp	9.8	TFT color LCD	640x400x4096
Mitsubishi	10	TFT color LCD	640x480x4096
Kyocera	10.1	STN color LCD	640x480x16
Stanley	10.3	VTN color LCD	640x400x8
Hoshiden	10.4	TFT color LCD	640x808
Toshiba	10.4	STN color LCD	640x480x16
Seiko	10.4	STN color LCD	640x480x64
Sanyo	10.4	STN color LCD	640x480x64
Sanyo	10.4	TFT color LCD	640x480xfull color
Toshiba	10.4	TFT color LCD	640x480x512
Hitachi	10.4	TFT color LCD	640x480x4096
Sharp	10.4	TFT color LCD	640x480x16million
Hiroshima Opto	10.5	STN color LCD	640x480x8
Seiko Epson	11	STN color LCD	640x480x8
Casio	7	STN monochrome LCD	640x480x1
Seiko Electric	8.8	STN monochrome LCD	640x480x1/16
Citizen	9.4	STN monochrome LCD	640x480x1
Seiko Epson	9.8	STN monochrome LCD	640x480x1/8
Toshiba	10	STN monochrome LCD	640x400x1/16
Alps	10.1	STN monochrome LCD	640x400x1
Hitachi	10.3	TFT color LCD	1120x780x4096
Seiko Epson	13	MIM monochrome LCD	1280x800x1/16
Hoshiden	15	TFT color LCD	1280x800x4096

 Table 1-2 Japanese Large Flat Panel Displays

A lot of personal computers are sold each year. In 1988, total sales of 20 million units were valued at \$50 billion. This increased to 22 million units in 1989, and the share of portables increased from 10% to 14%. For 1990, the share of portables is estimated at 16%, growing to at least 25% in 1995. This represents a market of 8 to 9 million laptops. At least 75% of these will have LCD screens, or 8 million LCD laptops. It's going to be a big market.

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Other kinds of office equipment already incorporate liquid crystal displays, but the information content of these displays is much lower than for computers. Examples include facsimile machines, typewriters, copiers, telephones and telephone answering machines. One exception to the rule is overhead projector devices which are attached to a computer to provide sequential displays for presentations. Overall growth of displays amount to doubling in units every three or four years.

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### **Television Displays**

Small screen active matrix displays have been available in Japan for the last four or five years. They are not generally available in the rest of the world. The manufacture of these displays has provided some of the necessary experience for moving upward to the more complex displays for computers. New equipment has been developed to allow the processing of larger substrates. Small displays with high information content have been developed for the video camera display market, almost entirely a Japanese industry. Projection TV displays of impressive quality and screen dimensions are in initial production. Table 1-3 lists some of the current display products for home entertainment.

### **1.2.1 PORTABLE TVS**

Portable TVs amounted to 2 million units produced in 1989, and some Japanese forecasts predict a stagnant market for the next five years. Costs for TFT modules are still too high, and projection systems with three LCD modules are becoming available. The projection systems are the technical solution to HDTV as well. Japanese experts are predicting a total production of portable LCD-TVs of 2 million units, and a further 1.5-2 million VCR/LCD-TV systems (e.g., the Sony Watchman). LCD projection TV could reach 1 million units in 1995. Traditional TN units will more or less disappear, replaced by TFT displays. However, some manufacturers expect the simple matrix display to continue be used, at least for small displays.

An increase in screen size is predicted, from 3-4" diagonal in 1989, to 7" diagonal in 1995. Therefore, a doubling of the diagonal size over the five year period is expected, resulting in a market for displays amounting to 60,000m<sup>2</sup>. It remains to be seen whether large size (7-14" diagonal) TVs can be sold at an acceptable price. It is unclear what an acceptable price for such a TV would be. A potential competitor is the projection LCD TV.

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Firm	Size (inch)	Display Type	Comment
Seiko Epson	0.9	VCR color viewfinder	
Matsushita	1.06	VCR color viewfinder	90,000 pixels
NEC	2.6	Direct view TFT color LCD	Game
Pioneer	4	Direct view TFT color LCD	Car navigation
Hitachi	5	Direct view TFT color LCD	Car TV
Sharp	5.6	Direct view TFT color LCD	Car TV
Toshiba	43	Rear projection color LCD	230,000 pixels
Mitsubishi	48	Rear projection color LCD	345,000 pixels
Sharp	60	Projection TFT color LCD	1.2 million pixels
Sharp	110	Projection TFT color LCD	
Sanyo	110	Projection TFT color LCD	1.5 million pixels

 Table 1-3 Japanese LCD TV and VCR Displays

### **1.2.2 PROJECTION DISPLAYS**

Projection displays, which make use of three liquid crystal shutters to control each primary color, have been introduced in Japan. These shutters are up to 3-inch in size, and allow resolution of up to 1 million pixels per primary color. Limits on light transmission through the shutter limit image brightness, and the screen must be viewed in a partially darkened room. Images of up to 110 inch diagonal can be projected, and the picture quality far exceeds that of projection CRT devices. However, the home theater concept promoted by Sharp and other manufacturers of projection TVs has yet to be widely accepted. The price for projection LCD TVs in Japan is in the \$2,000-3,000 range and higher, which is too expensive for widespread replacement of traditional CRT models.

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### **1.2.3 HIGH DEFINITION TV**

High definition TV, with up to twice the picture elements of a standard broadcast screen, is available now with CRT technology and screen sizes up to 40 inches. Several broadcast systems have been proposed for HDTV in different parts of the world, and more than one will be adopted. The highly political issues for such systems aside, HDTV is likely to become the last hurrah for the CRT. The resolution required by the HDTV systems is already available on projection LCD-TVs, and the only requirement for large screen HDTV is higher brightness than is currently available. At 40 inch diagonal, the LCD projection system should be cost competitive with the CRT unit. There is research in Japan on manufacturing 40 inch direct view LCD panels. This research may eventually allow even larger direct view screen sizes. It is unlikely that CRT displays will exceed the 40 inch size.

### **1.2.4 VIDEO CAMERA VIEWFINDERS**

Video cameras have been limited to black and white viewfinders until the recent introduction of the full color, LCD viewfinder display. These displays will be required by the millions, replacing older style displays, but their small physical dimensions mean relatively small volume of substrate processed. These displays are usually built on quartz substrates, and can be made using semiconductor manufacturing equipment and processes.

### **Automotive Applications**

Automotive applications for displays include the radio, dashboard, and new product areas like on-board navigation systems and car-mounted TVs. Displays for car radios are moving to color LCDs. Although some increase in the size of the display allows for additional information about the type of program, these will remain relatively small.

The complexity of hardware and software is still a big obstacle for on-board navigation systems for cars. These systems allow constant reference to computerized maps and provide information about the car's location and destination. The first prototypes are now 10 years old, although many more modern systems are under development in Europe, in Japan (a government project with 50 manufacturers started in 1987), and in the USA. All leading manufacturers of car electronics have projects, but the market will be slow to emerge.

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Only a small number of car makers are presenting modern electronic dashboard versions at car exhibitions in Tokyo, Frankfurt, Geneva, etc. On the other hand, a partial LCD instrumentation type is beginning to establish itself, and it is possible that 50% of the higher priced models have some LCD displays. Full LCD dashboards are something else. Attractive models have recently been introduced by Fiat and Lancia, and development is underway in Norway, Germany, and France. Concept cars such as the Toyota FXV II, Ford HFX Aerostar, and VW Futura include modern versions of LCD displays.

The proportion of vehicles with a digital dashboard is much higher in the US than in Europe, which is again much higher than in Japan. A large percentage of American digital dashboards are based on vacuum florescent display (VFD) technology. There may be a large untapped market potential for automotive LCD applications, but the Japanese and German manufacturers already in the business seem placed to profit from this growth. These include Optrex, VDO, and Borg Instruments. In Japan, there are highly developed prototypes in all the major Japanese vehicle manufacturers, although actual sales are limited. A combination analog/digital dashboard may find a higher degree of consumer acceptance.

Another trend for automotive is away from TN towards more sophisticated STN technology for higher information content displays. TFT technology is waiting in the wings for highly complex navigation systems. Heads-up displays, in which information is projected onto the windshield, are not very advanced at the moment.



### **Other Applications**

Information boards are used in banking applications and for score boards in sports arenas. These command a relatively high price at the moment.

Polymer dispersed liquid crystal displays were first investigated by Fergason.[1] These are termed PDLC or NCAP films. The films are highly translucent and scattering in the off state, and transparent when an electric field is applied. They are the basis of light valves and displays up to 3mx1m in size. Drzaic and coworkers at Taliq described such displays on plastic substrates for curved, flexible displays[2]. Addition of a dichroic dye confers the property of electrically controlled absorbance as well as scattering. The response time of a few milliseconds makes possible displays that maintain slowly changing information such as

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timetables, scoreboards and so forth, but is currently too slow for multiplexing high frame rate information. Droplet size is about 1.6 $\mu$ m, and film thickness is 16 $\mu$ m. Voltages of 40-60V are required to operate the displays. To achieve high levels of multiplexing, improvements are needed in the uniformity of droplet size and shape, which would increase the sharpness of the electro-optic response curves.

Nippon Sheet Glass encapsulated small nematic liquid crystals in a polymer matrix, and sandwiched the film between a pair of glass plates for architectural glazing purposes[3]. A combined rear projection screen and light controlled window have been developed. Total transmission of light is >70%. High brightness is achieved for low birefringence,  $\Delta n$ =0.143. Droplet diameter affects projection screen brightness and viewing angle, Brightness decreases as diameter decreases from 4µm to 1µm, then increases again for diameter d=0.87µm. The small diameter droplet produced the largest viewing angle.

Other markets include military and avionics displays. LCD is preferred for cockpit applications, and military aircraft applications for electronic displays are forecast to reach \$3 billion per year by the late 1990s. This does not include several billion dollars of expenditures prior to this to update current US military aircraft with displays. The military/avionics display business is dominated by Bendix/King, Rockwell Avionics, and Honeywell, with participation by Tompson CSF.

One attractive niche market is in-flight video for passenger aircraft [4]. In 1989, British Airways introduced 8-millimeter LCD video monitors for their first class passengers, and are also testing the new Airvision system, a Warner Brothers/ Philips joint venture display system. If the (3" LCD) screens are mounted in the seat backs, the viewing angle might be a problem.

### Liquid Crystal Display Technology

Liquid crystal materials are rod-like molecules typified by the cyanobiphenyl compound shown in Figure 1-5. These molecules possess the property of rotating the direction of polarized light passing through. Although the molecules are transparent to visible light, a container of the liquid material appears milky or translucent instead of transparent. The reason for this is because the long axis of the molecules are aligned at random angles, so the light is scattered randomly. A

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liquid crystal display cell is arranged so that the molecules follow a specific alignment. This alignment can be changed with an external electric field, allowing the polarization of incoming light to be changed.

Figure 1-5 Basic liquid crystal polymer molecule



The director, n, of a liquid crystal is a unit vector parallel with the long axis of the molecule. If liquid crystal molecules are parallel, their directors are also parallel. Furthermore, it is possible to arrange the molecules in a cell so that the liquid crystal director gradually changes direction, or "twists" from one side of the cell to the other. The angle of twist depends on a number of factors which will be discussed in this section.

Since the liquid crystal molecules respond to an external applied voltage, liquid crystals can be used as an optical switch, or light valve. A common arrangement is shown in Figure 1-6. The illustration shows two parallel glass plates, each with a polarizing film on its outer side. The space between the plates is filled with the liquid crystal polymer. The technical designation for the most commonly used liquid crystal type is twisted nematic (TN), and the twist refers to the tendency of the polymers to form chains that rotate from one side of the gap between the plates to the other side. The degree of rotation can be controlled during cell fabrication.

Light passing through one of the polarizers, then through the cell, has its polarization direction rotated, following the physical rotation of the liquid crystal. In the illustration here, the polarizer on the exit side of the cell has been positioned to allow the rotated light to pass through. Viewed from this side, this pixel is clear, or transmitting. Other arrangements are possible; this is only one example.

A transparent electrical conductor (not shown) is deposited on the inner surfaces of the glass plates, and patterned into a series of mutually perpendicular lines. If a voltage is placed across the cell gap by addressing the appropriate line on each side of the cell, the liquid crystal reorients to follow the applied electric field, and the material is "untwisted" as shown in the figure. As long as the voltage is present, the passage of light will be blocked by the exit polarizer. When the voltage is turned off, the liquid crystal returns to its original state, and the pixel LIQUID CRYSTAL FLAT PANEL DISPLAYS





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becomes clear again. Typical voltages and currents are quite low, which is why liquid crystal displays have been incorporated in battery-operated equipment, and in other applications where power consumption is an issue.

Liquid crystal materials for small displays have a twist angle of 90°. A "supertwisted" nematic material, developed in the mid-1980's forms a twist angle of up to 270°, and allows much higher contrast, faster response, and the ability to multiplex many pixel elements in a single display. The supertwisted nematic (STN) technology has continued to improve, and forms the mainstream of current display technology. Many other types of materials with very different properties have been developed for specialized applications.

### **1.5.1 TYPES OF LIQUID CRYSTAL DISPLAY**

A great variety of liquid crystal materials have been developed. These include the common twisted nematic materials, and exotic compounds which show very different response to an external field. The most important commercial ones are discussed here, based on a recent summary of the field[5].

Nematic liquid crystals show a root mean square (RMS) response to an applied voltage. This means a relatively slow response to the signal. As long as the information content is limited, TN-LCDs allow high contrast, since the ON voltage can be set to several times the threshold voltage to counteract the RMS response. Threshold voltage might be as low as 0.6V for TN materials.

Multiplexing addressing makes use of time sequential voltage changes to address individual pixels. The ratio of voltages in the select and non-select state has been derived by Alt and Plesho [6] and is given by

$$\frac{V_s}{V_{NS}} = \left(\frac{\sqrt{N}+I}{\sqrt{N}-I}\right)^{\frac{1}{2}}$$

where

 $V_s =$  Select voltage  $V_{NS} =$  Non-select voltage N=Maximum number of rows. Then  $N_{max}$ , the maximum number of addressable lines is a function of the ratio of select and non-select voltages, S

$$N_{max} = \left(\frac{s^2 + I}{s^2 - I}\right)^2$$
 where  $S = \frac{V_s}{V_{NS}}$ 

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 $\frac{V_s}{V_{NS}} = \left(\frac{\sqrt{N}+l}{\sqrt{N}-l}\right)^{\frac{1}{2}}$ 

N	$S=V_s/V_{NS}$	N	$S=V_S/V_{NS}$
2	2.41	32	1.20
3	1.93	64	1.13
4	1.73	100	1.11
8	1.45	128	1.09
16	1.29	200	1.07

**Table 1-4** shows the calculation of S for various values of  $N_{max}$ 

The table shows how small the voltage difference becomes when more than a few lines are multiplexed. Therefore, for multiplexing, the steepness of the electro-optic curve of the liquid crystal should be very high, close to infinite. The slope depends on the elastic properties of the material, although the dielectric properties and optical path difference also play a role. Three elastic constants for a long liquid crystal molecule can be defined. These are "splay", "twist", and "bend". In a "splay" deformation, the molecular directors diverge from one another. Twisting and bending refer to uniform changes in director direction. The ratio of bend/ splay constants,  $K_{A}/K_{1}$  determines the steepness of the electro-optic response curve. Advanced TN materials have a K<sub>4</sub>/K<sub>1</sub> ratio of 0.6 to 0.8, allowing a multiplexing of about 100 lines. For supertwisted nematic (STN) molecules, the twist angle is 240-270°, and a large  $K_{a}/K_{1}$  value is preferable. In practice, a  $K_{a}/K_{1}$  value of 2.5 is the largest for commercially available liquid crystal materials. Figure 1-7 is a schematic representation of the transmission characteristics versus applied voltage of a TN and STN material. The STN response curve is much sharper, allowing switching with just a small difference in ON and OFF voltages.

Supertwist LCD material was developed about 1982 when it was realized that very steep electro-optic response curve could be obtained for nematic liquid crystals with a twist angle >180°. At about 270°, an infinite slope occurs. This means that the slight voltage differences for multiplexing could be tolerated, and the "supertwisted" display was introduced. Some of the first displays were based on the supertwisted birefringence effect (SBE), which produced displays with distinctly colored backgrounds. Adjusting the polarizers to 60° and 30° with respect to the rubbing directions produced black figures on a yellow background.

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Figure 1-7 Transmission versus voltage curves for TN and STN materials.



With both polarizers at 45° to the rubbing directions, white figures on a blue background are produced. High surface tilt angles are required to avoid "striped domains" in STN displays.

To avoid the interference colors of the SBE display, several options have been explored to produce a true black and white display. One example is the optical mode interference (OMI) display, for which  $\Delta n \cdot d$  is reduced to 0.4-0.6µm from the previous standard STN value of 0.8-1.0µm. The quantity  $\Delta n$  refers to the optical anisotropy of the liquid crystal material. The control of this property is an important element in the synthesis of liquid crystal materials. The product  $\Delta n \cdot d$ is a design parameter of the liquid crystal cell. For a constant response, it should be maintained at a high value. Consequently, the OMI display suffers from low overall brightness.

Double layer STN LCDs produce a true black and white display with high brightness. The interference color of a standard STN-LCD can be compensated by a second STN-LCD with opposite helical twist sense but otherwise identical properties. Using a second STN-LCD with opposite twist sense instead of a compensation film guarantees the same temperature dependence of the birefrinLIQUID CRYSTAL FLAT PANEL DISPLAYS

gence and the same dispersion, assuming the LCD material is identical in both cells. Combined with color filters, a high information content full color display can be produced.

A new development in TN technology makes use of vertical alignment of the molecules, termed homeotropic. The director, n, is perpendicular to the glass surface instead of parallel to it, as in the case of STN displays. A very slight tilt may be introduced, perhaps  $0.5-1^{\circ}$ . The advantages of vertical TN technology include high display contrast, wide viewing angle, and a more stable grey scale. Summary of requirements for vertical TN cell are shown in Table 1-5. In this table, the requirement for a small value of  $\gamma$  is equivalent to a high contrast value. High information content displays of the vertical TN type are currently available from Stanley Electric.

Requirement	Ideal Values	
Thin cell	d<5μm±0.3μm	
Small pretilt angle	0.5-1.0°	
Large $\Delta n \cdot d$	$\Delta n \cdot d=0.8-1.0\mu m$	
Large ratio of $K_3/K_1$	$K_{3}/K_{1}>1.5$	
Small $\gamma' = \frac{ \Delta \epsilon }{\epsilon_1}$	γ '<0.5	

 Table 1-5 Requirements for Vertical TN LCD Display

Ferroelectric displays employ liquid crystals that maintain their orientation in the absence of an applied voltage. The display can be switched between the OFF and ON state, and will maintain the selected state without refreshing. In contrast, other display modes discussed here require that the voltage be ON for the state to be selected. Ferroelectric displays are therefore more easily multiplexed, and can serve as memory devices. Problems with these displays include the very thin cells (<2 $\mu$ m) required for their operation, and the lack of a suitable gray scale.

For active matrix displays, TN materials are suitable. However, the requirements are very different than for simple matrix displays. One requirement is extremely high resistivity, on the order of  $10^{13} \Omega$ -cm. New fluorinated materials are available for TN-AMLCD displays.

Table 1-6 shows the currently available displays, either R&D or production, and some critical parameters for each of them.
Properties	Status	NTS	IMO	STN FSTN	DSTN	N/TN	FLC	AM/TN	AM Proj.
Display Area	R&D Production	12" 12"	12" 12"	14" 12"	20" 12"	10" -	14" -	15" 10"	110" 100"
Resolution	R&D Production	640x480 640x480	640x480 640x480	1120x780 1120x780	1120x780 640x480	640x480	1120x1280 -	1280x800 640x480	960x1422 440x480
Duty Ratio	R&D Production	1/240 1/240	1/240 1/240	1/480 1/390	1/390 1/240	1/480 -	1/2000 -		τ ι
$\Delta n \cdot d(\mu m)$		0.8-1.0	0.4-0.6	0.4-1.0	0.8-0.9	0.8-1.0	0.25	0.5 (1. min.)	0.5 (1. min.)
d (µm)		7-8	4-7	4-7	4-7	4-6	1-2	4-7	4-7
Δ d(μm)		±0.1	±0.1-0.2	±0.05-0.1	±0.05	±0.1-0.2	±0.05	±0.1-0.3	±0.1-0.3
Definitions: ON FLC=ferroelectr	/I=optical mod ic, AM/TN=act	le interferen ive matrix a	nce, FSTN ddressed T	=film-compe N, AM/Proj.	ensated STN,	DSTN=dou	uble layer S display	TN, V/TN=	vertical TN,

. Table 1-6 Types of Liquid Crystal Displays

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# **1.5.2 PASSIVE VS ACTIVE ADDRESSING**

The information content of a computer display or television is much higher than for calculators or watches. The number of rows and columns of a VGA computer display is 640x480, or about 300,000 pixels. Full color displays require three color "dots" at each pixel, bringing the total number of discrete picture elements to nearly 1 million. There are two approaches to addressing so many pixels: using a passive addressing matrix or an active one. The difference is shown schematically in Figure 1-8. For the passive (STN) display, the transparent electrodes are patterned on both facing glass plates in perpendicular arrays. The pitch, or repeating distance, of the electrodes corresponds to the pixel dimension, about 100x300µm. Red, green, and blue (RGB) color filters on the outer glass plate provide the full color display. The figure also shows the corresponding active matrix construction. The active switch is shown as a shaded area on the rear panel at the corner of each pixel. This transistor or diode is connected electrically to the edge of the display, and is switched with an external electrical signal. The conducting electrode is patterned to follow the pixel shape on the rear glass panel, but is a continuous film on the front plate.

In principle, passive displays are much easier to fabricate, but in practice, are more difficult to operate. There are conducting lines on both sides of the display, and the drive circuits are much more complicated. This has produced an effort to develop thin film deposition technology that allows the manufacture of a million or more transistors on a glass plate, with a repeatability exceeding that for an integrated circuit.

Passive matrix displays are currently the most common, and have been used in simple watch and calculator applications for some time. Recently, improvements in liquid crystal materials have extended applications of passive matrix displays to large area, backlit computer and word processing products. These displays employ supertwisted nematic liquid crystals for very high contrast, and double cell or film compensation layer construction for a true black and white display. 10 inch displays are employed in portable and laptop computers, and power consumption is low enough for several hours of battery operation, even with a backlight.

Passive matrix displays depend on multiplexing signals on the upper and lower glass substrates. Multiplexing means that voltage pulses are repetitively intermixed and transmitted along row and column electrodes, combining at the

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**Figure 1-8** Schematic representation of passive and active matrix color liquid crystal displays.

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appropriate cross point, i.e., at the pixel being addressed. A pixel or picture element is turned "on" when a voltage is present at both sides of the liquid crystal, and is "off" in the absence of such a voltage. It is possible to manufacture displays with high information content, up to 640x480 pixels and greater. Color display manufacturing is being planned, and displays suitable for engineering work stations are under development. In some sense, these passive displays are competing for the same market as active matrix displays. Ultimately, the problems associated with passive display operation may limit their size and complexity. Very complex schemes are required in order to address each pixel separately from the outside. The transparent conductor for both the upper and lower panel must be patterned, and hundreds of connections are required. For large displays, the liquid crystal material properties, including response time, limit display performance. However, for the next year or two at least, most large displays will be of the passive matrix type.

### **1.5.3 WORKSTATION B/W DISPLAY**

One example of the excellent performance which can be achieved by STN technology is a fast response black and white display that has been reported by Toshiba[7]. For this display, response characteristic is fast enough to allow the use of a mouse in a graphical display environment. This means that the response time of the display has to be faster than 80ms.

The value of  $\Delta n \cdot d=0.67 \mu m$  was maintained in developing cell thickness, d, and other cell parameters. This value is optimum for supertwist displays with retardation films. A threshold sharpness function is defined as

$$\gamma = \frac{(V_{40} - V_{90})}{V_{90}} \times 100(\%)$$

where  $V_{90}$  is the voltage for which 90% transmission occurs, and  $V_{40}$  is the voltage for which 40% transmission is observed. A small value of  $\gamma$  gives a large contrast.

 $\gamma$  varies with cell thickness. The more desirable low values of  $\gamma$  are obtained at large cell thickness,  $6\mu$ m or greater. This requirement conflicts with the fast response speed which is obtained by cell thickness of  $5\mu$ m or less. A compromise value of  $5\mu$ m was chosen for the cell thickness.

Display development employed two retardation films to provide true black/white response and wide viewing angle. For the liquid crystal material the birefrin-

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gence,  $\Delta n$ , has to increase as d, the cell gap, decreases. The product  $\Delta n \cdot d$  must remain constant for best response. However, as the birefringence increases, so also does its wavelength dependence. This has a strong affect on the contrast ratio of the display.

Display specifications are shown below.

Panel size: 235mm (H) x 175mm (V) Display area: 211mm (H) x 132mm (V) Pixel density: 640 (H) x 400 (V) Pixel pitch: 0.33mm Duty cycle: 1/200 Bias ratio: 1/15 Frame frequency: 140Hz Response time: 75ms ( $\tau_{on} = \tau_{off}$ ) Contrast ratio: 14:1

## **1.5.4 POLYMER DISPERSED DISPLAYS**

Polymer dispersed liquid crystal (PDLC) displays make use of liquid crystal droplets to control the passage of light without the use of polarizers. This technology has been used by Asahi Glass to construct light valves for a full color projection TV system[8]. In this system, three light valves are combined with a metal halide lamp and dichroic mirrors as shown in Figure 1-10. Incident white light is divided into blue, green, and red light beams by two dichroic mirrors and one metal coated mirror. Three light valves modulate each primary color to produce the TV image. The light valves are poly-Si thin film transistor active matrix arrays which control the PDLC material. The light valves scatter light in the OFF state, and this scattered light does not reach the lens of the projection system. In the ON, state, light passes through the valve, is collected by the lens and projected as an image on the screen. The switching is accomplished without the use of polarizers.



LIQUID CRYSTAL FLAT PANEL DISPLAYS

The light valve material is a dispersion of liquid crystal droplets in a vinyl acrylate prepolymer. Ultraviolet light-induced polymerization creates a solid polymer film containing the dispersed droplets as shown in Figure 1-10. The droplets contain a twisted nematic liquid crystal, and the small droplet size of a few microns or less causes the liquid crystal directors to adopt a uniform alignment within each droplet. However, the alignment direction of each droplet is random, and light passing through the cell in the off state is scattered. An electric field orients the molecules within the droplets so that the directors are parallel to the field, and light passes through the cell. Rise time of 35ms and fall time of 25ms are fast enough for TV use.





Because the threshold voltage characteristics of the material are not sharp, an active matrix drive scheme is employed. Polysilicon TFTs are used because they are less sensitive to light than a-Si devices. TFT structure is the inverted staggered type, and polysilicon is obtained by laser recrystallization of amorphous silicon. This means that a glass substrate can be employed rather than quartz. The array includes a storage capacitor at each pixel to maintain pixel voltage since the PDLC has relatively low resistivity ( $<10^{12}\Omega$ -cm). Transistor characteristics include a mobility of 10cm<sup>2</sup>/Vs, and On/Off current ratio of about  $10^{6}$ . Array size is 3.4-in. diagonal, 240x360 pixel resolution, and aperture ratio of 60%.

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A full color TV image is achieved with contrast ratio of 100:1, 540 ft-L brightness, and 50 inch diagonal projected image. Screen gain is 5. Chromaticity coordinates of the display are comparable to those of a CRT. Compared with standard light valves employing polarizers, a factor of four gain in luminance is achieved. Since the light valve is not heated by the incident light, cooling is not required, and even higher screen brightness could be achieved with a more intense source of illumination.

## **1.5.5 AUTOMOTIVE DISPLAY**

Matsumoto and coworkers at Asahi Glass, a leader in automotive displays, with its manufacturing subsidiary Optrex, recently discussed some of the requirements for highly legible displays[9]. Advantages of these displays include good legibility under bright ambient light conditions and reduced restrictions on design and color of the display. However, the background transmission of the display, called bleedthrough, reduces legibility.

One solution to bleedthrough is very high contrast (VHC) display technology developed at Asahi Glass and Optrex. A light shielding black mask, positive mode TN-LCD and a reversed driving method are combined to produce contrast in excess of 1000:1. LCD panels for automobile dashboards have to be set in at an oblique angle to prevent display wash-out caused by surface reflection. Because of this oblique mounting angle, the optical anisotropy of the polarizers must be taken into account.

It is possible to obtain high contrast when the display is viewed perpendicularly, but the contrast ratio declines at shallower angles. The angular dependence is a function of the product of birefringence and cell thickness,  $\Delta n \cdot d$ , and must have a value of 0.45-0.5nm.

Polarizers used in this application must have a high degree of polarization, >99.9% to achieve 1000:1 contrast ratio, and the deviation of the cross-angle of the two polarizers must be maintained within  $\pm 1.0^{\circ}$ .

For the low angle viewing appropriate for dashboard installation, the twist angle of the liquid crystal layer should be reduced to about 70°, and the cross-angle of the polarizers shifted from 90° by about 2.6°. In this investigation, the unexpected retardation from the triacetyl cellulose film (which supports the polarizer) complicated the response of the display, and had to be corrected for.

LIQUID CRYSTAL FLAT PANEL DISPLAYS

# Active Matrix Devices

# 1.6

The limitations of liquid crystal switching by a multiplexing scheme can be overcome by placing an active device behind each pixel. The high information content displays for computers benefit from increased response speed, higher contrast, and higher overall brightness. The cost of these improvements is the added fabrication sequence for thin film devices behind each pixel, a total of hundreds of thousands of individual devices for each display.

Having a switch at each pixel greatly simplifies the electronics of the flat panel display. The front panel transparent electrode is not patterned at all, and acts simply as a ground electrode. Problems due to voltage nonuniformity along the display are reduced or eliminated. Twisted nematic liquid crystal material can be used instead of the more demanding supertwisted variety. Various kinds of switches have been investigated for this application, including diodes and transistors. All of these devices are deposited as thin films, and are patterned using technology similar to semiconductor integrated circuit methods. Current production displays employ either a metal-insulator-metal (MIM) diode made from tantalum and tantalum oxide layers, or a MOS thin film transistor (TFT) made in either an amorphous silicon (a-Si) or polysilicon thin film.

Polysilicon transistors have some performance advantages over a-Si devices, and transistor performance is good enough to allow simple integrated circuits to be fabricated at the outside edges of the display. These circuits act as on-board drivers, and greatly reduce the number of external connections. Processing requirements for polysilicon transistors currently require quartz substrates rather than glass. Since quartz is a much more expensive substrate, applications for polysilicon/quartz displays are currently limited to small displays used as viewfinders or projection units. One example is shown in Figure 1-11 below.

Most of the development effort for flat panel displays is devoted to amorphous silicon transistor switches. The technology for depositing thin film amorphous silicon with stable electrical properties has been known for some time, and is used commercially to make thin film "solar batteries" for pocket calculators[11]. Many of these calculators have no other battery, and operate with light from room illumination rather than sunlight. The additional complications of transistor fabrication have so far limited production to small displays, but the difficulties are being overcome, and 10 inch displays are in pilot production in Japan. Full color

## LIQUID CRYSTAL FLAT PANEL DISPLAYS

10 inch displays incorporating TFTs for computer displays are backlit, but they suffer from low overall transmission of light, less than 5% or so. The bright backlight required for adequate visibility limits their application; for portable computers, battery recharging is required after thirty minutes of operation.

The manufacturing process for active matrix liquid crystal displays (AMLCD) which employ a-Si transistors is described in the following section of the report. This complex process sequence employs specialized equipment, some of which is "home-made" by the display manufacturer. In some cases, advanced equipment is supplied by outside suppliers, but in almost no instance has a perfect



**Figure 1-11** *Projection display using polysilicon thin film transistors [10]* 

solution to high volume manufacturing been achieved. This means there are many opportunities for equipment suppliers to develop improved products for this fast growing industry. However, in order to succeed as a supplier, a significant presence in Japan is essential, since almost all active matrix flat panel displays are currently made in Japan.

## **1.6.1 TWO TERMINAL DEVICES**

Two terminal devices are simpler to make than TFTs, and have the potential for higher yield for large active matrix displays[12]. Several kinds of devices have been investigated, including  $SiN_x$  thin film diode,  $Ta_2O_5$  metal-insulator-metal (MIM) diode, and a-Si PIN diode. It is essential for all of these devices to eliminate polarity-asymmetry to prevent a DC bias from occurring.

The amorphous silicon PIN diode structure is shown in Figure 1-12. Bottom and top metals are chromium, which also forms the address line. The bottom Cr layer is also used to form a light shield for the amorphous silicon. a-Si films are formed by PECVD, and  $p^+$ , i, and  $n^+$ , layers are deposited sequentially. The ON/OFF current ratio is about 8 orders of magnitude, much larger than the MIM devices, and PIN diodes should be able to be used for high resolution AMLCDs.

LIQUID CRYSTAL FLAT PANEL DISPLAYS

Figure 1-12 Amorphous silicon PIN diode



 $Ta_2O_5$  devices are simple and device characteristics are stable, so high yield should be possible for large area arrays. Figure 1-13 shows the fabrication sequence of the  $Ta_2O_5$  MIM. A 600Å  $Ta_2O_5$  layer is deposited on non-alkali glass and 3000Å of Ta metal is sputter deposited. Photolithography and etching form a tapered Ta metal structure. Anodic oxidation in citric acid solution forms a 600Å  $Ta_2O_5$  coating over the metal line, and chromium is deposited and patterned. For the chromium pattering, four quadrants are needed to create the active areas, and four photomasks are used to expose this layer. ITO deposition and patterning completes the process. Sheet resistivity of the ITO layer is 20  $\Omega$ /square. The state of the Ta metal in the as-deposited form affects the stability and performance of the device, and nitrogen doping during deposition has been used to create an a-Ta+TaN<sub>2</sub> structure.

The Ta<sub>2</sub>O<sub>5</sub> MIM device has been used to produce a high resolution black and white workstation display, 13" diagonal size[13]. The counter substrate ITO layer is covered with a protective organic film, 4000Å thick, to prevent short circuits through the cell. Reduced resistivity of bus lines was achieved using a double layer structure of Ta and Cr. The width of the Ta line is 24 $\mu$ m, and Cr 18 $\mu$ m, to include a margin for error in alignment in masking. Bus line resistivity is 17.6 $\Omega$ / cm. The cell gap is maintained at 6.0±0.3 $\mu$ m, and twisted nematic liquid crystal is used.

Redundancy is obtained using a double pixel design, as shown in Figure 1-14 Each subpixel is  $86x189\mu$ m, and overall pixel pitch is 0.22x0.22mm. Two cold cathode backlights were employed for illumination. Display characteristics include 1280x800 pixels, pulse width modulated addressing, 16 levels of gray, device size of  $4x4\mu$ m, and aperture ratio of 85%. Contrast ratio is maintained through a wide viewing angle. Right/Left viewing angle is about  $\pm 30^{\circ}$ , and Up/ Down viewing angle is about  $\pm 15^{\circ}$ .

Color filter arrays for full color operation presented a problem when using this device when the color filter is formed over the ITO layer on the front substrate. This increases the voltage drop across the cell, making it difficult to apply

LIQUID CRYSTAL FLAT PANEL DISPLAYS



sufficient voltage to the liquid crystal. For this reason, the color filter must be formed first, then covered with ITO. This adds to the difficulty of patterning the ITO, and open circuits sometimes occur.

Given the same yield, a thin film diode (TFD) costs only 75% as much to manufacture as a TFT array, since the number of process steps are fewer[14]. For comparison, an STN panel is only 15% the cost of a TFT panel. Table 1-7 shows the comparison. However, full color with 16 gray scale, near CRT equivalent display type cannot be easily achieved by TFD.

LIQUID CRYSTAL FLAT PANEL DISPLAYS

Display Type	Masking Operations	Thin Film Depositions	Relative Array Cost	Relative Total Cost
Thin film transistor	7-8	8-9	100	100
Thin film diode	3-4	3-4	50	75
STN	1	1	-	15

 Table 1-7 Processing and Relative Cost of Active and Passive Displays

# **1.6.2 AMORPHOUS SILICON TRANSISTORS**

Two types of TFT structures are used for amorphous silicon (a-Si) devices. One is the inverted staggered (IS) type, which can be either back channel etched (IS-BCE) or tri-layered (IS-TL). The other is called a normal staggered (NS) device. These three transistors (IS-BCE, IS-TL, and NS) are shown in cross-section in Figure 1-15. They are currently being used for LCD TVs or other products in Japan as shown in Table 1-8.

Manufacturer	Toshiba	Hitachi	Sharp	Matsu- shita	Hoshi- den
Screen size	4-inch	5-inch	3-inch	3-inch	10-inch
IFI type	12-BCC	IS-DCE	13-1L	13-1L	0
Number of masks	6	9	8 	9 500 %	ð
a-Si thickness	3000A	2000A	500A	500A	300A
Gate insulator	SiN/SiO	SiN	SiN/TaO	SiN	SiN
Gate line	Mo-Ta	Al/Cr	Та	MoSi/Cr	Al
Signal line	Al/Mo	Al	ITO/Ti	Al	ITO/Cr
Storage capacitor	Yes	Yes	Yes	Yes	Yes

 Table 1-8 TFT Array Process and Specifications

The performance of a TFT as well as the manufacturing yield and throughput depend on the transistor's construction. The inverted staggered back channel etched transistor, (IS-BCE), can be fabricated with the minimum number of six masks, whereas the inverted staggered tri-layered transistor, (IS-TL) requires nine. On the other hand, the IS-TL type has only a 500Å a-Si layer, minimizing

LIQUID CRYSTAL FLAT PANEL DISPLAYS



Figure 1-15 Cross-section view of three TFT configurations[15]

the deposition time for this layer. This is important because amorphous silicon deposition is very slow, and can constitute a manufacturing bottleneck when thick layers are required.

Double layer gate insulator structures such as  $SiN_x/SiO_x$  or  $SiN_x/TaO_x$  are commonly used to minimize yield loss due to line or point defects which cause crossover shorts. These kinds of shorts are difficult or impossible to repair.

Specific resistivities of tantalum (Ta), chromium (Cr) or molybdenum-tantalum alloy (Mo-Ta) films used for gate lines and gate electrodes in some of these structures ranges from 20 to  $40 \mu \Omega$ -cm. These values are too high for large screen TFT-LCDs, since the high resistance and capacitance of the gate line leads to gate pulse delay. For a 12 inch TFT-LCD with 1024x768 pixels and a 16 level grey scale, the resistivity of the gate line should be less than 10  $\mu \Omega$ -cm. Aluminum is the only appropriate material for such high density displays,

One of the difficulties in transistor design and manufacturing is the need for a storage capacitor to improve the image quality. The storage capacitor adjoins the TFT and has an ITO top plate. Charging this capacitor requires that the TFT be relatively large, and the increased area at each pixel devoted to the transistor reduces the amount of light which can be transmitted (aperture ratio). If a second transistor is added at each pixel for redundancy, transmitted light can drop to less than 5% in a finished display.

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Tsumura and coworkers at Hitachi described a 10.3" full color display using a TFT with an aluminum gate, which is shown in Figure 1-16[16]. This gate design uses aluminum for low resistivity, and an anodized aluminum material forms the gate oxide of the device. Aluminum has about one tenth the electrical resistance of chromium. Aluminum is



Figure 1-16 Aluminum gate a-Si TFT

also used for the common electrode of the storage capacitor, as shown in the figure. The TFT is of the inverted stagger type. The storage capacitor is added to improve the uniformity of the displayed image.

Figure 1-17 shows that stray light passing through the display structure can leak through, reducing display contrast. In order to eliminate this stray light, a second light shield was added to the structure, as shown in the lower part of the figure. Figure 1-18 shows the plane view of the active matrix device. The pixel size is 64x192µm. Aperture ratio of more than 25% and contrast of 100:1 were measured. Using 8 level signal drivers, 512 colors were obtained for a full color display.



**Figure 1-18** *Plan view of TFT structure with light shield.* 



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Hitachi's investigation of TFT technology was summarized by Tsukada[17]. The effect of the data or drain address line on the delay time is relatively small. Therefore, the choice of metallization and metal thickness for this line is not critical. However, the situation for the gate line is different. The gate line is deposited at the beginning of the process for inverted structures. This places some limits on the metal and its thickness. Metals investigated for the gate address line application include Cr, Ta, Mo-Ta, and Ta-Cu-Ta. The resistivity of these metals is relatively high, as shown in Table 1-9. For large displays, these materials cannot be used by themselves; ultimately, the choice of metals is limited to Al and Cu. Gold, the only other candidate, is not cost effective. Copper has low resistivity and low cost, but adherence to the substrate is a problem. Therefore, a three layer metal system like Ta-Cu-Ta has been proposed. Hitachi, however, is using aluminum.

The equivalent circuit of the TFT array used by Hitachi is shown in Figure 1-19. The resistivity of the gate line is more than one order of magnitude lower than for the other metal, with reduced gate delay. For computer applications, the display is driven in the non-interlaced mode. In this case, the time allotted to the gate line



Figure 1-19 Hitachi TFT array equivalent circuit

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address is about 20-30 $\mu$ s. Assuming 10% of the gate address time is allowed for gate delay, the gate delay time should be 2-3 $\mu$ s. It is possible to achieve this value using aluminum.

Another important benefit from aluminum gate metallization is the capability of anodic oxidation. This initial step in gate oxide formation provides a defect free structure which resists the shorting effects of foreign particles which might deposit in subsequent processes. This provides a more robust gate insulator structure, and a reduced incidence of crossover shorts. For larger panels and smaller pixels, such shorts between conductors become a more serious problem.

Metal	<b>Resistivity</b> (μΩ-cm)	Anodic Oxidation Possible
Al	3	Yes
Cr	55	No
Та	180	Yes
Ta-Mo	40	Yes
Ti	84	Difficult

 Table 1-9 Resistivity of Metals

Usually in processing aluminum lines, heating causes hillock formation. However, if the surface is anodized, hillock formation is suppressed, and a strong, etch resistant oxide film covers the surface. Leakage current is only  $3 \times 10^{-12}$ A at 20V for a 200nm, 1mm<sup>2</sup> layer. Breakdown field is 7MV/cm, which is less than for other oxides. Metallization shorts are reduced to a low value. For TFT production, a double gate insulator structure of Al<sub>2</sub>O<sub>3</sub> and SiN is used. The ON current of the Al-gate TFT is higher compared with a TFT with only SiN single layer insulation. The dielectric constant of aluminum oxide is higher than silicon nitride, but its mobility is also higher. The transconductance of the Al gate structure can be increased by using a thinner SiN layer.

# **1.6.3 POLYSILICON TRANSISTORS**

Current applications for polysilicon TFT displays include projection and video camera displays which are physically very small, about 1 inch diagonal or smaller for video cameras, and up to 3 inch diagonal for projection devices. It is economical to fabricate such displays on quartz substrates. However, the large

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area displays needed for direct view can't be made on quartz substrates, and the high performance of polysilicon will be available only if a low temperature process can be developed.

Such a process was recently described by Morozumi of Seiko Epson[18]. Manufacturing of large area polysilicon TFTs requires processing temperatures of <600°C. At the same time, the carrier mobility must be increased to achieve higher operating speed. Self-aligned transistors are made by depositing poly-Si, then gate oxide followed by source/drain regions which are self-aligned with respect to the gate electrode. The device is completed with a thick oxide, ITO, and Al contacts.

Non-self-aligned devices are made using doped poly-Si for the source/drain layer, then intrinsic poly-Si for the channel region. After the gate oxide is formed, contact metallization is made using some overlap between the gate and source/drain electrodes.

Five photomasks are used for both processes. Special equipment is required for self-aligned structures for B or P diffusion. Otherwise, "standard" equipment is used for both processes.

Poly-Si material allows the formation of CMOS circuits, which is not possible using amorphous material. Carrier mobility is about 6 cm<sup>2</sup>/Vs for n-channel devices. This is suitable for up to 240x320 pixel displays. For larger displays, higher mobility is required. One way to increase the mobility is to reduce the trap density around the grain boundary by hydrogenation. Doing this increases the mobility of n-channel devices to  $30 \text{ cm}^2/\text{Vs}$ , and p-channel devices to  $20 \text{ cm}^2/\text{Vs}$ . A second approach is to increase the grain size by laser annealing. The mobility increases to about  $120 \text{ cm}^2/\text{Vs}$ .

Driver circuits made from polysilicon transistors have to be fast enough to drive at least 640 horizontal rows. Recrystallized polysilicon shift registers show 30MHz operation, which is fast enough for this requirement.

Process and performance comparisons of amorphous and polysilicon TFTs is shown in Table 1-10.

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	a-Si TFT	poly-Si TFT
Substrate	Hard Glass	Hard Glass
Fabrication		
Mask Steps	6	6
Deposition	Plasma CVD (2 steps)	LPCVD (3 steps)
Sputtering	3 steps	3 steps
Substrate Area	1m square	1ft square
Throughput	3 substrates/hr	30 substrates/hr
Temperature	350°C	550-600°C
Source/Drain	Doped n <sup>+</sup> a-Si	Ion doping/Diffusion
		(self-aligned),
		Doped n <sup>+</sup> poly-Si
		(non-self-aligned)
Transistor Properties		
Mobility	0.5 cm <sup>2</sup> /Vs	5-100 cm <sup>2</sup> /Vs
Threshold Voltage	1-2 volts	1-5 volts
On/Off	10 <sup>6-8</sup>	10 <sup>6-8</sup>
Current Ratio		

Table 1-10 Comparison of a-Si and poly-Si TFTs

Substrate cost is <10% of the fabrication cost of the device, so the cost difference of the glass for a-Si and poly-Si, if any, may be negligible. Facility operating cost is determined by the number of processing steps and throughput at each step. The difference is mainly in the CVD processes. Two CVD steps are used for a-Si TFTs, and three steps are required for CMOS poly-Si. In addition, two ion doping steps are used for poly-Si devices. However, throughput of a-Si depositions is very low. In the end, the competing factors result in a fabrication cost which is almost equal for the two transistor types.

Cost advantage of having the drivers on-board is difficult to calculate. There is some yield degradation due to having the drivers. However, since they occupy a very small area, it may be possible to achieve a high yield, making the cost difference of fabrication very slight. In considering a relatively low yield process, polysilicon on-board drivers make sense only for very small area displays. For

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large area displays, outside drivers make more sense. In the future, for very high yield manufacturing processes, it may be cost effective to place the drivers on-board.

In a recent survey of polysilicon, a summary of conditions for deposition, annealing, transistor type and characteristics was presented. Table 1-11 shows the survey results, with emphasis on sputtering as the deposition method of the future for polysilicon [19].

Precursor (Deposition Method)	Annealing Method	TFT Structure	Mobility (cm²/Vs)	Grain Size (nm)
a-Si	Thermal	coplanar	37	20
(LPCVD)	Ar laser	coplanar	-	<100
	XeCl laser	coplanar	120	60-100
	ArF laser	inverted	90	-
		staggered		
	KrF laser	coplanar	60-120	-
a-Si	Thermal	coplanar	(158)	2000
(PECVD)	XeCl laser	staggered	102	200
	XeCl laser	coplanar	60	80
	Ar laser	coplanar	40	30
	Ar laser	inverted	50	10-100
		staggered		
a-Si (Sputtered)	Ar laser	coplanar	383	40

**Table 1-11** Polysilicon Fabrication Methods and TFT Properties

Problems with the LPCVD material include the high temperature deposition required, above the strain temperature of 7059 glass or equivalent. This means that quartz must be used as the substrate. For PECVD a-Si precursor material, converting to polysilicon by laser annealing causes the eruption of hydrogen; some method of dehydrogenation must be found for this to become practical. The

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Hitachi researcher says that sputtered a-Si gives high quality polysilicon after laser annealing, and thinks that this is the future direction for the technology.

# **1.6.4 COMPARISON OF DEVICE PERFORMANCE**

There are advantages and disadvantages for each of the active devices used for liquid crystal switching. For two-terminal and transistor devices, the considerations are shown below[20].

# a-Si diodes

• Advantages, Ion/Ioff>10<sup>8</sup>, simple process and simple device

• Disadvantages: non-reproducible breakdown, voltage not optimized to liquid crystal threshold. Low threshold with one diode, complex structure with multiple diodes

# **MIM devices**

• Advantages: 2-3 masks, tantalum oxide MIM is light insensitive, hi resolution, no crossovers

• Disadvantages: cross talk, tight tolerances on voltage and temperature, insulator thickness, device area, materials, complex cover plate. For the tantalum oxide MIM, tapered edge is required for Ta line. Spread of taper angles is too large for gray scale.

# **PIN diodes**

• Advantages: charge storage possible, small diodes, redundancy, series/parallel, Ion/Ioff-10<sup>8</sup>

• Disadvantages: twice the row interconnects required, poor storage capacitors, complicated color filter with column lines and ITO on top of filters, non-uniform diode threshold.

# a-Si Transistors

• Advantages: charge storage, fewer interconnects, storage capacitor

• Disadvantages: complex process, Ion/Ioff ~ 10<sup>6</sup>, light sensitive

The leakage current requirement is  $I=C\Delta V/t_{frame} \sim 10^{-12}$ A, where C=0.3pF,  $\Delta V=50$ mV,  $t_{frame}=16$ ms. For a single transistor, the leakage current is higher than

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desirable. A more complex two gate transistor structure can reduce the leakage considerably.

These devices are compared in Table 1-12.

Property	a-Si TFT	a-Si PIN	Ta <sub>2</sub> O <sub>5</sub> MIM	SiN <sub>x</sub> MIM
On/Off current ratio	106-107	108	10 <sup>3</sup> -10 <sup>4</sup>	10 <sup>4</sup> -10 <sup>5</sup>
Number of masks (active substrate)	6-8	6-7	3	2-3
Number of film depositions (active substrate)	6-8	7-8	3	3
Number of leads required for M x N matrix	M+N	2M+N	M+N*	M+N*
for M x N matrix				

 Table 1-12 Comparison of TFT, PIN Diode, and MIM Diode Displays

no crossovers

# **Poly-Si TFT**

• Advantages: higher mobility, transistor performance. CMOS circuit capability for on-board drivers.

• Disadvantages: higher process temperature, ion implantation requirement.

Table 1-13 compares the CMOS poly-Si TFT with a-Si:H TFT. There are two types of poly-Si processes; HT CMOS describes the process for high temperature CVD of polysilicon, while LT CMOS employs a 600°C maximum deposition temperature.

The advantage of developing a CMOS poly Si process is the fact that on-board drivers can be fabricated, cutting down on the number of interconnects to the outside world. However, the LT CMOS process shown above, while it produces transistors with much higher mobility than a-Si devices, cannot operate at a speed high enough for on-board shift registers for high information content displays, at least not yet.

The relative cost of the three processes, amorphous silicon, high temperature polysilicon, and low temperature polysilicon, is shown as a function of display

LIQUID CRYSTAL FLAT PANEL DISPLAYS

	Poly-Si TFT HT CMOS	Poly-Si TFT LT CMOS	a-Si:H TFT NMOS
Substrate	fused quartz	hard glass	hard glass
Maximum process temperature	~1000°C	600°C	300°C
Number of mask steps	6*-8	5*-7	5-6#
Dielectric depositions	3	4	2
(LPCVD or PECVD)			
a-Si Deposition	1	1	2
(LPCVD or PECVD)			
Metal sputtering	3	3	3
Ion Implantation	3	2	N/A
Hydrogenation	Yes	Yes	N/A
Threshold Voltage	2.0	2.0	1.5
(Volts, n-channel)			
Mobility	100	40	0.75
$(cm^2/V \cdot s, n-channel)$			
Shift register @ 15V; L=10µm	20MHz	5MHz	0.1MHz

## Table 1-13 CMOS poly-Si TFT and a-Si:H TFT Comparison

\*=NMOS #=light shield

size in Figure 1-20. The cost is estimated in arbitrary units. For small displays, high temperature polysilicon is low in cost, even when the cost of a quartz substrate is included. This indicates that small displays such as video cameras and projection TVs will be built with this technology, to display sizes of 2-3-inch diagonal. Amorphous silicon is much lower in cost for large displays. The future of low temperature polysilicon lies in this large display area. As mentioned above, low cost relative to amorphous silicon requires a very high yield process, and integration of driver circuits onto the glass substrate. New manufacturing processes and equipment for CVD, implantation, and recrystallization will be required.

A brief discussion of some of the circuit types is shown in Table 1-14. The basic types of integrated circuits that can be considered for driving the active matrix devices include D/A converters, sampled ramp, and 1-of-n selector for digital input. On the other hand, for video input, multiplexer, sample and hold, and double sample and hold are available. The table shows the comparison.

# LIQUID CRYSTAL FLAT PANEL DISPLAYS



Table	1-14 AMLCD	Drive	Circuit	Types
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Driver Type	Advantages	Disadvantages
Digital Input		ny nanonan'n Konne agenetien en dealender pe activitien yn Roben activitien yn de ar yn yn yn yn de ar yn de a
D/A Converters	digital input	complex requires precise correction for LC
Sampled Ramp	digital input programmable ramp	complex high speed, reduced
1-of-n Selector	digital input programmable external voltages	complex high speed, many pass gates per data line
Video Input		gates per data inte
Multiplexer	simple fewer external connections	many analog inputs reduced pixel charging time
Sample and Hold	video input	fast data line charging needed, reduced pixel charging time
Double Sample and Hold	video input, small load, full line time to charge pixel	complex analog circuit large size

## LIQUID CRYSTAL FLAT PANEL DISPLAYS

The demands on driver circuits increase as the complexity of the display increases. Figure 1-21 shows the data rate in megahertz (MHz) needed to address displays of differing complexity, expressed as pixel count. Above 1 million pixels, the data rate exceeds 10MHz, and approaches 50MHz for workstations.

DATA RATE (MHz) Frame Rate = 60Hz 50 Nork Station 1027x768x3 10 VGA 640x480x3 EGA 640x400x3 5 CGA 640x200x3 V 480x240 1 0.5 0.1 1 5 10 **PIXEL COUNT (Million)** Source: Toshiba

Figure 1-21 Data rate of driver circuits for complex TFT displays

# **1.6.5 FERROELECTRIC POLYMER**

There is a new two terminal device which is termed a FEMT, Ferroelectric Matrix device[21]. Figure 1-22 shows the construction of the device. A ferroelectric layer, composed of vinyliden fluoride, VDF, and trifluoroethylene, TrFE copolymer is deposited over an ITO pixel electrode. Thickness of the copolymer is 180 nm. A 400nm thick aluminum common electrode is formed on the ferroelectric layer. Only two photolithography processes are required. The active layer is formed by spin coating after dissolving in a solvent. Coating is followed by annealing at 145°C and slow cooling which induces recrystallization and the ferroelectric transition. The polymer layer is transparent and colorless, with a dielectric constant of approximately 9.

Figure 1-23 shows the LCD panel structure, which is the same as a conventional MIM-LCD structure. The Al common electrodes are connected in the horizontal direction. The ITO segments on the counter glass substrate are perpendicularly arranged with respect to the common electrodes.

Ferroelectric material has a spontaneous polarization which can maintain a

LIQUID CRYSTAL FLAT PANEL DISPLAYS





surface charge. This spontaneous polarization is inverted or reversed by an applied electric field greater than the coercive field, Ec, of the material. The inversion of spontaneous polarization causes a change in surface charge which results in a current flow. The change in surface charge of the FEMT is used to control the voltage on the liquid crystal.

When a negative voltage is applied, spontaneous polarization is inverted over parts of the polymer. An amount of charge  $-Sf \cdot Pr$  is induced on the active layer surface connected to the liquid crystal. Sf is the area polarization and Pr is the remnant polarization (surface charge density) of the active layer. In the non-selected period, the voltage applied to the terminal is opposite in sign to the select voltage. A charge amounting to -SfPr is maintained by capacitances due to the liquid crystal, Clc, and the device, Cf. Therefore, Vlc= $-Sf \cdot Pr/(Clc+Cf)$ 

In the next field, a positive voltage is applied to terminal T in the select period. The spontaneous polarizations are repeatedly inverted, and +Pr is induced instead

LIQUID CRYSTAL FLAT PANEL DISPLAYS

of -Pr. The polarity of Vlc is changed, meaning that ac driving of the liquid crystal is achieved. The symmetry of Vlc results from the symmetry of the ferroelectric material itself. The value of Vlc can be controlled by changing the value of Pr, which is in turn controlled by the pulse height and width of the applied voltage when the active layer is composed of multidomain structure.

Vlc is maintained without decay during the non-selected period because of the memory effect of the Pr. This means that the leakage current of the device is eliminated. This promises high contrast ratio and reduction of cross talk.

The surface charge of the active layer is able to apply ac voltage with good symmetry. Voltage is maintained during non-select periods. Vlc decays with time constant Rlc(Clc+Cf) when Rlc is connected in parallel with Clc. Vlc is continuously controlled by pulse height and pulse width modulation.

The characteristics of the experimental display built using this ferroelectric device are shown in Table 1-15.

Display Size	2 inch diagonal
Pixels	220x320
Active Area	4x4µm
Capacitance Ratio, Clc/Cf	18
Display Operation	Normally White TN
Contrast Ratio	>80
Gray Scale	>10

 Table 1-15 Characteristics of Ferroelectric Liquid Crystal Display

# **1.6.6 PRINTED TRANSISTORS**

GTC Corporation in Japan is conducting fundamental research in manufacturing methods to produce 40-in. diagonal HDTV liquid crystal displays. The research focuses on ways to substitute processes such as printing for photolithography in TFT fabrication. The objective is to provide a low-cost, high speed fabrication process that can produce a 40-in. panel. Such a large substrate size is likely to be outside the practical limit of conventional photolithography. Figure 1-24 compares the standard optical lithography approach to the printing method of the GTC investigators.

#### **CHAPTER ONE: PRODUCT APPLICATIONS** LIQUID CRYSTAL FLAT PANEL DISPLAYS Figure 1-24 Light Source **Optical Mark** Lens *Schematic* Blanket comparison of (a) (a) (b) photolithography Substrate Lens and (b) printing for Substrate imaging transistor

Results of offset printing of photoresist patterns have been reported[22]. The technique is shown in Figure 1-25. A glass substrate is patterned by etching and a UV curable ink is applied, filling the etched grooves, referred to as intaglio. A cylinder covered by a silicone blanket is rotated on the intaglio at constant pressure to transfer the ink to the cylinder. The ink is then rolled onto the TFT substrate as shown. Since semiconductor ink is not yet available, a double resist process is used.



Stage

features on that

panels displays.



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The devices are self-aligned n-channel MOS transistors. Polysilicon is used as the semiconducting material. The substrate is Asahi AN glass, and the processing temperature was limited to 600°C maximum, which is compatible with the glass properties. After the first polysilicon deposition, solid-phase recrystallization is performed to increase the mobility. Doping of source and drain is performed by ion implantation, and all patterning is done by the offset printing method. The transistor fabrication process using printed resists produces working devices with reasonable electrical properties. Threshold voltage is 9V, on/off current ratio is more than 5 orders of magnitude, and electron mobility is 40 cm<sup>2</sup>/Vs. Figure 1-26 shows a TFT made by the printing process compared to a similar one made by photolithography.





technique



(a) TFT made by a print patterning (b) TFT made by a photolithographic technique

# **Display Manufacturers**

This section provides a summary of liquid crystal display manufacturers around the world.

# 1.7.1 JAPAN

Japan is most active in the LCD industry, and estimates of Japan's portion of worldwide production, including simple TN displays, range from 65-75% of the total number of displays manufactured. The portion of the large display market that belongs to Japan is nearly 100%.



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## **Current Suppliers**

A summary of Japanese display manufacturers' current activity is presented in Table 1-16. The table indicates the technology for large area displays, and the status of production, development, and research in different technologies. Production status is indicated as either major, indicating that the firm in question is a major supplier of the product specified, or minor, a minor supplier status. Abbreviated designations for the technologies are listed at the bottom of the table. In subsequent sections, research and production efforts for liquid crystal displays are summarized.

#### 1.7.2 USA

## Xerox

For several years, Xerox has been actively researching amorphous silicon material, and makes use of it in page scanners and other kinds of sensors used in Xerox products. The amorphous silicon devices are manufactured by Fuji-Xerox, a joint venture company in Japan. Recently, Xerox extended R&D activity to include displays of various kinds, and also to include polysilicon materials and devices. Complete display prototyping facilities were built at the Palo Alto Research Center, and an example of a Xerox display was shown in an earlier chapter. The firm has formed a joint venture with Hamlin/Standish, the liquid crystal display maker, to make large active matrix displays. Currently, the firm is seeking to form a separate company supported by a consortium of display users.

## **Department of Defense Initiatives**

The US Department of Defense supports research activities to produce various kinds of displays, including AMLCD displays for avionics applications. Through the Defense Advanced Research Projects Agency, DARPA, a number of other programs are being funded at firms such as Xerox, Sarnoff Labs, and other locations. Research activity at Sarnoff labs includes polysilicon TFT development, and contracts to investigate drive circuit IC design. DARPA has initiated discussions to form a research consortium for pilot display manufacturing with a number of firms.

## IBM

As the largest manufacturer of computers, IBM deserves separate mention whether or not it is manufacturing displays. The joint venture with Toshiba to form Display Technology Incorporated, DTI, has been delayed. The factory has started to manufacture displays. The potential demand for flat panels combined

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Firm	Production	Development	Research
Sharp	a-Si, STN major, TN, minor	p-Si	FLC
Epson	MIM, p-Si major	a-Si	
Hitachi	a-Si, STN, TN, major		p-Si, MIM, FLC
Toshiba	a-Si, STN, major TN, minor	TFD, p-Si	FLC
DTI	a-Si startup		a a construction and a construction of the second
Sanyo	STN, major	MIM, a-Si	FLC
Matsushita	STN, major a-Si, TN, minor	p-Si	FLC
Hoshiden	a-Si, major TN, STN, minor	p-Si	
Optrex	TN, STN, major	MIM	
Asahi Glass			a-Si, p-Si, STN, FLC, PLCD
Mitsubishi/Asahi Glas	SS	a-Si in '92	TN, FLC
(Advanced Display)		p-Si	
Seiko Denshi	TN, major STN, minor	MIS in '92	FLC
Casio	TN, major STN, minor		FLC
Citizen	TN, STN, minor		TFD, FLC
Alps	TN, STN, minor	a-Si in '92	
Stanley	TN, STN, minor		a-Si, FLC
Kyocera	STN, minor	a-Si in '92	
NEC	a-Si, major	p-Si, TFD	STN, FLC
Rohm	TN, minor	TFD, p-Si	
Sony		p-Si	
TDK		a-Si, p-Si	
Oki		a-Si	
NTT			a-Si, p-Si, TN, FLC

 Table 1-16 Liquid Crystal Display Status in Japan

FLC = ferroelectric liquid crystal, MIM = metal/insulator/metal device, TFD = thin film diode

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with IBM's ability to manufacture any of the components of its products lend credibility to speculation that it is considering high volume production in the US, perhaps at its Manassas, VA plant

### **Advanced Display Manufacturers**

The US Commerce Department and more recently the International Trade Commission has agreed to impose levies on imported active matrix displays. The duties amount to a substantial 62.67% on displays which are now imported in small volumes by Sharp and Hoshiden. For passive matrix displays, no duties were imposed since there is no equivalent domestic industry. For electrolumines-cent displays made by Sharp, duties of 7.02% were imposed. No duties will be collected on gas plasma displays.

This decision was prompted by the petition of a newly formed association, the Advanced Display Manufacturers Association. Composed of seven small display manufacturers, the ADMA represents only one actual supplier of AMLCDs. Table 1-17 lists the companies and their principal products.

Firm	Principal Product
Planar Systems	Thin-film electroluminescent displays
Beaverton, OR	
Plasmaco	AC plasma displays (IBM technology)
Highland, NY	
OIS	AMLCDs for military/avionics
Troy, MI	applications
Magnascreen	CdSe TFT technology
Pittsburgh, PA	
Cherry	Thick-film electroluminescent displays
Waukegan, IL	
Electroplasma	AC plasma displays
Milbury, OH	
Photonics Systems	AC plasma, large displays
Northwood, OH	

#### Table 1-17 Advanced Display Manufacturers Association Members

The action of the Commerce Department was objected to by the major computer

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suppliers, especially IBM, Apple, and Compaq. Apple is buying black and white AMLCD displays for its portable computers from Hoshiden, and had been importing them for assembly in the US. At the request of Apple, Hoshiden will now send the screens to Apple's plants in Asia or Europe. There is no duty on imported, fully assembled computers, so Apple and other manufacturers will avoid the duties that way.

There is some place for duties used to protect native industries during periods of early growth. But the action of the Commerce Department and the ITC benefited no one. Not the petitioners, not the Japanese screen makers, not the computer makers, not the user. The action reduces the level of computer manufacturing in the US, since the assembly of laptops will have to be done overseas. Arbitrary rulings of this sort are to be expected in the absence of a US trade policy or industrial policy.

The Commerce Department also provided a \$7.5 million research grant to the ADMA. The funds will be administered by MCC, the Microelectronic and Computer Research Corporation in Austin, TX.

#### Others

US suppliers of TN liquid crystal displays are shown in Table 1-18.

Firm	Display Type	
Hamlin	TN production, STN and AM R&D	
Crystalloid	TN, GH (guest-host)	
LXD	TN	
Tektronix	TN, STN	
Polytronix	TN	
OIS	AM	

<b>Table 1-18</b>	US	Liquid	Crystal	Display	Activity
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# **1.7.3 REST OF WORLD**

#### Europe

Philips is constructing an AMLCD plant in Eindhoven, Netherlands, based on a-Si diode arrays. In addition, a collaborative venture is being discussed by Philips, Thomson (France), and AEG-Telefunken (Germany) in development

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and manufacture of large LCD displays. Thomson has acquired a-Si TFT capability from GE (USA). GEC in Britain will also possibly join the group. GEC performs research on liquid crystal display technology at its Hirst Research Laboratory near London. GEC Plessey Semiconductors has the high volume manufacturing experience. English Electric Valve, EEV is another GEC company that has worked on LCDs for many years.

Table 1-19 shows the liquid crystal display activity at European firms. Research on active matrix display technology is led by Philips and Thompson CSF. Of the firms shown in the table, AEG currently has the largest manufacturing activity, based on coated glass purchases.

Country/Firm	Display Type
UK	
EEV	TN
GEC	STN, FLC R&D
Racal	TN
Thorne EMI	FLC R&D
Germany	
Optrex Europe	TN, STN
AEG/Hitachi	TN, STN
Hoerner	TN
Univ. Stutgart	AM R&D
Netherlands, Philips	AM diode array
Italy, Tecdis	TN. STN
Switzerland	
EM Micro, Asulab, ETA	TN
Norway, Autodisplay	STN
Finland, Nokia	STN
France	
Thomson LCD, CNET	AM R&D
Belgium, Univ. Ghent	AM R&D
Czechoslovakia, Tesla	TN
Poland, Polo Color	TN

 Table 1-19 European LCD Activity

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# Korea

The major Korean electronics equipment manufacturers have taken a recent interest in the liquid crystal display technology developments, and have undertaken production and development activities as indicated in Table 1-20.

Firm	Production	Research & Development
Goldstar	-	a-Si
Samsung	TN, STN	a-Si
Daiwo	-	TN
Hyundai	TN	STN
Zuitsu	-	TN
Kankoku	TN major produc	er

Table 1-20 Liquid Crystal Display Status in Korea

## **Other Asian Firms**

South East Asia accounts for 20-25% of liquid crystal display manufacturing, primarily small, low cost TN displays. Table 1-21 shows the companies involved.

<b>Table 1-21</b> <i>LCD</i>	Manufacturing	in Asia
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Country/Firm	Display Type
Taiwan	
Epson, Hitachi, Mesostate, Excel, Goldentek,	TN
URT, Wintek, Isotek	
Picvue	TN, STN R&D
Hong Kong	
Philips, Epson, Conic, Yeebo, SII, Jic, Truly	TN
RCL, DTL, Clover, Hosiden, Adamant	
Varitronix	TN, STN
China	
Vikay, Jinghua, Hebei, Shantow, Shanghai,	TN
Beijing, Quirtao, Kwan Tong	
Tianma	TN, STN R&D
Singapore	
Vicay	TN, STN
PCI	TN
India	
Bharat, Coventry	TN

2

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# DISPLAY MANUFACTURING PROCESS



The manufacturing flow for flat panel displays is shown conceptually in Figure 2-1. This figure indicates that two glass substrates are processed separately, then joined together. One substrate is patterned to create a color filter array, and the other is patterned to form thin film transistors. These plates are mated in the assembly process. In the case where several displays have been patterned on the substrate, they are sliced and separated into individual displays. Liquid crystal material is injected into a gap between the two glass plates, and the finished display is ready for incorporation into a computer or other product. Not shown in the figure are operations to attach integrated circuits to address the display, nor the backlight to illuminate it. These are discussed later on.

The individual processes required to pattern each glass plate, to assemble and test each unit, and to create a finished display, are numerous, and require specialized equipment, materials, and processes. These are discussed in some detail in subsequent sections of this book.



SEPARATION

LIQUID CRYSTAL INJECTION

Figure 2-1 Schematic outline of the display manufacturing process.

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# **Color Filter Manufacturing**

This section includes a discussion of glass substrate manufacturing and finishing, which precedes both color filter and TFT manufacturing.

## 2.1.1 GLASS SUBSTRATE PREPARATION

The glass substrate is an essential component of the display, and a rather expensive one at that. Very tight control of the optical and mechanical properties of the material are required at every stage of the process, especially when heating is involved. The glass, ordinarily 1.1mm thick, ranges in size from 300x300mm to 450x550mm for the fabrication of large displays. Even larger sizes will be used in the future. This section outlines the glass manufacturing process.

## **Glass Fabrication**

Very thin glass with very precise dimensions and reproducible mechanical properties can be made by two processes. The so-called fusion process, developed by Corning, is shown in Figure 2-2. Glass fusion employs a feed rod of glass which melts in a wedge-shaped trough and flows up and over the sides of the trough. Flowing down both sides of the trough, the molten glass joins into a single sheet at the bottom of the trough, and can be drawn downward as a uniform sheet. Thickness of the sheet is controlled by the speed of drawing down the glass. Widths of up to 36" can be obtained.



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Other manufacturers of glass with the appropriate dimensions for LCD substrates use the float method of manufacturing. In this method, the molten glass is allowed to flow out onto a bed of molten tin. The glass does not dissolve or react with the metallic tin, but floats on the surface. This allows gravity to smooth the surface and allow both sides to become parallel.

Sodium free glass is used for active matrix displays, because the presence of sodium is considered harmful to the reliability of displays where thin film devices such as diodes or transistors are employed. Glass can be supplied to users in three surface finish conditions; as drawn, polished, and annealed. Each material has a specific application in display technology.

Table 2-1 shows the variety of glasses available for display manufacturing. The glasses are ranked in order of increasing strain point. The strain point is indicative of the maximum processing temperature of the glass. Low temperature glasses are restricted to simple TN applications, and medium temperature strain point materials, such as Corning 7059, Hoya NA45, and Asahi AN substrates are used for STN and active matrix displays. These are borosilicate glasses, which offer low levels of alkali metals as well as higher strain point. The silica glasses (quartz) shown in this table are used for very small displays used as viewfinders in videocameras. These displays require the performance of polysilicon transistor switches, and this can only be obtained using high temperature LPCVD deposition of silicon at 600-900°C, far above the practical working temperature of the glasses.

A variety of substrate sizes are available, up to a current substrate of typical 300x350mm dimensions, but extending to 450x550mm and larger. Typical glass thickness is 1.1mm, also referred to as 1.1t. Thinner glass is available, and is used for some smaller displays, such as pagers, telephones, games, and so forth.

### Cutting, Beveling, Polishing

Glass substrates are trimmed to size after the fusion or float process, typically to about 1 meter on a side. Various mechanical operations follow the forming process, depending on the ultimate application of the material.

Since glass is brittle and easily chipped or cracked at the edges, these are typically beveled, chamfered or otherwise treated to reduce chipping during handling. Thermal stresses at edge cracks accumulate during substrate processing, and lead

			Refe	rence Tem	beratures	Th	ermal Expansic	D D	ensity
Glass	Code	Type	point °C	point °C	point °C		x 10 <sup>-7</sup> /°C (0-300°C)	530	/cm³
Corning	0211	Alkali-zinc Borosilicate (Microsheet)	508	550	720	74		2.57	
Corning	7740	Borosilicate (Pyrex)	510	560	821	32.5		2.23	
Asahi	AS	Soda lime	511	554 571	740	81	(50-200°C)	2.49 2.41	
NEG	BLC	Sodium borosilicate	535	575	775	51	(30-380°C)	2.36	
Corning	7059	Barium aluminoborosilicate	593	639	844	46		2.76	
Hova	NA45	Borosilicate	- 610	658	859	46	(100-300°C)	2.78	
Asahi	AN	Alkaline-earth aluminoborosilicate	616	661	862	43	(50-200°C)	2.72	
DEG	0A2	Alkaline-earth-zinc aluminoborosilicate	635	685	895	47	(30-380°C)	2.76	
Corning	1733	Alkaline-earth Boroaluminosilicate	640	689	928	36.5		2.49	
Hoya	NA40	Alkaline-earth-zinc-lead aluminosilicate	656	708	895	43	(100-300°C)	2.87	
Corning	1724	Alkaline-earth boroaluminosilicate	674	721	926	4		2.64	
Corning	1729	Alkaline-earth aluminosilicate	661	855	1107	35		2.56	
Corning	7913	96% silica (Vycor)	890	1020	1530	7.5		2.18	
Corning	7940	Fused silica	066	1094	1580	5.5	2.20		
Asahi	AQ	Synthesized silica	1000	1120	1600	9	(50-200°C)	2.20	
		Silicon Stainless SUS 304 Stainless SUS 410				38 175 105	(327°C)	2.3 8.0 7.7	

Table 2-1 Glass Substrates for Flat Panel Display Manufacturing

LIQUID CRYSTAL FLAT PANEL DISPLAYS

to breakage. Glass breakage is a major problem in flat panel production. First of all, the broken plate is itself a yield loss, but fragments of glass may remain behind in carriers or equipment to cause particulate contamination or scratching of other substrates.

Surface flatness is an important parameter of the substrate, and is a function of the glass forming process. A certain level of waviness occurs in fusion glass. Such slight thickness variations as well as other "nonflat" conditions are either difficult or impossible to remove in a polishing operation. Instead, a grinding step must be performed, which greatly adds to the manufacturing cost, and makes it uneconomical as a finishing step for display substrates. Glass manufacturers concentrate on improving the forming process to reduce surface irregularities in manufacturing.

Glass polishing is more and more difficult as substrate size increases. Large substrates must be mounted to carriers using wax or other adhesive, and polished using a slurry of abrasive material. This polishing process must be followed by a thorough chemical cleaning to remove any remaining wax or other organic residue, as well as the metallic contaminants which are part of any abrasive or polishing medium.

For glass prepared by the fusion or float processes, the surface of the as-produced glass is smoother than a polished surface. However, some scratches are found on the as-grown surface. If glass can be formed without scratches, the polishing process may well be eliminated.

#### Annealing

Figure 2-3 shows the thermal expansion of Corning 7059 glass as a function of temperature. For substrates used in thin film transistor fabrication, process temperatures of 350-450°C are common, and are repeated several times. At these temperatures, thermal expansion of several parts per million is observed. Near the strain point, thermal expansion increases in a nonlinear fashion. This makes it difficult to control the properties of the thin films deposited on the surface. For this reason, thin film deposition is performed at temperatures considerably lower than the strain point of the glass.

Heat treatments to control thermal processing during display manufacturing include annealing processes to produce compaction or shrinkage of the glass, so

LIQUID CRYSTAL FLAT PANEL DISPLAYS



Figure 2-3 Thermal expansion of Corning 7059 glass

that further shrinkage during use is minimized. Hoya has developed a new glass, NA35, suitable for polysilicon TFT fabrication. This material has a strain point of 610°C, and Hoya suggests processing temperatures as high as 600°C. Abrupt heating and cooling occur in the TFT process. When glass is subsequently heated at a lower temperature, the glass may transform from a high temperature structure to a low temperature one, leading to shrinkage of several parts per million. Figure 2-4 shows the shrinkage observed for NA 35 annealed at 600°C and 610°C. Shrinkage increases linearly with time at a constant temperature. However, there is some limit to how much shrinkage will occur. Annealing treatments by the glass manufacturer can bring the glass near to this limit and stabilize its properties for reproducible overlay of photolithography patterns.

Figure 2-4 Thermal shrinkage of NA 35 glass as a function of heat treatment time and temperature



LIQUID CRYSTAL FLAT PANEL DISPLAYS

Specifications and standards for glass substrate properties are being developed by suppliers and users, with the cooperation of standards committees at SEMI Japan. (SEMI is the name of the Trade organization, Semiconductor Equipment and Materials International.) A typical specification for an active matrix display substrate is shown in Table2-2. This specification includes surface properties and thermal shrinkage requirements appropriate for TFT array fabrication. When displays are manufactured, the front panel containing the color filter array experiences very little high temperature treatment, so preannealing is not required.

Parameter	Value
Size (mm)	300 x 350 ±0.2
Thickness (mm)	$1.1 \pm 0.1$
Chamfer (mm)	0.1 to 0.4
Corner Cut (mm)	1.5 ±0.1
Orientation Corner (mm)	$(2.0 \pm 0.1) \times (5.0 \pm 1.5)$
Warp (mm/mm)	0.45/300
Inclusion (mm)	Not allowed over 0.1
Streak (µm)	Under 0.1
Shrinkage (ppm)	<10 for 1 hr. at 350°C
Surface Quality	No visible defect under
(scratch, stain)	10K Lux

 Table 2-2 Glass Substrate Specification for Active Matrix Display

It has proven difficult to establish standard substrate sizes for flat panel displays, which makes substrate and process equipment manufacturing difficult as well. Literally dozens of sizes of substrates are in use, with more than ten size specifications for active matrix substrates alone. The SEMI organization is the focus for standardization efforts for substrates, and a set of sizes is under consideration before the substrate standards committee at SEMI Japan. This set of proposed standard sizes is shown in Table 2-3.

## Cleaning

Cleaning processes are used for bare glass substrates, and for substrates covered with organic films, such as color filters, polyimide orientation films and so forth. In addition, substrates with semiconductor, insulator and metal films require cleaning

LIQUID CRYSTAL FLAT PANEL DISPLAYS

**Table 2-3** Proposed Substrate Standard Sizes for Flat Panel Displays

 (dimensions in millimeters)

300 x 300	300 x 350	300 x 400	300 x 450	300 x 500
	350 x 350	350 x 400	350 x 450	350 x 500
		400 x 400	400 x 450	400 x 500
			450 x 450	450 x 500
				500 x 500

as the fabrication process progresses. As a minimum, cleaning is required prior to each masking step in color filter or thin film transistor fabrication. An overview of the cleaning steps used in the entire process will be presented here.

The types of cleaning used in flat panel display manufacturing include physical, chemical, and dry cleaning. Physical cleaning is currently most important, and includes brush scrubbing, ultrasonic, and megasonic assisted cleaning. Megasonic cleaning is effective in eliminating submicron particles[3]. Table 2-4 summarizes the cleaning methods currently employed, with comments on their efficacy. Most panel cleaning employs a combination of physical and chemical methods, with selective use of dry methods. After chemical etching or cleaning, substrates are usually dried using isopropyl alcohol.

One way of evaluating the performance of a cleaning sequence is to measure the contact angle of a water drop on the surface of a bare substrate. The test indicates whether organic contaminants remain on the substrate surface. If organic molecules are present, the water droplet will not wet the surface, since "oil" and water don't mix. This causes the water to form a bead with a contact angle that is relatively large, up to 45°. On the other hand, a clean surface will be wetted by the droplet, which will spread out over the surface, resulting in a contact angle of zero. Figure 2-5 shows the results of an investigation of substrate cleaning methods where a combination of methods was employed [4].

The illustration shows a sequence of steps. Step 1 is a wet cleaning with the appropriate chemical and water rinse, each with brush scrubbing followed by ultrasonic (US) rinse and water spray. After step 1, two different final treatments were used. In the sequence step 2 and step 3, an air knife plus an infrared/ ultraviolet (IR/UV) heating were applied. An alternative consisted of isopropyl alcohol (IPA) dip, freon vapor dry, and IR/UV treatment. The illustration shows

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CLEANING METHOD	COMMENTS
Physical Cleaning	
Brush scrubbing	Removes adhering particles, not necessarily smaller ones; effect proportional to brush pressure
Jet spray	Suitable for patterned, hydrophilic, and soft surfaces; substrate may acquire static charge
Ultrasonic	Accelerates chemical cleaning, but particles remain; standing wave formation in bath limits uniformity
Chemical Cleaning	
Organic solvent	Contaminant specific, removes organic films
Neutral detergent	Suitable for organic films and particles, little or no substrate damage, but residual film may remain
Chemical cleaning	Process specific for etching, cleaning, and stripping; suitable for all contaminants and particles
Pure water	Suitable for chemical removal, not for particles and organic films
Dry Cleaning	
Ultraviolet ozone	Can eliminate adsorbed organic films, improves photoresist adhesion
Plasma (oxide)	Photoresist ashing; not suitable for particle removal, low throughput
Plasma (non-oxide)	Eliminates low level organic and in organic contamination; limited application
Laser	Localized cleaning; not suitable for full surface cleaning

 Table 2-4 Cleaning Processes for Flat Panel Displays

that effective removal of residual contaminants requires more than just a wet cleaning step. The method of drying is an essential component of cleaning the substrate.

Organic contamination is one limit to high yield flat panel display production. Another, more serious limitation is due to particles. Although typical linewidths

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Figure 2-5 Cleaning methods evaluated by contact angle measurement

for thin film transistors are  $5\mu$ m, and the lower limit appears to be  $3\mu$ m for the near future, particles of  $0.5\mu$ m size and greater are extremely detrimental to yield. One major contributor to particles on the substrate surface is the rinse water itself, in the case of low purity water. Table 2-5 shows measurements reported by Tamada comparing water resistivity and surface particle count before and after rinsing the substrate. Clearly, a relatively high purity water source is essential.

Water Specific Resistance MΩ	Initial Particle Count	Post-Rinse Particle Count	Increase in Particles
7.5	7	10	3
1.0	2	5	3
0.15	5	328	323
0.01	14	6356	6342

**Table 2-5** *DI Water Quality and Substrate Particle Count* (*particles >0.5µm on 4 inch Si substrate*)

## **ITO Deposition**

ITO is indium tin oxide, actually a mixture of the oxides,  $In_2O_3$  and  $SnO_2$ . This material is the only one suitable for the transparent conductor application for

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liquid crystal displays; a thin film of ITO is required on both sides of the display, either as a continuous film or patterned to form stripes, lines, or rectangular plates.

When sodalime glass is used, just prior to ITO deposition, the glass is covered with a  $SiO_2$  coating, to prevent ion migration from the glass during further processing. The coating can be performed by dipping the substrate into a liquid colloidal source or coating by chemical vapor deposition.

Today, ITO thin films are mostly made using vacuum evaporation and sputtering. ITO films with a small amount of added  $\text{SnO}_2$  show low electrical resistance,  $-2x10^{-4}$  ohm-cm, depending on the quantity added, and transmittance in the visible spectral region of 75-90% or more. Film thickness is ordinarily in the 1000-2000Å range.

Usually, for vacuum evaporation, in a chamber evacuated to less than  $1 \times 10^{-5}$  Torr, oxygen gas at a pressure of  $\sim 1 \times 10^{-4}$  Torr is introduced, and a pellet of indium is evaporated from a e-beam gun. At a temperature of 400°C, quantity of oxygen, and control of evaporation rate are important parameters. Heated In<sub>2</sub>O<sub>3</sub> decomposes and evaporates, and, on the way to the substrate, recombines.

For ITO films made by sputtering, two methods are used. In-Sn alloy targets are used in one method, and, for the second, reactive sputtering, in which about (5-10) weight % SnO<sub>2</sub> is added to In<sub>2</sub>O<sub>3</sub> to form an ITO target. The cost is relatively low for the first method, but it is difficult to control the conditions for good film production, and reproducibility is inferior. Reactive sputtering using In<sub>2</sub>O<sub>3</sub>-SnO<sub>2</sub> targets, compared to using metal targets, shows reduced cycle time, and stable reproducible properties. 400°C substrate temperature is necessary for evaporation, and it is hard to evaporate high quality films at lower temperatures, but for sputtering, low temperature formation can be used, with resistance values somewhat higher than for evaporation. Temperatures as low as 200°C are necessary when the ITO film must be deposited over the color filter array, discussed later in the report. There is no great difference in the transparency of sputtered films compared to evaporated films.

The resistivity of ITO films is a complicated function of oxygen and tin content, as well as deposition conditions. Increasing oxygen content during sputtering or evaporation may increase the crystallinity of the ITO film, leading to a higher carrier mobility. On the other hand, increasing the oxygen content reduces the

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carrier concentration, supposedly due to chemical combination with the Sn<sup>+4</sup> species. An optimum oxygen concentration must be determined for each process.

The glass substrate with thin film coating is patterned by etching, either wet or dry. For large area high information content displays, this results in a large number of very small features. Since the pattern size is small, and at the same time, low surface electrical resistance is required, inevitably, the transparent electrode film thickness tends to increase. Typical sheet resistance for ITO films are  $100 \Omega/$  square down to  $50 \Omega$ /square. However, addressing high density displays requires much lower values, either 20 or  $10 \Omega$ /square. Achieving low sheet resistance by increasing the film thickness produces lower light transmission and panel contrast is degraded. In addition, etching is more difficult. Etch materials and etch rate are adjusted so that etching time is reasonable and so that overetching does not occur. The etch rate for sputtered films is generally lower than for evaporated films.

Thin films of ITO are easy to etch with wet chemicals such as hydrochloric acid, but, as the pitch of the electrodes become smaller and features become finer, dry etching may be necessary to prevent undercutting of the lines due to overetching. Plasma etching can be employed with good results. Researchers at General Electric have discovered that a two step plasma etching process is most efficient.[6]. They used HCl as the reactive gas in the first step, followed by acetone and other hydrocarbons in the second; HCl provided etching speed, while the hydrocarbon mixture gave good control over the endpoint.

Where ITO films are deposited over a color filter pattern, special processing must be employed to ensure that low resistivity films are obtained at the low deposition temperatures that are required when depositing onto organic thin films. Two approaches to solving this problem have been reported recently.

The first approach modifies the parameters of a sputtering system to obtain low resistivity films at temperatures of 200-250°C. This system employs DC magnetron sputtering for which the sputtering voltage is adjusted (reduced) to obtain improved results. Figure 2-6 shows the relation between sputtering voltage and film resistivity for voltages of -400V, (the normal bias voltage used in the system), -250V, and -110V. The figure also shows the change of resistivity as a function of temperature. At temperatures of 250°C and below, it is difficult to obtain a low enough resistivity with high sputtering voltage without making the

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film very thick. The reduced bias voltage allows lower resistivity while increasing light transmission through the film.

The investigators studied the reason for lower resistivity with lower sputtering voltage. They determined that at -400V bias. oxygen atoms were sputtered from the target with high energy, and these oxygen atoms impacted the substrate with energy 400eV. One result was the formation of a sub-oxide. InO, rather than the expected In<sub>2</sub>O<sub>2</sub> compound. This InO material is high resistivity, and is also black (absorbing). Lowering the sputter bias voltage eliminates this black particle formation, lowering the resis-



**Figure 2-6** Relation between sputtering voltage, deposition temperature, and ITO film resistivity

tivity and improving the optical transmittance at the same time.

A second method for depositing ITO over color filters has been reported, using plasma-assisted electron beam evaporation [8]. Figure 2-7 shows a schematic diagram of the apparatus. Substrates of 300x300mm size are heated prior to deposition in a separate chamber. The deposition chamber contains a crucible containing ITO pellets and a set of arc plasma generators. Argon and oxygen gases are mixed in controlled volume ratios of 0-50% and introduced into the chamber at a pressure of  $2x10^{-4}$ - $1x10^{-3}$  Torr. ITO deposition rate is 50Å/sec, and film thickness is 1000-2000Å.

Film stress is an important property, since highly stressed films can cause substrate bow, which makes control of the cell gap difficult. Also, where color filters are present under the ITO film, high stress can cause peeling and lifting of the filters. Compressive stress was minimized by employing higher total gas pressure, near  $1 \times 10^{-3}$  Torr. Film resistivity for 200°C deposition was  $1.8 \times 10^{-4} \Omega$ -cm,

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and 10  $\Omega$ /square films were patterned for color STN displays using 100 $\mu$ m ITO stripes with 10 $\mu$ m spaces between them. The displays were driven at 1/400 duty ratio without additional metal electrodes to reduce the sheet resistance of the conducting lines.

Figure 2-7 Schematic diagram of plasma-assisted electron beam evaporation equipment



# **2.1.2 COLOR FILTER PROCESS**

Color filter processing involves a number of steps besides color filter application. These include CVD or spin coating of insulators and metals, as well as planarization and orientation film coatings. Currently there are at least ten firms in Japan involved in color filter manufacturing, either as merchant or captive suppliers. These firms perform the entire process, with the exception of orientation film deposition and rubbing. For the most part, display manufacturers purchase completed panels from outside suppliers.

The first step, color filter formation on the front glass substrate, is shown schematically in Figure 2-8. The illustration indicates the equipment used in each step of the process. This figure includes some of the glass finishing and preparation steps common to both the front and rear panels, including the beveling and lapping processes. Operations such as substrate washing and cleaning, coating, curing and other steps are performed repetitively on the substrate. Many points of similarity with silicon wafer processing exist. Glass substrates are typically handled in track systems for cleaning and coating.

Table 2-6 summarizes the various materials, application methods, and suitability for various flat panel display types. The most important methods for color filter preparation are discussed in this section.

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Material	Application Method	Element Definition	TFT Compatible	MIM Compatible	STN Compatible
Dyestuff	dye	photolitho- graphy	Yes	No	No
Dyestuff	dispersed	etching	Yes	No	No
Pigment	dispersed	photolitho- graphy	Yes	Yes	Yes
Pigment	dispersed	printing	No	Yes	Yes
Pigment	electro- deposited		No	Yes	Yes

 Table 2-6 Types of Color Filters for LCDs

Source: Nikkei Microdevices

## **Black Matrix Definition**

The figure indicates that color filter formation is a repetitive process, occurring either three or four times in succession. Three primary color elements are formed, each one about 100x300µm in size. A black border area is needed around each color element for contrast. If the black border is deposited and patterned using photolithography, a total of four steps will be required for red, green, blue, and black color deposition. The black border is very important for definition and contrast, and can be deposited in two ways. The first method is to deposit a thin layer of chrome metal, the back surface of which is either oxidized or coated with CrO light absorbing film. The second way is to mix all three color pigments to form a black organic border around the filters. Typically the chrome matrix is applied before the filters while the pigment mixture black border is applied afterwards.

## **Dye Method**

Table 2-7 shows the primary types of organic materials which are suitable as light absorbing color filter materials. Basically, either a dyestuff or a pigment can be used, and either one can be deposited and patterned in several ways. Currently gelatin is deposited and dyed in successive photolithographic operations, using proximity printing equipment and standard photoresists.

### **Pigment Method**

In addition, pigments dispersed in photoresist are being employed. The pigment dispersion method has the advantage of eliminating the gelatin layer, and higher

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temperature capability is one result of its use. Both of these methods produce uniform color elements with the spectral purity required for full color displays. Color filters formed from pigments dispersed in polyimide give the highest temperature capability and some simplification in processing [9].

# Electrodeposition

Other methods for forming color filters are being investigated. These include

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electrodeposition and printing. One new electrodeposition process employs only one photoresist deposition, and can include the black matrix deposition as a final step [10]. Another process uses a charged mist of dye molecules which deposit to uniform final thickness over the substrate in a self-limiting electrodeposition scheme [11]. Although these have the potential for low cost, technical problems prevent them from being employed for the TFT active matrix display, since they allow only the deposition of color stripes.

# Printing

Screen printing is already in use for some passive displays, but the minimum thickness is  $10\mu m$ . Other kinds of printing processes, such as offset printing, with 1-2 $\mu m$  film thickness capability, are being investigated for high density displays. The table summarizes the properties of color filters made by the various processes.

# Overcoating

Both dyeing and pigmented photoresist methods leave a non-planar surface after color filter definition. Since an ITO common electrode thin film as well as a liquid crystal alignment polymer layer must be deposited over the filters, at least one intermediate planarizing layer must be added over the color filter array, thus adding to its cost. In addition, some sort of definition of the outer edges of the planarizing layer must be performed, so that the ITO conductor makes good contact with the underlying glass substrate. This is a particular problem for simple matrix color displays, for which the ITO is patterned in stripes rather than as a continuous layer. Each stripe must form an electrically continuous line.

# **ITO Deposition**

After color filter preparation, the final step is the sputter deposition of a transparent electrode material. This is indium-tin oxide (ITO), which is ordinarily not patterned when active matrix thin film transistors are used to switch the color elements. On the other hand, STN color displays have patterned ITO stripes as mentioned previously. One limit on the performance of the color filter material is the compatibility with the ITO sputter deposition conditions. Ideally, a substrate temperature of >200°C is preferred for sputtering in order to achieve the lowest possible resistivity for the ITO film. However, not all color filter materials can withstand such a temperature. This consideration, as well as other requirements for color filters, has led to investigation of the various approaches to color filter manufacturing mentioned here.

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Properties	Dye	Dye Dispersion	Printing	Pigment Dispersion	Electro- deposition
Film Thick-	1.0-2.5µm	1.0-2.5µm	2.0-3.5µm	0.8-2.0µm	1.5-2.5µm
ness				·	·
Spectral	Superior	Good	Good	Good	Good
Properties					
Resolution	10-20µm	10-20µm	70-100µm	20-30µm	10-20µm
Planarity	Good	Good	Inferior	Good	Superior
Heat	180°C/1 hr	200°C/1 hr	250°C/1 hr	<250°C/1 hr	250°C/1 hr
Resistance					
Chemical	Inferior	Good	Good	Good	Good
Resistance					
Resin	acrylic	polyimide	epoxy	acrylic,	acrylic
Material				Sbq-PVA	-
Color	dyestuff	dyestuff	pigment	pigment	pigment
Element					
Advantages	spectral	detail	light & heat	light & heat	light & heat
	properties		resistance	resistance	resistance,
					planarity
Disadvantage	es stability	stability	planarity		pattern
					restriction

<b>Table 2-7</b>	Color	Filter	Process	<b>Comparison</b>
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Source: Toppan Printing



# Active Matrix Display Manufacturing

The fabrication of an active matrix flat panel display is performed in three distinct operations. In the first step, the (front) glass substrate is prepared, including the deposition and patterning of the color filter elements. A separate (rear) glass substrate is used for the formation of thin film transistors, as well as for metal interconnect lines. The third and final step is the assembly of the two panels, injection of the liquid crystal material between them, and final inspection of the finished device.

# **2.2.1 THIN FILM TRANSISTOR MANUFACTURING**

Thin film transistor fabrication is shown in Figure 2-9. The illustration shows

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both processes and equipment for thin film transistor formation. This process is very similar to the fabrication of an integrated circuit. With the extra transistors often used for redundancy, a total of one million transistors may be fabricated on a single 10 inch panel, meaning that the complexity of the process is similar to that of a dynamic memory chip. Substrates begin the fabrication process with a thin film application step. Then, a photoresist is applied and imaged to allow etching of the thin film to the appropriate dimensions. A sequence of thin films is deposited and etched, as with integrated circuit fabrication.

## Plasma CVD & Sputtering

The number and sequence of thin films depend on the transistor design being used. Thin films are deposited by chemical vapor deposition, (CVD), or physical vapor deposition (PVD). Plasma enhanced CVD, also known as glow discharge, is used for amorphous silicon, silicon nitride, and silicon dioxide. Amorphous silicon is used in all active matrix TFT devices. PVD, usually sputtering, is used primarily for metal films. Thin film deposition typically occurs in in-line deposition chambers which incorporate vacuum load locks, and, in some cases, chambers for sequential deposition of several thin films in a single operation. The combination of large substrate size, up to 400x400mm, sequential handling of multiple substrates in succession, and precise and repeatable deposition requirements makes in-line CVD equipment especially complicated and expensive.

For plasma-assisted CVD (PECVD), glass substrates are moved sequentially through in-line, load-locked chambers that are tens of meters long. Substrates are preheated and maintained at temperatures of 300-400°C during deposition. Source gases are introduced for one thin film, deposition occurs, and the panel is moved to the next chamber. In the case of sequential deposition, another film is deposited while low pressure conditions are maintained. The plasma is generated by RF power, typically 13.5 MHz, and 60-70 mW/cm<sup>2</sup> power density. Gases include silane and hydrogen for a-Si films, silane, hydrogen and phosphine for n<sup>+</sup> doped a-Si, and silane/ammonia mixtures for SiN<sub>x</sub> films. Amorphous silicon film properties depend on the incorporation of a controlled amount of hydrogen during the deposition process of 5-15%. Hydrogen atoms tie up dangling silicon bonds, rendering the film stable. Control of hydrogen content is thus an essential element of the deposition process.

Deposition rates are low, typically less than 100Å per minute. Problems include control of film thickness and uniformity over the dimensions of a large substrate,

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particle formation during deposition, and control of sequential formation of undoped, doped, and insulating films in a single deposition step. Equipment uptime and throughput is especially problematic for amorphous silicon deposition.

Sputtering for the deposition of metals is performed using in-line equipment, although batch sputtering and electron beam deposition is still used for ITO, as mentioned previously. Magnetron sputtering technology is well developed compared to PECVD. Metal deposition for aluminum, chromium, tantalum, molybdenum and the other metals used for gate electrode and source/drain lines is possible using the semi-automatic in-line equipment, with either vertical or horizontal transport of substrates. Control of pumpdown conditions is employed to minimize particle generation in this step. Elevated substrate temperature is also employed. In the case of ITO, pass-through sputtering processes, in which the substrate travels continuously past the sputtering target, can be used. Typically, throughput of in-line sputtering equipment is two to three times greater than for PECVD.

## Photolithography

Typically, 6-9 thin film layers are used, with photolithography required at each step. Typical dimensions for the active layer (channel) in a thin film transistor are 3-5µm, and images are obtained with steppers or mirror projection units that can image the large substrate used. Currently, very long photoresist application and etching lines, up to 30 meters in length, are used to process TFT substrates. Standard IC photoresists are employed. Photoresist adhesion is a strong function of the substrate surface preparation prior to coating. Figure 2-10 shows the amount of side etching of photoresist features as a function of etching time[12]. Strong adhesion of photoresist results in a very small amount of side etching. Best results are indicated with a brush scrubbing followed by ultrasonic rinse and baking prior to photoresist application

Although the technology developed for integrated circuit photolithography is applicable to forming thin film transistor arrays, the problems to be solved are somewhat different, and the equipment is tailored to solving these problems. TFT substrates are very large compared to silicon wafers, and full field imaging of a large display is not possible. Instead, the lithography is usually performed in steps which are stitched together to form the array. Specialized steppers have been developed which allow imaging of 10 inch and larger displays.

One major difference between these steppers and those used for IC's is that the

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TFT array is continuous, whereas discrete chips are imaged on a silicon wafer. This means that there are no "streets" between images for TFT production, and the images must be stitched or butted together precisely across the display. Another major difference is the thermal compaction or shrinkage of the glass substrate during TFT fabrication. This change in substrate dimension is a function of the masking step, and the amount of correction required is a function of the distance from the center of the substrate. Controlling the stitching accuracy and accounting for substrate shrinkage require advanced metrology and control hardware and software.

An alternative to steppers for TFT manufacturing is mirror projection, in which an image is scanned across the substrate in continuous fashion. It is necessary to scan the substrate and the photomask as a unit, and the photomask is the same size as the substrate (1:1 projection). The details of stepper and projection equipment are provided in the section on manufacturing equipment.

## Etching

Etching of amorphous silicon, silicon nitride, silicon oxide, and metal films is usually performed by wet etching. Although it is possible to use a batch process, continuous, single substrate process systems are more commonly employed. Dry

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processing is under evaluation for some steps, as mentioned previously for ITO etching. Reactive etching many offer advantages of linewidth control and reproducible end point detection. However, for the time being, throughput considerations ensure that most etching steps will be performed in wet systems.

## **Transistor Processes**

Two types of TFT structures are used for amorphous silicon (a-Si) devices. One is the inverted staggered (IS) type, which can be either back channel etched (IS-BCE) or tri-layered (IS-TL). The other is called a normal staggered (NS) device. These three transistors (IS-BCE, IS-TL, and NS) are shown in crosssection in Figure 2-11.

**Figure 2-11** Cross-section view of three TFT configurations [13]



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The process flow for each of these transistors is shown here, with indications of photolithography and other processing operations. The first flow chart, shown in Table 2-8, is for the inverted-staggered back channel etched (IS-BCE) device.

**Table 2-8** Process Flow Chart forInverted-Staggered Back Channel Etched TFT

Material/Feature	Process
Gate definition	
Mo-Ta	Sputter
1st masking step	Photolithography, etching
a-Si island definition	
SiO/SiN/a-Si(i)/a-Si(n <sup>+</sup> )	Plasma CVD
2nd masking step	Photolithography, etching
Display electrode formation	
ITO deposition	Sputter
3rd masking step	Photolithography, etching
Thru-hole formation	
4th masking step	Photolithography, etching
Source/Drain/Signal Line definition	
Mo-Al deposition	Sputter
5th masking step	Photolithography, etching
Back Channel definition	
n <sup>+</sup> a-Si etching	Wet, dry etching
Passivation	
SiN deposition	Plasma CVD
6th masking step	Photolithography, etching
Array Completed	

The process for an inverted staggered trilayered (IS-TL) device is shown in Table 2-9.

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Material/Feature	Process
Gate definition	
Ta deposition	Sputter
1st mask step	Photolithography, etching
Gate oxide formation	
oxidation	anodization with mask
a-Si TFT deposition	
SiN/a-Si(i)/SiN	Plasma CVD
deposition	
2nd mask step	Photolithography, etching
a-Si island definition	
3rd mask step	Photolithography, etching
Source/drain definition	
a-Si(n <sup>+</sup> ) deposition	Plasma CVD
4th mask step	Photolithography, etching
(source/drain)	
5th mask step	Photolithography, etching
(thru hole)	
Ti deposition	Sputter
6th mask step (metal)	Photolithography, etching
Display electrode formation	
ITO deposition	Sputter
7th mask step	Photolithography, etching
Passivation	
SiN deposition	Plasma CVD
8th mask step	Photolithography, etching
Array Completed	

# Table 2-9 Inverted-Staggered Trilayered TFT Process

The process flow chart for the normal staggered (NS) device is shown in Table 2-10 .

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Гab	le	2-10	Process	Flow	for	Normal	Staggered	TFT
-----	----	------	---------	------	-----	--------	-----------	-----

Material/Feature	Process
Light shield and signal line	
formation	
Cr deposition	Sputter
1st mask step	Photolithography, etching
Insulator Deposition	
SiO, deposition	Plasma CVD or Sputter
2nd mask step	-
(thru hole)	
Display electrode, signal line	
formation	
ITO deposition	Sputter
3rd mask step	Photolithography, etching
TFT formation	
a-Si (n <sup>+</sup> ) deposition	Plasma CVD
Source/Drain formation	
4th masking step	Photolithography, etching
a-Si (i) deposition	Plasma CVD
5th masking step	Photolithography, etching
(island)	
Gate dielectric formation	
SiN deposition	Plasma CVD
6th mask step	Photolithography, etching
Gate electrode definition	
Al deposition	Sputter
7th mask step	Photolithography, etching
Passivation	
SiN deposition	Plasma CVD
8th mask step	Photolithography, etching
Array Completed	

The transistors whose process sequence has been described above are currently being used for LCD TVs or other products in Japan as shown in Table 2-11.

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Manufacturer	Toshiba	Hitachi	Sharp	Matsushita	Hoshiden
Screen size	4-inch	5-inch	3-inch	3-inch	10-inch
TFT type	<b>IS-BCE</b>	IS-BCE	IS-TL	IS-TL	NS
Number of masks	6	9	8	9	8
a-Si thickness	3000Å	2000Å	500Å	500Å	300Å
Gate insulator	SiN/SiO	SiN	SiN/TaO	SiN	SiN
Gate line	Mo-Ta	Al/Cr	Та	MoSi/Cr	Al
Signal line	Al/Mo	Al	ITO/Ti	Al	ITO/Cr
Storage capacitor	Yes	Yes	Yes	Yes	Yes

Table 2-11 TFT Array Process and Specifications

Some previous comments about TFT manufacturing are repeated here for reference. The performance of a TFT as well as the manufacturing yield and throughput depend on the transistor's construction. The inverted staggered back channel etched transistor, (IS-BCE), can be fabricated with the minimum number of six masks, whereas the inverted staggered tri-layered transistor, (IS-TL) requires nine. On the other hand, the IS-TL type has only a 500Å a-Si layer, minimizing the deposition time for this layer. This is important because amorphous silicon deposition is very slow, and can constitute a manufacturing bottleneck when thick layers are required.

Double layer gate insulator structures such as  $SiN_x/SiO_x$  or  $SiN_x/TaO_x$  are commonly used to minimize yield loss due to line or point defects which cause crossover shorts. These kinds of shorts are difficult or impossible to repair.

Specific resistivities of tantalum (Ta), chromium (Cr) or molybdenum-tantalum alloy (Mo-Ta) films used for gate lines and gate electrodes in some of these structures ranges from 20 to  $40 \,\mu \,\Omega$ -cm. These values are too high for large screen TFT-LCDs, since the high resistance and capacitance of the gate line leads to gate pulse delay. For a 12 inch TFT-LCD with 1024x768 pixels and a 16 level grey scale, the resistivity of the gate line should be less than  $10 \,\mu \,\Omega$ -cm. Aluminum is the only appropriate material for such high density displays.

One of the difficulties in transistor design and manufacturing is the need for a storage capacitor to improve the image quality. The storage capacitor adjoins the

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TFT and has an ITO top plate. Charging this capacitor requires that the TFT be relatively large, and the increased area at each pixel devoted to the transistor reduces the amount of light which can be transmitted (aperture ratio). If a second transistor is added at each pixel for redundancy, transmitted light can drop to less than 5% in a finished display.

# 2.2.2 IN PROCESS TESTING

Inspection and repair are common at each step of the transistor fabrication process, and commercial equipment is just beginning to be developed for this application. Table 2-12 shows the cause of defects in TFT array processing. About half of the defects, including severed signal lines and gate line etching defects, might be repaired if they could be located. Current inspection technology focuses on optical microscopy, although electrical testing and non-contact imaging of transistor arrays are under development. Accurate and rapid inspection must be accompanied by information allowing automatic or semi-automatic repair, based on inspection results. Typically, a substrate is moved to a separate repair station, which uses a laser to cut away shorts. Decomposition of organometallic vapors allows the laser to form conducting metal paths around open circuit areas as well.

Defect	Occurrence (% of total)
Severed signal line	26.1
Substrate breakage	24.8
Gate line etching defect	23.0
Faulty transistor characteristics	11.2
Other	14.9

Table	2-12	Defects	in	LCD	TFT Arr	av Ma	nufacti	iring
~		~ 0,0000			** * * * * * * *	ay maa	10170000	" "LA

Source: Toshiba

## **Optical Inspection**

Optical inspection consists of automatic inspection of images after each photolithography step to identify defects in lithography or etching. The equipment used for the process is adapted from automatic or semi-automatic equipment used for semiconductor device or mask inspection. Similar software routines can be used for rapid inspection and defect classification. Generally, the repair or rework of defective sites is performed on another piece of equipment. The information

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needed to locate a defect may be transferred from the inspection equipment's computer to that of the repair device.

Because the patterns consist of small transistors of  $10x10\mu m$  or so in a pixel of  $100x200\mu m$  size, not every defect is automatically a fatal one. This means that sophisticated software routines are needed which allow classification of defects automatically.

## **Electrical Inspection**

Optical inspection is the most common form of inspection during manufacturing. Other types of equipment are under development, including electrical testing during the fabrication process. In silicon circuit manufacturing, the electrical properties of a thin film or implanted region can be tested using test patterns on the wafer, often at several sites across the substrate. These can be probed and electrical evaluation performed. In addition, test wafers specifically evaluate each deposition and doping process.

It is more difficult to perform electrical evaluation on TFT work in process. Test sites are not possible on large area display substrates, and "test wafers" are expensive. In order to perform electrical continuity tests on signal lines and transistor layers, special connectors around the outside of the display pattern must be designed in. These electrical connectors must be separated prior to final assembly. Because of the difficulties involved in electrical inspection, most display manufacturers use redundant transistors at each pixel. After the TFT process is completed, each pixel is addressed. If one transistor is not working, the second one can be "turned on" using a laser to cut a metal trace between the two.

## **Functional Inspection**

Non-contact testing of transistor arrays has recently become possible using an electro-optic modulator which transform voltages on the individual transistors into optical impulses [14]. The modulator forms an optical image of a transistor array which is fed to electronic processing equipment for defect detection. The modulator is indexed across an array and the computer files information on defective sites to be fed to a repair station.

## **2.2.3 DEFECT REPAIR**

Redundancy and repair are two important measures to obtain high yield in TFT manufacturing. The second of these, repair of defects, makes use of a laser to cut

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or deposit metal lines on the display. Simple shorts may be adjacent lines with residual metal between them. These are repaired by laser cutting, using information from the visual inspection equipment which locates the defect. The more serious kinds of shorts occur where one line crosses another. If a short occurs through the insulation separating these lines, there is currently no good way to repair the defect. For this reason, redundant transistors are often built into the array, and if a crossover short renders a transistor inoperative, the second one can be activated by cutting metal lines around the first one.

Open circuit defects are more difficult to repair than simple shorts, and the strategy is to use laser-assisted CVD to deposit metal in selected areas, building a conducting path around the open circuit. Metal-organic vapors are the precursors for deposition, and laser power breaks the molecules apart, causing metal to deposit on the substrate.



# **Display Assembly**

The assembly process for active matrix displays is presented here. The color filter array and thin film transistor substrate are joined together and liquid crystal material is injected into the gap between them. Polarizers are applied to both sides, integrated circuits for driving the display are mounted, and a backlight is installed to complete the operation.

## **2.3.1 ORIENTATION FILM DEPOSITION AND RUBBING**

The assembly process is shown in Figure 12. For each substrate, a thin polymer film is deposited for orientation of the liquid crystal molecules at the glass surface. This orientation film, perhaps only  $0.1\mu$ m thick, may be a polyimide or other "hard" polymer material. After deposition and baking, it is rubbed with fabric in a chosen direction, leaving barely detectable grooves in the surface. There is more art than science in choosing the rubbing material and process. The grooves serve to aid the liquid crystal molecules to align at the substrate surface, and also to assume the proper tilt angle. The latter feature of tilt angle is especially important for supertwist passive matrix displays, for which a high tilt angle provides the high twist of up to  $270^{\circ}$ .

The orientation film can be deposited by spin coating or by printing. The printing method is more efficient in material usage; 70-80% of the polyimide is transferred from the printing roll to the substrate surface.

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Rubbing can be done with a once through cloth on a belt, fed from a roller on one side, passing under roller which contacts the substrate, onto roller on the other side. The substrate moves underneath the cloth in same direction as the cloth. Other methods include a traveling brush that moves across the substrate. The nap of the rubbing material is important.

The mechanism of alignment of liquid crystals by rubbed films isn't well understood. Depending on materials and process conditions, tilt angles of from 1° for low tilt liquid crystals to the 5-10° range are obtained. Using an SEM, researchers can't detect the changes in the surface that are produced by rubbing, but a slight optical anisotropy occurs, which can be detected by polarizing microscope.

The tilt angle is controlled by rubbing pressure and speed. Display manufacturers would like to have greater than 10° for wider viewing angle. The know-how of polyimide selection and rubbing process details constitutes the key to successful LCD manufacturing. STN displays need high twist angle, and aligning the material is difficult. Some polyimide will work in one process and not another. Curing temperature for high tilt polyimide is 250°C, but is 200°C for low tilt. For color STN displays, lower curing temperature is needed.

The cleaning processes prior to and after the orientation film deposition step are perhaps the most critical cleaning operations in the entire panel manufacturing process. At this point, the color filter array on one substrate and the TFT array on the other substrate are completed; any failure to clean the surface thoroughly at this point is even more critical to yield than earlier processes.

## 2.3.2 SEAL PRINTING

After the orientation film has been applied, the substrates are ready for seal printing and lamination. Depending on the size of the substrate and final display size, a substrate may constitute several displays. and a seal is needed around each display. Seal material can be applied more than one way. Typically, silkscreening is used. Finally front and rear substrates are laminated together. Just prior to lamination, spacers are deposited on one substrate to allow a precise gap between the front and rear surfaces. Spacers may be fibers or spheres of a uniform dimension, made either from glass or plastic. Typical large area flat panel displays have a cell gap of  $5-10\mu m$ .

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Figure 2-13 shows the flow of work through an automated assembly line [15]. The illustration shows an assembly sequence consisting of adhesive dispense, required for sealing the panels, spacer application, location and optical alignment of one plate with respect to the other, exposure to cure the adhesive and bond the two glass plates together, which ends the assembly process. Automated transport of both top and bottom plates through the line is indicated; one plate receives the adhesive, and the second plate is introduced at the spacer applicator station.



# Figure 2-13 Automated flat panel assembly line

Screen printing is often used for LCD seal application, but here a programmable X-Y dispenser is employed. In this case, the dispense time can be matched to other process times and multiple heads and sequential machines allow automation of the entire process. A further advantage of dispensing the adhesive, rather than screen printing it, is that contact with the inner surface of the display is avoided, and contamination and degradation of the aligning surface is greatly reduced.

Traditional edge seal adhesives, usually epoxies, have been heat cured after screen printing. The curing removes the solvent, and the resultant  $\beta$ -stage material is dry to the touch, allowing plate-to-plate alignment even when plates are in contact. After alignment, heat and pressure are applied to cross-link the seal polymer. Pressure must be maintained during the cross-linking process so that the proper spacing is achieved. Problems with this process include incomplete

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solvent removal, non-uniform pressure during curing, and movement of plates away from alignment as the seal deforms under pressure.

UV-cure epoxies have some advantages in an automated process, including the low viscosity needed for dispenser application. However, the adhesive must remain wet until the final UV curing step, which introduces some complications into the assembly process. The entire assembly equipment line must be kept in a controlled environment chamber, and plate-to-plate alignment must be accomplished without allowing the plates to touch.

## 2.3.3 SPACER PLACEMENT AND SEALING

In the next assembly step, the second plate is introduced into the spacer application station, and spacers are applied by air scattering. This plate is moved to the initial locator station, which orients it for transport to the optical alignment station. The first plate, with the adhesive, is then inverted, moved to the locator stage, and then to the optical alignment station above the second plate.

Alignment of the two plates is performed using marks etched into one of the conducting layers on each side. Optical pattern recognition and computer control can assure precise alignment. After alignment, the plates are brought into contact, a sealing membrane is lowered, and the space between the plates is evacuated. Clamped together by the outside air pressure, the plates are moved to the curing station for UV exposure. After curing, the assembled plates are off-loaded into a cassette for liquid crystal injection.

Obtaining uniform performance of large area displays requires that the gap between the two plates be very closely controlled. This is especially true for STN displays, where the cell gap may be only 5 $\mu$ m, and gap tolerance is ±0.1 $\mu$ m or even less. This introduces extreme requirements for uniformity of spacer size and for reproducibility of positioning the plates prior to curing. Figure 2-14 shows the schematic relation between variations in spacer size, pressure, and final spacing of the plates. It indicates that a broad range of sizes in spacers will translate to final spacing non-uniformities; the variation of pressure is held to a minimum by employing an evacuated cell and air pressure exerted against the plates and through them to the spacers.

# 2.3.4 LIQUID CRYSTAL INJECTION

In the case where more than one display has been constructed on the substrate, the

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Figure 2-14 Variations in external pressure and spacer size lead to variations in cell gap.

displays are now separated by slicing. At this point, the liquid crystal material can be introduced into the gap between the substrates, making use of a hole left in the seal material. This entrance hole is then sealed, and prepared for final inspection. Liquid crystal materials are often delivered as two or three component systems which are mixed at injection. Injection systems provide mixing and purging of the cell to avoid trapping bubbles during the filling process.

# 2.3.5 INSPECTION AND TEST

Inspection and functional testing are performed after assembly and liquid crystal injection. The causes of rejected cells are shown in Table 2-13. Most defects are related to particles, including point and line defects, and cell gap problems.

# 2.3.6 POLARIZER ATTACH

The final manufacturing step for the liquid crystal display itself is the application of the polarizer to the outside of each glass plate. In some cases, a compensation film is applied prior to the polarizer.

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Defect	Occurrence (% of total)			
Point defect	32.6			
Particles, scratches, dirt	24.7			
Breakage	4.9			
Line defects	7.7			
Faulty cell gap	6.1			
Other	20.4			

 Table 2-13 Causes of Defects in Assembled Flat Panel Displays

Compensation films are polymer films that are stretched in one direction. This stretching changes the optical properties of the film. By combining several films of two or more materials and with different orientations of the stretched direction, many improvements in LCD display characteristics are achieved. This is especially true for STN displays, which have a distinct yellow or blue color unless corrected by a means such as compensation films. True black and white displays can be obtained, and viewing angle is also increased using compensation films. Film materials include polycarbonate and polymethyl methacrylate. The films are usually attached to the polarizer material according to customer specifications about the number of layers, angle of the stretch direction with respect to the polarizer and so forth. The compensator/ polarizer is delivered as a unit to the display manufacturer for attachment.

Polarizer films are composite films which contain the pressure sensitive adhesive layer needed to attach the polarizer to the glass. The direction of polarization is selected for each side of the glass. Usually, if the liquid crystal material has a twist of 90°, then the polarizers will be set at this angle with respect to one another. This allows light passing from one side and rotated by the liquid crystal to pass through the other side, a "normally white" condition. Polarizers are often trimmed to size for delivery to the display manufacturer. They are applied by automated machines which dispense the material from rolls or precut sheets. The machines are variants of labeling machines developed for other industries. The polarizing film is attached to both sides of the display.

The completed display is shown in cross-section in Figure 2-15. The illustration indicates the many materials needed to form the final product.

A completed display will ordinarily have driver integrated circuits mounted on or near one of the glass substrates, usually the TFT side. A variety of mounting
Figure 2-15 Active matrix liquid crystal display cross section. From, "Solving the AMLCD Puzzle", copyright SEMI 1991



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methods are employed, with TAB bonding especially suited for the space and weight saving requirements of flat panels.

# **2.3.7 DIE ATTACH**

Integrated circuit drivers are an important part of a flat panel display, and several dozen circuits may be required to drive the display. Packing these circuits around the display requires special techniques to minimize the space and weight of

Figure 2-16 Packaging configurations in flat panel displays.



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circuits and connectors. A variety of packaging and die attach methods are employed in flat panel display production, depending on the location of the circuits. Figure 2-16 shows three types of chip packaging methods, termed chip on board, (COB), chip on film, (COF), and chip on glass, (COG), respectively. For each of these packages, a different attachment method is used. This illustration and others in this section are taken from a recent presentation by Adachi [16].

The density of pin-outs possible with these three packaging methods is shown in Figure 2-17. Monochrome displays for computer (OA) applications have a pixel pitch of 300-500 $\mu$ m and 500-700 leads per panel side. Personal TVs have a similar number of leads, but a much reduced pixel pitch of 50-200 $\mu$ m. In the monochrome display situation, chip on board packaging is satisfactory, but chip on film must be used for the TV. Similarly, even finer pitch and higher lead count for projection TV for example, will require chip on glass bonding.





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For chip on board assembly, ICs are wire bonded directly to the printed wiring board. Bare chips reduce the area required by the package assembly. The heat seal connector between the printed wiring board and the panel has a pitch limited to about  $260\mu m$ , but advanced patterns of  $100\mu m$  pitch have been achieved with etched copper foil and anisotropic paste connecting the foil to the panel ITO lines.

Currently, chip on film configurations are the most widely used, and TAB bonding is employed to attach devices to the flexible polyimide film. Source driver and gate driver ICs having up to 200 pinouts can be mounted and tested prior to bonding using the TAB approach. Anisotropic conductive adhesive is used to connect the tape carrier directly to the ITO conductor leads. This conductor is resin containing conductive particles dispersed evenly throughout. When heat and pressure bond the TAB tape carrier to the glass substrate, electrical connection is made via the conductive particles only between the copper foil on the tape and the ITO on the glass, as shown in Figure 2-18.





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Chip on glass mounts drivers directly on the glass substrate using some kind of flip chip assembly. This method should allow for the highest possible packing density, as well as minimum weight and volume for the display. However, mounting and repair technology have to be developed to make this assembly method possible. In addition, the method will require more area on the glass substrate itself to allow for chip mounting. Ultimately, the chip on glass mounting method may compete with polysilicon circuit manufacture at the edge of the display. Polysilicon, deposited during display fabrication or formed by annealing the a-Si film in selected areas, can be used for circuits in thin film form. For viewfinders and projection displays, polysilicon circuits on glass offer the ultimate match to fine pitch displays.

## 2.3.8 BACKLIGHT

Backlighting for flat panel displays typically makes use of cold cathode fluorescent lamps that possess the characteristics needed to illuminate the display. These include high luminous efficiency, long life, light weight, and ruggedness. These factors make battery operation possible in portable computers. These lamps are used in pairs along the sides of the display, and a light pipe arrangement is used to create uniform light across a diffuser screen as shown in Figure 2-19. Other arrangements are possible, including the use of a variable transmission curtain [17]. Improvements in backlighting described by Hathaway and coworkers include a flat fluorescent backlight and a wedge-shaped light pipe which distributes the light from a single bulb evenly over the entire display surface.



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# 2.4

# **Display Manufacturing**

## 2.4.1 STN DISPLAY MANUFACTURING

The current "state of the art" production display is the STN, black and white model. Improved versions of this display will include a response speed fast enough for mouse operation, higher resolution, and full color displays. In some ways, improvements in STN technology divert resources and attention from active matrix development and production. However, as liquid crystal displays, STN cells are much harder to make that AMLCDs. If only we can learn how to make the TFTs, everything else is easier.

An STN display manufacturing facility processes displays at a very rapid pace of 120 panels per hour. It is unlikely that AMLCD panel throughput will ever approach this figure. Although STN manufacturing processes are relatively "straightforward", there are many distinct steps. Figure 2-20 shows a schematic representation of an STN line. This figure is adapted from one in a recent book entitled "Liquid Crystals - Fundamentals and Applications" published by Kogyochosakai in 1991 (in Japanese). The process flow is shown beginning with substrate preparation and first cleaning on the upper right. Process areas are numbered sequentially. The details of each process step have been described in previous sections, but actual ambient conditions for processing are shown in Table 2-14. The table lists the temperature, humidity, and cleanliness of the process areas shown in the diagram. ITO deposition, photolithography, orienta-



Figure 2-20 Factory layout for passive matrix LCD manufacturing

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tion film printing and seal printing areas have a particle class requirement approaching that of an IC factory. In other areas, the surface of the glass is not exposed directly to room ambient and a lesser grade of clean room is required.

Process Areas	Temperature (°C)	Relative Humidity (%)	Particle Count (Class)
(4), (6), (10)	23±1.5	30±5	10-100
(3), (9)	23±1.5	40±5	10-100
(7), (11), (12)	23±1.5	30±5	500
(2), (5), (8)	23±1.5	40±5	500
(1), (13), (14), (15)	23±1.5	40±5	1000

 Table 2-14 Clean room Conditions for STN Process Line

Manufacturing yields for STN displays vary from 60% to 80%, with the industry average for large displays near the lower figure. Overall yields are not expected to improve since more complex displays are being introduced into manufacture. Cell thicknesses are going down for improved response speed. ITO linewidth is going down for higher resolution. Color filters and retardation films are being added. The added performance is welcome, but manufacturing is more difficult. Therefore, industry average yields will be static even though yields on more mature products will improve.

STN manufacturing uses proximity printers for imaging the relatively wide ITO patterns for STN displays. These printers are used in lines as shown in Table 2-15. The table also lists some active matrix lines, such as those of DTI.

The reasonable cost and quality of STN displays will make these the displays of choice for the next few years for low cost laptop computers and dedicated word processors. The dedicated word processor is a product that is peculiar to Japan. Until very recently, it was impossible to produce typed or printed documents using the Chinese character set except with extremely complicated mechanical equipment that only typesetters could master. Development of the microprocessor-based word processor including a one or two line LCD display and thermal print head that could produce the characters revolutionized the Japanese office. Further improvements have included the half-page backlit STN display capable of displaying black characters on a white background.

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Firm	No. of Production Lines	Firm No. of Pro	oduction Lines
Sharp	8	Futaba Denshi	4
Toshiba	6	Rohm	3
Hitachi	4	Mitsubishi	2
Hoshiden	4	Optrex	2
Seiko/Epsoi	n 4	Matsushita	1
Casio	4	Akita Seimitsu	1
NEC	4	DTI (Toshiba/IBM)	2

**Table 2-15** Production Lines for Large Liquid Crystal Displays in Japan

The CRTwas never a candidate display for this type of office equipment. Japanese word processors are still rather complicated, but can be used by ordinary office workers. However, like software for word processing on computers, most people know how to use only one product. Each brand expands and improves its products, and the display is a prominent candidate for further improvement.

Expansion of the word processor, laptop computer, and notebook computer markets will be assisted by improved STN displays. These displays will include very high resolution, response speeds suitable for the use of a mouse, and full color display. Low cost will extend their use to other products such as games and pocket TVs. In most of these categories, they are real competition for AMLCD's.

## **2.4.2 COLOR FILTER MANUFACTURING**

The attention of display manufacturers is concentrated on the active thin film transistor formation, while the color filter panel is built on the outside by firms such as DaiNippon Printing and Toppan printing. The color filter matrix consists of 100x300µm rectangles of the three primary colors, formed a single color at a time by standard photolithographic processes. Each color is imaged at 300,000 picture elements across the display. DaiNippon Printing forms the color elements by using a photoresist with colored pigment dispersed throughout, while Toppan Printing deposits a gelatin base that is subsequently dyed the appropriate hue. Neither of these processes is a high volume production process, in the terms required by flat panel display manufacturers. The completed color filter panels are quite expensive, nearly \$200 per display at present, and production for AMLCDs is limited due to relatively low yields.

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The display manufacturers' goal for mid-1990's color filter cost is \$40 per panel, a five-fold decrease from the current price. The pigmented photoresist and dyeing processes will probably be unable to meet this pricing goal. Color filter manufacturers are investigating alternative methods, such as offset printing, to increase the volume and reduce the manufacturing cost, but it may be very difficult to do. In the printing process, for example, alignment of panels from one color to the next is a problem. Also, printed filters don't yet possess the required uniformity of transmission across each pixel. A technical breakthrough is required to provide the registration, color uniformity, low price, and high volume required for flat panel displays. If this doesn't occur, the laborious photolithography technique may limit the number of displays available, and make them high ticket items for the next five years.

## 2.4.3 EQUIPMENT FOR COLOR FILTER MANUFACTURING

The manufacture of color filters makes use of only some of the equipment described in the previous section. Primarily a photoresist operation at present, color filter manufacturing employs proximity photolithography tools and associated photoprocessing lines for coating, developing, etching and stripping. A typical process employs sputtered chrome and four masking steps to produce the three colors plus black matrix. A transparent overcoat protects the filter array after completion. Spin coating is used for applying the materials.

# AMLCD Factory >

## 2.5.1 THROUGHPUT AND PRODUCTIVITY

Throughput of major equipment is shown in Table 2-16. For the most part, productivity is similar to IC manufacturing equipment. Productivity is a problem especially in PECVD, where amorphous silicon deposition is a bottleneck. However, overall yield problems are more serious, and productivity limitations could be accepted if improvement in material quality and yield could be achieved.

Productivity considerations determine the number of units of each item required in a factory. The current equipment list and number of units is shown in Table 2-17. The table shows that the least productive equipment is for PECVD deposition, and, in this hypothetical factory, 5 units are required for a balanced manufacturing line. For inspection and repair equipment and for assembly equipment, the equipment is listed as 1 item here, and the detailed equipment list is shown separately.

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Equipment	Throughput (panels/hr)	Concerns	Price (\$M)
PECVD	20-25	particles	2.50-3.20
Sputtering	45-50	particles	2.2-2.6
Coater/Developer	50-60	photoresist consumption	0.2-0.3
Cleaning	60	-	0.2-0.4
Lithography	35-40	stitching accuracy	1.6-1.9
Wet Etch	60	particles	025-0.35
Dry Etch	20-25	particles	0.5-1.5
Asher	60	particles	0.3

# Table 2-16 AMLCD Equipment Productivity and Price

Table 2-17 AMLCD Production Equipment Categories

Equipment	Number of Units per Fab		
Photolithography	4		
(stepper or projection)			
Photoresist Process Lines	6		
Wet Etching/Stripping Lines	3		
Dry Etching/Ashing Systems	3		
Physical Deposition Systems	3		
(metal & ITO sputtering)			
Plasma-enhanced CVD	5		
(amorphous Si, silicon nitride)			
Panel Cleaning Lines	3		
In-Process Inspection and Repair	1 - equipment list shown separately		
Assembly	1 - equipment list shown separately		
Final Test	1		

Table 2-18 shows the kinds of test and repair equipment required for TFT panel manufacturing. Some of the items are similar or identical to those used for IC manufacture while others are specifically designed for TFTs. Where equipment is specifically designed for TFTs, it is generally not available at the moment, and

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is either being designed or is in prototype form. Not all the test and repair equipment needed for manufacturing has be invented yet, and a continuous flow of new products is expected for the next decade. Multiple items of each category may be required for manufacturing, including optical or voltage imaging for defects.

Equipment	Remarks		
Electrical Parametric Test	Design based on IC test equipment		
Substrate Flatness	Similar to IC equipment		
Sheet Resistivity Monitor	ITO, metal line monitor, off-line and in-situ		
Critical Dimension Measurement	Similar to IC equipment		
Particle Monitors	Similar to IC equipment		
Optical Microscope Inspection	Similar to IC equipment		
Digital/Analog Optical Inspection	Based on mask/wafer inspection of ICs		
Voltage Imaging or	Specific design for TFT arrays		
other TFT imaging	· · · ·		
Laser Cutting	Cut shorted metal lines -combine operation with laser deposition		
Laser Deposition	Metal deposition to repair opens		

 Table 2-18 In-Process Inspection and Repair Equipment List

Table 2-19 is a list of assembly equipment with pricing for each item. The price includes semi-automatic cassette to cassette handlers, but does not include transport equipment from equipment item to equipment item. Equipment for assembly includes the actual joining and sealing of the substrates, separation and final testing, and die attach equipment for placing driver circuits on the completed panel or on flexible circuit boards which are attached to the panel.

# 2.5.2 MANUFACTURING COST AND YIELD

## Yield vs ASP

Yield considerations will be even more important for AMLCD manufacturing than for integrated circuit production. Figure 2-21 shows a simulated yield chart based on differing levels of defect densities and display sizes. This chart, developed by the process consultant N. Yamamura and published in the August, 1990 issue of Nikkei Microdevices, shows the dramatic effect of defect density on yield and cost of color TFT displays.

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Equipment	Price/Remarks
Orientation Film Printer	\$180K
Orientation Film Rubbing	\$80K
Substrate Cleaning	\$120K
Spacer Spraying	\$35
Seal Printing	\$120K
Alignment/Sealing	\$560K includes cassette/cassette han- dling
Liquid Crystal Injection	\$40K
Scribe/Break	\$65
Die Attach Equipment	\$500K for both inner and outer lead TAB bonder

 Table 2-19 Assembly and Die Attach Equipment





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On the left hand side of the illustration is the calculated yield vs display size line corresponding to 0.1 defects/cm<sup>2</sup>. This solid line is about the defect density for small LCD displays, like those used for calculators and watches. It is impossible to build large TFT displays at all with this defect density. The next level of defects, 0.01 defects/cm<sup>2</sup>, corresponds approximately with the current manufacturing practice in Japan. At this defect level, shown by the dashed line, a 10" display yield is about 20% at best, and corresponding display pricing is \$2000 each. A much reduced defect level, 0.003 defects/cm<sup>2</sup>, results in a higher yield curve shown by the dotted line. At this defect density, the next step for TFT manufacturing, a 60% yield can be obtained. This yield might be expected in the mid 1990s, and will result in an average selling price of \$800.

A much lower defect density, 0.001 defects/cm<sup>2</sup>, will lead to yields in the range of 80% for displays, and a corresponding selling price of \$500 each or less. This level of defects, a total of 10 defects per square meter of substrate, is a lower level that is currently achieved in semiconductor manufacturing. Of course, the size of the critical dimension in TFT manufacturing is larger, but absolute defect levels are much more important for displays than for integrated circuits where many chips are manufactured at the same time on the silicon wafer.

## **Manufacturing Cost Model**

A manufacturing cost analysis of a high definition TV factory based on AMLCD displays has been presented recently. According to this analysis, substantial differences exist between flat panel display and IC manufacturing. A written presentation by G. Resor, entitled "The Surprising Economics of Flat-Panel Production", was published in the Society for Information Display Technical Digest, p186, 1990. One of the principal differences between AMLCD and IC manufacturing is the optimum factory size, which is relatively small for displays at about 500,000 starts per year. Another difference concerns the relative importance of the cost of capital and materials. For integrated circuits, especially cost competitive products such as DRAMs, the initial investment dominates all other costs. For displays, the situation is quite different, and materials costs are dominant. Figure 2-22 shows the cost breakdown for a "minifab" with 500,000 display starts per year. The factory product in this case is a completed 14 inch high definition television. The cost analysis indicates that material costs account for more that 50% of the total, with depreciation and R&D costs at less than 10% each. The factory price of \$862 per completed TV applies to the fifth year after the start of the project, and the factory is still ramping up production. After ten

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years of operation, production costs have declined to levels competitive with CRT-base TV sets, but materials costs continue to dominate.



## **Manufacturing Yield Model**

A comparison of TFT-LCD manufacturing to DRAM manufacturing reveals significant differences. (See R. R. Troutman, "Forecasting Array Yields for Large-Area TFT-LCDs", Society for Information Display Technical Digest, 1990, p197) Partially good displays are not acceptable, and the probability of a fault must be small over a large area. A Poisson distribution is used to analyze and predict the yield in this situation.

The most common single cell fault is a pinhole short in a storage capacitor because of the large area of the capacitor. The resulting high leakage path produces a fixed ON or OFF condition, depending on voltage and polarizer settings. Another single cell fault is a source to drain short in the data metallization, which prevents charge transfer. A Poisson distribution of faults is constructed, and it is assumed that a few single cell faults are tolerable, as long as they are not clustered. If 10 single cell faults are allowed, then the yield is 100% at 10 faults, about 50% at 12 faults, and 20% at 15 faults. However, to ensure 99% yield at 10 allowable faults, the average number of faults has to be fewer than 5 per array.

Faults other than single cell faults are intolerable, and must be repaired. If a gate

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or data line is open, it is easily detected by an electrical continuity check. Repair consists of laser welding a spare line driver to the initially undriven end of the line. An interlevel short is repaired by laser cutting either the gate line or the data line and then treating the cut line as an open line. Two types of repairability are described.

Type 1 repairability is the case where gate line repairs are made only for open gate lines. In displays using the inverted staggered TFT structure, the gate is buried under several thin film layers, and laser scribing these lines might cause a yield loss by itself. Data lines are more accessible, and data line repair options cover both open lines and interlevel shorts.

Type 2 repairability assumes a high yielding technique for scribing gate lines in the array. Type 2 repairability is significantly better than Type 1 only when there are many spare gate lines available to repair interlevel shorts.

Total array yield is the product of single cell fault yield and repairable fault yield.  $Y_{tot} = Y_{sc}Y_{rf}$ . If the single cell fault yield can be raised to 99%, then the overall yield is determined by the repairable fault yield. Table 2-20 shows the relation between yield, defect size, and defect density without repairability. The calculation is performed for a 640x480x3 array, and assumes an average defect size of 1µm.

Yield	Faults/Display	Faults/cm <sup>2</sup>
10%	2.3	0.24
50%	- 0.68	0.072
90%	0.10	0.01

 Table 2-20 TFT Array Yield Summary (No Repair)

Consider a 1Mbit DRAM line operating at 50% yield. For a chip area of 0.5cm<sup>2</sup>, the allowable fault density is 1.5/cm<sup>2</sup>. Compare this to the value of 0.072 from the table, and one sees that without repair, the fault densities for a TFT array must be 21 times lower than for current DRAM manufacturing.

Repairability of the data lines and gate lines can significantly improve the yields. By providing 5-10 extra lines for repair, the major challenge to achieving high yields is interlevel (crossover) shorts. This fault type must then be maintained below 1 fault/cm<sup>2</sup>.

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## **AMLCD Factory**

The NEC Kagoshima plant in Kyushu is manufacturing 10" flat panel TFT displays, and has achieved 50% manufacturing yields, according to an article in the August 1991 issue of Nikkei Microdevices. The yield might go as high as 70% in certain instances. The plant is inputting 5000-7500 substrates per month, which, on the 300x350mm substrate, comes to a potential 10,000-15,000 10" displays per month. Factoring in the yield, output is 6000-9000 displays per month.

The manufacturing equipment is interconnected only where this is easy to do. Substrates are transported around the factory by automatic ground vehicles. These vehicles, which are provided with HEPA filters, are used to transport the heavy 20-substrate carriers, and to avoid particulate contamination which would occur if an operator performed the transport. Operators are used to load carriers onto the equipment, which may be an in-line series of individual processes. Equipment such as for photolithography is not fully interconnected. Computers are used to control the operation and collect information regarding machine performance.

NEC has made a high yield process using their LSI experience, and finds the process quite similar to LSI. They don't understand the cause of the yield problems in TFT fabrication reported at other companies. In NEC's opinion, the cell assembly process is a much stricter and more difficult to control process. The TFT manufacturing equipment is very like the LSI processing equipment already in use at most companies who are making TFT's, and the equipment is made by large, reliable companies. In contrast, the equipment for cell assembly is made by small and medium sized companies, and may not be available.

Figure 2-23 shows the floor plan of the factory. The upper floor contains the TFT panel fabrication area. This area is composed of lithography, cleaning, sputtering, CVD and so forth. An elevator connects this floor to the assembly area below. The floor space for the clean room is 40mx90m, and the total area is 4000 m<sup>2</sup> per floor. 20% of the clean room is class 100, 20% is class 1000, with the rest class 10,000. For the lithography area, class 10 is used. In the cell assembly area, the equipment and processes that generate particles, such as the rubbing equipment, are enclosed.

Right now, completed TFT panels are sent downstairs, and purchased color filter panels are started into the cell assembly process. Module assembly, with back-light occupies 2000 m<sup>2</sup> in another building.

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Figure 2-23 NEC two story AMLCD fabrication facility layout

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The factory is operated with 250 people on three shifts. In addition to the operators, there are 100 additional staff, and of these, 70 are technicians. 25-26 are LCD specialists, and the others are from the semiconductor process area. New technology transfer takes 3-6 months.

The TFT area has room for expansion to 10,000 substrates per month. It has been converted for 10 inch panel manufacturing. New equipment was installed and pilot manufacturing was initiated. The biggest problem was with the lithography and plasma CVD equipment. Then, Nikon stepper equipment was adopted. Each panel requires 4 exposures. Stitching accuracy is  $0.2\mu m$ . Defect inspection equipment has not been chosen yet. The operation rate of the equipment has reached LSI levels. 4 stepper lines are in operation.

Anelva supplied the plasma CVD equipment for 3 lines. Due to particle buildup, thorough periodic maintenance is required. Uptime of 50% is achieved. There are 3 sputtering lines and 5 dry etching lines, also from Anelva. Resist coating lines come from Dainippon Screen. Particle inspection equipment is from Hitachi Engineering.

The 4096 color display produced at this factory has a diagonal measurement of 9.8", with 640xRGBx400 lines. Each color pixel measures 0.11x0.33mm<sup>2</sup>. Contrast is 80:1. A 20:1 contrast ratio or greater is maintained for a viewing angle of ±20° vertical, ±35° horizontal. Response speed is 20ms. Brightness is 80cd/m<sup>2</sup>. Backlight power consumption is 12 W. TFT design employs a bottom gate construction, with a 2-layer, ITO/Cr construction. Gate insulator is SiO<sub>2</sub> plus Si<sub>3</sub>N<sub>4</sub> deposited by plasma CVD. Gate line and data line metal is chromium, and transparent electrode is ITO. The gate electrode, channel, dielectrics and so forth are dry etched. Defective pixels number 10 or less in completed displays. Defective blue pixels are most easily detected, and two defective blue pixels can reject the entire display. As the level of cleanliness of the clean room improves, the defect level is expected to decrease.

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# **Materials for Flat Panel Displays**

The particulars of materials for flat panel displays are presented in this part of the book, emphasizing the unique requirements for active matrix displays. In many cases, the ultimate combination of materials performance, quality and price has not yet been achieved. Particularly for color filters, significant cost reduction is essential for high volume manufacturing. For other materials, cost effectiveness is determined primarily by beneficial effects on transistor manufacturing yield.

## **Glass Substrates**

Glass substrates of various types are used for liquid crystal displays. Substrate types were discussed in Part 2, with emphasis on fusion glass as an active matrix substrate. This section describes float glass manufacturing and ITO deposition.

Advantages of float glass material were pointed out in a recent article by Pilkington Micronics [1]. Flat glass was made by drawing processes until the advent of the float process, in which molten glass is allowed to settle onto a bath of molten tin. The glass achieves a uniform thickness with smooth surfaces on both sides. Stringent glass specifications are required for LCD applications in spite of the fact that this constitutes less than 1% of the world-wide flat glass market.

Some difficulty in obtaining the tolerances on glass properties, especially surface smoothness, arose from processing float glass for LCDs in the same furnaces used for architectural and other purposes. These furnaces might have a production capacity of 5000 tons per week, enough to satisfy the world market for LCD applications in a few days. By moving the float glass manufacturing for LCDs to a small dedicated float line, materials specifications were improved.

Float lines can produce 3 meter wide continuous ribbons with thickness variations of  $\pm 0.1 \mu m$ , negligible warp, and microcorrugation controlled to averages of less than 0.1 $\mu m$ . On-line CVD processes are also used by this glass manufacturer to provide SiO<sub>2</sub> coated surfaces. Characterization of microroughness will allow classification of substrates, and reduced polishing of selected classes of glass can be achieved for STN applications. Eventually, float glass suppliers hope to eliminate the polishing process completely.

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Processing the base glass substrate into a form useful to the display manufacturer is a multi-step process, with several Japanese firms offering services at each step. Table 3-1 shows the types of operations for LCD glass and suppliers at each step. Processes for SiO<sub>2</sub> and ITO coating are indicated. Various glass fabricators supply material to several firms for cutting and polishing. SiO<sub>2</sub> coating may be done be another firm, and ITO by a fourth.

Bare Glass	Cutting/Polishing	SiO <sub>2</sub> Coating	ITO Coating
Asahi Glass	Kuramoto	Matsuzaki	Matsuzaki
NSG	Fujimi	(dipping) Tokyo Ohka (dipping)	(sputter & evap.) Asahi Glass (sputter & evap.)
Central Glass	Mitsuru	Kuramoto	Sanyo Shinku <sup>*</sup> (sputter)
N.E.G.	N.E.G. (BLC & OAZ type	Asahi s)	NSG CVD Central
			Seiko Epson Sharp
			Optrex Sputter
Corning			-

 Table 3-1
 LCD Glass Supplier Matrix in Japan



# **ITO Sputtering**

ITO sputtering is a crucial and ubiquitous part of the flat panel display industry. The material is deposited from a sintered powder source to a thickness of 1500-3500Å. Important deposited film properties are transparency, resistivity, and ease of patterning. Transmittance of 90% and resistivity of 1-3 $\mu$ ohm-cm are normal values for these properties. These are a sensitive function of the oxygen content of the film, and oxygen is often added in the gas stream during sputtering, to make up for any loss of oxygen during transport from the ITO target to the glass substrate. Deposition temperature is a critical parameter of the process.

The higher the deposition temperature, the lower the resistivity of the film. Previously, a glass substrate temperature of 300°C was common for ITO depo-

\* 100% Sharp subsidiary

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sition, but 200°C is necessary for color LCD displays, where the polymer color filters cannot withstand the higher temperature. Lower temperature deposition has been made possible by the new, higher density targets, which can provide uniform deposition at higher magnetic fields than the previous model, which allows for lower deposition temperatures. Table 3-2 shows film properties of deposited films. Ulvac has described a process for low temperature sputter deposition which provides resistivities as low as 5  $\Omega$ /square.

<b>Deposition Conditions</b>	Resistivity/Resistance	Application
350°C, 1000Å, e-beam or sputtering	1.5x10 <sup>-4</sup> ohm/cm	B/W STN ~20 ohm/ square
200°C, 1000Å, e-beam sputter	2x10 <sup>-4</sup> ohm/cm	Color Filter (requires or 2000Å for 10 ohm/
Ulvac - new system 200°C sputter	1.2x <sup>-4</sup> ohm/cm	As low as 5 ohm/square is possible at low temp- erature for color filter

 Table 3-2 ITO Film Properties

ITO targets are usually prepared in the form of rectangles about 15"x5" in size, about 6 mm thick. The material is usually cold-pressed, then sintered after isostatic pressing. Usual composition of the target is  $10 \text{ wgt}\% \text{ SnO}_2$ . After machining to the correct final size and shape, the ITO material is bonded to a backing plate using some form of indium or indium alloy bonding preform. Table 3-3 shows the currently available target densities available from suppliers. The higher density material is more difficult to prepare, but provides longer target life and fewer deposited InO black particles.

	Table 3	3-3	<b>Characteristics</b>	of $I$	ΤO	Targets
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Density	InO black particles	Target Life (using high density life as ~100%)
Low (70%)	most	70%
Medium (80%)	some	80%
High (95%)	fewest	~100%

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Sputtering processes consist of bombarding a material such as ITO with energetic argon ions. These ions dislodge atoms from the target, and these atoms travel to the substrate under the influence of electric and magnetic fields. If the composition of the target is non-uniform, less desirable results can occur. These include non-uniform sputtering across the target, which shortens its useful life. In addition, non-uniform density or composition can lead to absorbing particle formation.

The rectangular target is used in large batch or in-line sputtering equipment made by a variety of suppliers in Japan, including Ulvac, the largest commercial supplier, Anelva, Asahi Glass (makes equipment for their own use), and Shinku Kikai. For very large systems, the targets can be used two at a time, forming a one meter long sputtering source. Glass panels have a wide range of sizes, both because many products may be prepared in a single factory, and also because no standard sizes have been developed by the manufacturers.

Erosion of the target by the sputtering process is not uniform, and an elliptical cavity is etched out more or less in the center of the rectangle. Because a lot of ITO is left in an unusable form at the end of life of the target, and because the material is somewhat expensive, there is some interest in reclaiming the targets.

Film properties may be enhanced by annealing in air after deposition. Subsequent patterning and etching forms the transparent electrodes whose function was discussed in the previous section.

ITO sputtering is mostly done by glass coaters, primarily Matsuzaki Shinku and Asahi Glass. Glass can be supplied in coated form, except for the panels used for the active matrix TFT backplane. These are ITO coated after transistor fabrication, and this will be done internally at the display manufacturer.

Requirements for glass type, ITO thickness and other parameters vary according to the type of display being produced. Table 3-4 is a summary of the types of displays, ITO resistivity, deposition methods, and type of substrate.

# **3.2.1 ITO POWDER AND THIN FILM PROPERTIES**

ITO targets depend on powder formulations of consistent particle size and shape, as well as adequate purity. Powder sources are Nippon Mining and Mitsui Metal Mining, with some material produced by Dowa Mining and Osaka Asahi Metals, and perhaps Sumitomo Metal Mining for internal use. Nippon Mining and LIQUID CRYSTAL FLAT PANEL DISPLAYS

Application	Resistivity (ohm-cm)	ITO Deposition Method	Substrate Type
TN (twisted nematic)	100-200	Electron Beam (200°C)	Soda-lime, SiO <sub>2</sub> coated
STN (supertwist)	15-100	Electron Beam (300°C)	Soda-lime, SiO <sub>2</sub> coated
STN (newer type)	10	Sputter (300°C)	Soda-lime, SiO <sub>2</sub> coated
Active Matrix	10	Sputter (300°C)	Low-expansion
Color filter	10	Sputter (<200°C)	Low-expansion

**Table 3-4** Glass Substrates for Liquid Crystal Displays

MitsuiMining may sell a portion of their powder production for outside use, and Tosoh is currently buying powder from one of them. But each of these is concentrating on the target market.

Typical properties of ITO target material are shown in Table 3-5.

Matsuzaki Shinku is the primary glass coater in Japan, and uses equipment made by Shinku Kikai. Asahi Glass makes their own equipment. Neither Shinku Kikai nor Asahi attempts to make the target material. This is in contrast to the older technology of sputtering ITO from indium-tin metal alloy targets, using an oxygen ambient as the source of oxygen in the film. In that case, the user could make his own target in a crucible by melting the proper amounts of metal. The other supplier of equipment of note is Ulvac, with a captive target supplier, VMC. VMC is the largest supplier of targets for the semiconductor industry in Japan, but is just beginning ITO target development.

# Other Sputtering Materials



Metals used for TFT fabrication are deposited by sputtering, using similar or identical equipment as for ITO. Chromium is used for black matrix formation on the color filter portion of the display in most current processes. For TFT

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Property	Value
Composition	10 Wgt% SnO <sub>2</sub>
Actual Density	$6.07 \text{ gm/cm}^3$
Percent Theoretical Density	95%
Bulk Resistivity	0.22 mohm-cm
Thermal Conductivity	19.55 mcal/cm-sec°C
Tensile Strength	12.8 kg/mm <sup>2</sup>
Bonding Material	In, In/Sn, In/Bi
Bond Void Ratio	<2.0%
Deposited Film Properties	
Thickness	1500-3000Å
Resistivity	<20 ohm/square
Optical Transmission	>85%

 Table 3-5
 Specifications for High Density ITO Target

manufacturing, the materials choices are aluminum, tantalum, molybdenum, tungsten or other refractory metals for the gate lines. Source and drain metallization is primarily aluminum, with underlayers of molybdenum or other refractory for diffusion barriers. The metallurgy of thin film transistors was described in Part 2. Other than the form factor of the sputtering target, requirements for these metals appear to be identical to those for semiconductor applications. Also mentioned in Part 2 is research to develop sputter-deposition of silicon for the thin film transistor material itself.



# **Color Filters**

Color filter applications began with manufacture of pocket sized TV which appeared on the market in the mid-1980's. The filter was made by the dye method, and its spectral properties equalled those of the CRT [2]. This method and its companion, pigment dispersion, were scaled to meet the size requirements of notebook computers. Required properties of color filter material include those shown in Table 3-6. Color filter materials such as dyes and pigments are supplied by companies such as Dainippon Paint, Dainippon Ink and so forth. Specialized formulations of polyimide with dissolved colorants are available from Toray and Brewer Science.

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Property	Comment			
Spectral property	Colors of red, blue and green filters should be close to CIE chromaticity of CRT			
Contrast ratio	Loss of light should be minimal			
Uniformity	Spectral properties should be uniform across the surface of the array			
Flatness	No foreign objects or projections. (most severe restriction on STN filters, $\pm 0.1 \mu m$ )			
Defects	No foreign object, pin-hole, crack or dirt			
Dimensional accuracy	Sufficient to align substrates easily			
Thermal stability	Resistant to cell sealing and polarizer application process (250°C, 1hr target)			
Chemical resistance	No discoloration, swelling, separation or creasing during cleaning or ITO etching processes.			
Reliability	Temperature extremes and thermal shock (80°C to -30°C), and temperature/humidity resis tance (40°C + 95% RH)			
Light stability	Resistant to bleaching in ambient light			

 Table 3-6 Properties of Color Filters

Test conditions for color filters are summarized in Table 3-7.

## **3.4.1 DYE METHOD**

Presently the dyeing method is the most widely used technique. Its materials and processes are both well established, with reproducible spectral properties. However, the use of dyes and water soluble polymers as binders pose some problems, resulting in poor resistance to heat, light, and chemicals. The way around this results in increased process complexity. Patterning and dyeing of each color plus other steps such as substrate cleaning and drying result in a process with a total of 40-50 steps of various types. For example, the water soluble polymer such as gelatin is made photosensitive, exposed with UV light, and then the pattern is developed. This sequence is accomplished using equipment similar to the photolithography equipment in the semiconductor industry. Next, the relief pattern is dyed by acid or reactive dyes. Because the optical density of the dye is influenced by the degree of polymerization of the resin, and because the film thickness varies depending on the dyeing process, control is necessary for each

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Test	Equipment	Treatment Condition	
Thermal stability Thermal stability (long term)	Oven	180-200°C, 1hr 80°C, 500hr	
Thermal Shock	Environmental Testing Machine	-30°C, 50hr 40°C, 95%RH, 420hr. -30-80°C, .5hr 20 cycles	
Light stability	Xe-Fademeter	200-500 hr	19. d - Carlon M <b>Carlos and Anno 19. a</b>
Chemical resistance		Dipping 10-30min	IPA Xylene Butyl Acetate NMP Butyl Lactate NaOH (5%) H <sub>2</sub> SO <sub>4</sub> (5%)
		60°C, 30min Supersonic Wave 5min	H <sub>2</sub> O IPA H O
		Vapor 5min	IPA Fluorocarbon

 Table 3-7
 Test Conditions for Color Filters

dye lot, its stability over time, and its optical density. Some investigation is being made to replace the water soluble resin with acrylic resin. In order to prevent the mixing of colors, it is possible to use an intermediate hardening step after each filter is formed, and also an intermediate transparent passivation layer is sometimes deposited separately over each color element.

Toppan is investigating offset printing as a low cost replacement method of production color filters arrays, and has presented comparison of properties of filters produced by different methods. Figure 3-1 shows the CIE chromaticity diagram for color filter arrays made by dyeing, pigment dispersion, and printing. The chromaticity coordinates are close for each of the methods, and indicate that good color balance can be achieved with these methods.

Transmittance of each filter element as well as resistance to fading is shown in

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Figure 3-2, comparing dyed and printed filter elements. Printed filters show increased resistance to fading.

**Figure 3-1** (Below Left) *CIE Chromaticity Diagram for color filters made by dyeing, pigment dispersion, and printing* 



**Figure 3-2** (Above center and right) *Resistance to fading of dyed and printed color filters* 

Certain problems have to be solved in order to make printing the practical production process for color filters. These include the registration of the filter array in the direction in which the print head rolls. Registration along the axis of the ink roller is easy to do. The surface tension of the ink causes it to tend to form a spherical shape when printing the 100x300µm rectangles. Figure 3-3 compares the cross-section of a spin-coated filter element with a printed one. Some of the non-uniformity which results from this droplet shape can be accommodated by the black matrix around each pixel.

In the end, even relatively high volume production will be accompanied by retouching of panels. Automation of the inspection and retouching process will be of paramount importance to improve manufacturing yield.

# **3.4.2 PIGMENT DISPERSION**

There are various methods for dispersing a colorant in resin, and one method uses PVA steel stilbazolium negative type photosensitive resin [3]. It is a clear, water

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Figure 3-3 Comparison of spin-coated and printed filter element

soluble resin. Under UV exposure, the double bond of the steel stilbazolium base forms a cyclobutane ring which cures by crosslinking. High sensitivity is retained after dispersion of the colorant. Pigment is used as the colorant, but generally available pigments are in large, coagulated particle form, and transparency is inadequate in this form. Therefore, the coagulated resin is refined and a dispersing agent is added to prevent coagulation. The viscosity is then adjusted and any large particles are removed by filtration. This mixture is added to the steel stilbazonium photosensitive resin. Viscosity adjustment and filtration are then performed on this final mixture.

Pigment particle size averages  $0.04\mu m$ , with a maximum of  $0.2\mu m$ . Non-ionic dispersing agents are employed. Figure 3-4 shows the transmittance of green pigment material as a function of pigment particle size. The small average particle size of  $0.04\mu m$  assures high transmittance.

The repetitive process for color filter formation using photolithography is employed, and each color element is resistant to subsequent processing. For this reason, a neutral passivation layer is not required between each color. After the color filter array is formed, a transparent overcoat is applied, followed by ITO deposition. Good stability of color arrays has been achieved.

Other types of resin materials can be used for pigment dispersion color array formation. These include an acrylic photosensitive resin, developed with alkali developer, and thermally polymerized. The polymerization reaction is suppressed when carried out in the presence of oxygen. Exposure is made in a nitrogen environment from which the oxygen has been removed.

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It is also possible to disperse pigment in non-photosensitive materials such as a polyimide. Positive photoresist is used for patterning.

Electrodeposition is another method for color filter formation. In this case, an ITO pattern is covered by a colorant such as polymer dispersed pigment. Electrophoresis, which has been used for automobile body painting, can be used. Normally, anionic deposition is performed in aqueous solution, but solvent media can also be employed. A highly crystallized ITO layer with resistivity of 20  $\Omega$ /square or less is required. The ITO electrode is patterned, **Figure 3-4** *Transmittance of green pigment material as a function of pigment particle size* 



and colors are electrodeposited one at a time. In this case, the black matrix cannot be formed from Cr thin film deposition that is used in dyeing or pigment dispersion processes. Alternatively RGB filters can be formed without patterning the ITO, using photoresist to mask each color.

Other kinds of color filter formation methods have been suggested, including multilayer interference films. This method has been used for image pick-up tubes, but because of a lengthy production process, the cost will probably be too high. It may have applications in projection type displays [4]. Alternative methods are listed in Table 3-8. The color filter pattern can be mosaic, triangular or striped, with pixels of 80-100 µm size.

 Table 3-8
 Alternative Methods of Color Filter Formation

Multilayer interference film Color Evaporation Alumite coloring Sublimation transfer Photographic coloration Lenticular Electromist

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The color filter spectral characteristics must be matched to the particular backlight being used so that the overall chromaticity matches that of the CRT as closely as possible. The color filter material must not elude ionic contaminants into the liquid crystal cell or otherwise adversely affect the liquid crystal material.

## **3.4.3 ELECTRODEPOSITION**

Nippon Paint has developed an electrodeposition process for color filter manufacturing on unpatterned ITO [5]. The process makes use of a single positive photoresist application at its beginning. The photoresist is sequentially developed to allow the red, green, blue filter elements to be deposited. Finally, the photoresist is removed and a black border material composed of a mixture of the three colors is electrodeposited.

The process is shown schematically in Figure 3-5. The glass substrate is coated with ITO and photoresist, then patterned with UV light for the first color filter layer. After heating, the first area is developed with alkaline developer such as NaOH. The, the next two color filter patterns are formed in the same way, one at a time. Finally, the photoresist is removed, and the "black" material is plated in the areas between filters, a shown in the figure.

A new type of photoresist was developed for this process. The standard quinone diazide material lost its sensitivity after the process sequence of electrodeposition, alkaline development, and heating. This required the application of a new photoresist coating after each electrodeposition step. On the other hand, the new positive material, coated to a uniform thickness of  $2\mu m$ , was exposed with 254nm UV light,  $30mJ/cm^2$ , and developed with 0.5% sodium hydroxide solution.

Color filter materials are water dispersed resins. Initially, anionic resins were used, but when a second color was developed, the one that preceded it dissolved in the alkaline developer. Cationic resins were evaluated, but initially these caused the ITO film to turn yellow. New cationic materials solved this problem, and allow heating of the electrodeposited film at 100°C for 10 min in alkaline solution without dissolution. An emulsion of red, blue or green pigment is dispersed, and average particle size is less than 400nm.

The ability to strip the photoresist, leaving the color filters cleanly exposed at the edges, allows the final electroplating step of the black matrix, a composite mixture of red, blue, green pigments. Carbon black dispersions were also evaluated.

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Color filter production by electrodeposition is reported to be very slow, requiring many hours for each color. On the other hand, plating equipment is rather simple and inexpensive, and the process shouldn't need constant monitoring by production personnel. The process requires that ITO be deposited on the glass substrate prior to the color filters. This may preclude its use for AMLCD displays. When the cell is assembled, there is an added voltage drop compared to cells where the ITO is over the color filter material, caused by the high resistivity of the color filter material itself. This extra voltage drop is hard to accommodate in the active matrix scheme.

## **3.4.4 ELECTROMIST**

Color filter material is deposited from a mist whose droplets have been charged to a few volts potential [6]. The color material is deposited directly onto the TFT pixel by addressing the TFT with up to 10-20V potential. Up to 30V can be placed across the TFT without damaging it. The color pigment deposits on the ITO layer over each pixel. No masks are required and three colors can be sequentially deposited in one step. A wide variety of color filter materials can be used, including inks, polyimides and sublimable dyes. The resolution of 160µm is better than currently required pixel pitch.

The apparatus consists of an ultrasonic mist generator, a drop size separator which produces  $3\mu m$  nominal size drops, and a chamber in which the droplets are charged with an AC voltage. This method allows up to 0.008 coulombs/kg charge

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to mass ratio, much larger than achieved with DC charging. Positive air ions are formed at a DC corona wire and the droplets are swept out of the chamber in the air stream, which passes over the ITO coated substrate. The pixels are charged and drops deposit only on the pixels with negative charge. The deposition is self-limiting, reaching a thickness of  $2\mu m$ .

## **3.4.5 OVERCOAT**

Clear plastic material used over color filter material to protect color filter array, and to planarize the surface for ITO deposition. The ITO layer is relatively thin and cannot conform to feature thickness variations.

## 3.4.6 TWO COLOR APPROACH

Based on the work of Edmund Land, full color perception is possible using only two colors instead of three [7]. For example, a red/white pixel arrangement might produce the perception of full color with only 2/3rds the number of individual pixels and associated connections and driver circuits. The observations are especially relevant to automotive displays in terms of simplicity and cost.



# **Process Chemicals & Gases**

Process chemical and gas requirements are very similar to those for integrated circuit manufacturing. Since tremendous strides in liquid and gas purity have been achieved for semiconductor applications, these can be adopted directly for flat panel display manufacturing.

In general, organic solvents are more widely used in processing liquid crystal displays, since the many organic polymer layers are soluble only in organic solvents. In addition, cleaning solutions often must be organic as well. Table 3-9 shows the properties of common organic solvents used in this application. This table and others in this section are taken from a recent handbook of LCD processing [8].

Improved purity in terms of lower particle levels has been the subject of active development at suppliers of semiconductor chemicals. Table 3-10 shows typical particle counts as a function of size for common process chemicals. The most important process chemical is the rinse water, supplied by an in-house system. Semiconductor grade water supply systems show performance like those of the firms in Table 3-11.

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Chemical	Formula	Boiling Pt. (°C)	Solubility in Water	Solubility in Alcohol
Acetone	CH <sub>3</sub> COCH <sub>3</sub>	56.5	Soluble	Soluble
Methanol	CHJOH	64.56	Soluble	Soluble
Ethanol	C,H,OH	78.3	Soluble	Soluble
n-propanol	CH,CH,CH,OH	97.2	Soluble	Soluble
i-propanol	(CH <sub>3</sub> ) <sub>2</sub> CHOH	82.7	Soluble	Soluble
o-xylene	$C_6H_4(CH_3)_2$	144.0	Insoluble	Soluble
m-xylene	0 1 5 2	139.0	Insoluble	Soluble
p-xylene		138.0	Insoluble	Soluble
Trichloroethylene	ClHC=CCl <sub>2</sub>	87.0	Insoluble	Soluble
Tetrachloroethylene	CCl <sub>2</sub> =CCl <sub>2</sub>	121.0	Insoluble	Soluble

 Table 3-9
 Solubility of Cleaning Chemicals

<b>Table 3-10</b>	<b>Particles</b>	in Electron	ic Chemicals
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	Particle Size Range (µm)					Total
Chemical	2-5	5-15	15-25	25-50	>50	#/100cc
Trichloroethane	150	119	22	9	4	304
Acetone	172	90	8	8	0	278
Methanol	406	483	17	11	1	618
Xylene	203	43	12	4	1	263
Isopropanol	856	600	152	60	10	1678
Nitric Acid	3362	1627	204	38	3	5234
Hydrogen Peroxide	894	420	12	6	1	1333

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Property	Company A	Company B	Company C	Company D	Company E	Average
Resistivity (M $\Omega$ -cm)	>18	>15	>16	>15	>10	>16
Particles/liter	<150	<150	<100	<150	<100	<130
Particle size (µm)	< 0.5	< 0.5	<0.5	< 0.5	< 0.5	< 0.5
Dissolved gas (ppm)	-	<200	-	<200	<200	<200
TOC (ppm)	<1.0	<1.0	<1.0	<1.0	<1.0	<1.0
Bacteria (colonies/liter)	-	<8	<10	-	<10	<9

## Table 3-11 DI Water Quality

Cleaning efficiency can be measured in a number of ways, including the contact angle measurement described in Part 2. Other ways of determining cleaning efficiency are shown in Table 3-12. These include static friction measurement. The higher the value of static friction, the cleaner the surface; contaminants such as organic films reduce friction. Another test is the LC chromatograph, for which the lower values indicate the highest cleanliness. Liquids such as hot water and acid provide the cleanest surface except for argon bombardment. Unfortunately, the material being cleaned will often react with these chemicals. In addition, acids tend to have a higher level of suspended particles, requiring careful rinsing and handling.

• • • • • • • • • • • • • • • • • • •	Measurement Method				
Method/Material	Wetting	Static Friction	LC Chromatograph		
Methanol		0.41	0.7		
Neutral Solution		0.39	0.41		
Proprietary Chemical	Wetting	0.38	0.21		
Hot Water	Wetting	0.53	0.17		
Acid	Wetting	0.77	0.05		
Argon Ion Bombardment	Wetting	0.63	0.03		

**Table 3-12** Measurement of Cleaning Efficiency

Gases include deposition gases for chemical vapor deposition of amorphous silicon, silicon nitride, and silicon dioxide. Primary source gas is silane, with hydrogen as background gas in some cases for control of hydrogen content of deposited layer.

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# Photoresists

3.6

Positive and negative resist materials were recently evaluated for LCD applications using ITO coated glass substrates and an MRS panel printer for exposure [9]. The softbake condition was optimized for both kinds of resist, and is a critical parameter for good sensitivity and process latitude. However, the lower limit of 3.0µm resolution was achieved for all soft bake conditions. The mechanism for softbake conditions to influence ANR negative photoresist sensitivity depends on the effect of the solvent. Of course, increased softbake time and temperature leads to increased solvent removal. However, the solvent enhances the sensitivity of the resist, possibly by promoting increased diffusivity of photogenerated acid, the crosslinking agent. Similarly, post-exposure bake conditions strongly affected sensitivity while resolution limits remained the same. For post exposure process times of 110-130°C for 90-210 seconds, increasing the bake temperature by 10°C or bake time by 60 seconds increased the sensitivity by a factor of two.

For positive resists, the exposure latitude available can be used to ensure straight sidewalls even for small numerical aperture lenses. Both positive and negative resists will be needed for active matrix device manufacturing, and resists with adequate sensitivity and resolution, adapted from semiconductor photoresists, are available.

Etch resistance of photoresists parallels the requirements for IC processing, although for wet etching, less concentrated acids are used. Plasma etch requirements appear to be virtually the same.

Photoresist suppliers include Tokyo Ohka, JSR and Shipley. Standard negative and positive resists and associated developers and strippers are used in flat panel processing.

# Photomasks

Steppers use standard photomask reticles made just like those for integrated circuit manufacturing. Typical reticles are 5" quartz plates, and steppers are configured to accept pellicles on both sides of the reticle. Reticle libraries allow storage and retrieval of needed masks. Design rules are typically 3-5µm for thin film transistor manufacturing. Suppliers include semiconductor reticle manufacturers, Toppan Printing, Dainippon Printing, and Sashin Kagaku.
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Scanning projection or full projection exposure equipment requires a large mask, up to the same size as the glass substrate. For dimensional stability, the mask must be made of quartz. Very large quartz substrates are required, and specialized electron beam exposure equipment is needed. Quartz blanks are becoming available in Japan from mask substrate suppliers such as Hoya, SEH and Toshiba Ceramic. These blanks are very expensive, since cutting losses are very high. Diamond saws with very large saw kerf (cutting width) are required. Cutting is followed by laborious grinding and polishing to flat, optical finish on both sides. Standard sized blanks for use in integrated circuit mask making use well developed slicing and polishing equipment and processes not available for the large-sized substrates. In addition, the substantial investment needed for projection masks won't be made until the projection unit sales indicate that a large installed base of equipment will justify the demand. Until then, large quartz masks will remain very expensive items.



## **Orientation Films**

Alignment of liquid crystals at the substrate surface refers to the orientation of the liquid crystal director at the surface, and can be either homeotropic or homogeneous. For homeotropic orientation, the liquid crystal director is perpendicular to the substrate. An organic surfactant can be applied to the substrate with long chains trailing off perpendicular to it, orienting the liquid crystal molecules in the same direction. New display materials based on homeotropic liquid crystals are being commercialized by Stanley.

Homogeneous orientation is more complicated. The liquid crystals are aligned with the director parallel to the surface. However, in addition to this orientation, the LC molecules must be oriented in a particular direction along the surface, which is more difficult than for homeotropic alignment. The orientation is accomplished by depositing and rubbing a thin organic film, usually polyimide. It is difficult to detect the change in the surface of the material after rubbing. In addition to determining the direction the liquid crystal molecules will follow on the surface of the substrate, the rubbing process controls the "pretilt angle" of the molecule, the slight angle the molecule makes with the substrate. This angle, ranging from 2°-8°, should be as high as possible for fast response STN displays. The mechanism by which a rubbed polyimide film of a certain composition achieves a given pretilt angle is not understood. Materials are developed and improved on an empirical basis.

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## **3.8.1 POLYIMIDE ORIENTATION FILMS**

During the 1970's, various kinds of material were investigated for the alignment of liquid crystals at the substrate surface, including inorganic compounds like silicon monoxide. Generally, liquid crystal alignment materials are heat resistant polymers with high  $T_g$ . Polyimides were selected based on properties such as mechanical strength, thermal strength, and low solubility in process solvents [10]. Normal aromatic polyimides must be baked at temperatures higher than 300°C, which is too high for color filters composed of organic polymer and dyes. Therefore, development of a film which could be cured at 180°C or below was undertaken. The material is an aliphatic cyclic polyimide which is soluble in solvents such as butyrolactone and NMP.

Generally, it is easy to align liquid crystal molecules, no matter what kind of material is used, if it is rubbed in a certain direction to align the material's molecules. However, liquid crystal stability after rubbing will be influenced by the materials used. Polyimides were found to be suitable in the early 1970's, and in the 1980's, flexographic printing was adopted as mass production machines for alignment film deposition. Generally speaking, a High T<sub>g</sub> polymer will meet the requirement of alignment films, but producing a thin film is difficult. However, for polyimides, the precursor polyamic acid will dissolve in polar solvents. After thin film formation by the precursor, heating produces imidization and a satisfactory thin film. Table 3-13 shows the properties of alignment layer materials.

<b>Required Property</b>	<b>Relevant Process</b>
Thin film (<1000Å)	Film forming (flexo printing)
Adhesion to substrate	Film forming, rubbing
Chemical resistance	Cleaning
Adhesion to sealant	Sealing, Assembly
Thermal stability	Sealing, Assembly

**Table 3-13** Alignment Film Material Requirements

For AMLCD's, standard polyimides cannot be used. Requirements for AMLCD include imidization at 200°C or lower, and good voltage holding ratio and RC time constant of liquid crystal cell. Standard polyimides required 300-350°C processing, and unstable polyamic acid radicals will remain in the film if cured at 200°C. NMP, used as solvent for standard polyimides, has a strong extractive

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power for the dyes used in color filters. Development work centered on eliminating the aromatic, conjugated molecular structure, since this was believed to affect the voltage holding ratio and RC time constant of the cell. In addition, the fully imidized material was targeted, which could be prepared as a thin film simply by evaporating the solvent.

Synthesis route and structural formula for a typical soluble polyimide are shown in Figure 3-6. No imidization was observed below 220°C, providing a very stable film. RC time constants of liquid crystal cells made using this alignment material are reported superior to conventional films. The imidization rate can be matched to device characteristics, and the alignment film optimized for each device.





Newer liquid crystal materials impact the alignment film in two ways. First, tilt angle is being added as a requirement, and improvement of afterimage is required. Tilt angle control is being pursued by modifying the STN alignment film materials. Control of afterimage is more difficult, since the relation between voltage holding ratio, afterimage and alignment film is not clear.

Further research is concentrating on developing alignment layers that require no rubbing.

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A recent article by researchers at Nissan Kagaku Kogyo discussed the properties of polyimides used for orientation films [11]. An important ingredient in polyimide performance is to provide a high pretilt angle for the liquid crystal molecules. The higher the pretilt, the wider the viewing angle of the display. This is especially critical for STN displays, but is becoming important for TFT displays also. The Nissan researchers have investigated the effects of varying the molecular structure of the polyimide on the pretilt angle. Alkyl radicals were introduced into the polymer, providing a wide range of curing temperatures. Selecting the polyimide skeleton correctly allows maximum pretilt angle with minimum rubbing pressure.

Two factors influencing the pretilt angle of a polyimide are the polymer side chain groups and the presence of fluorine end groups. Pretilt angle is much higher when alkyl groups are present. The addition of fluorine reduces the surface tension, and further raises the pretilt angle. The higher the fluorine content, the higher the pretilt angle. At the same time, it is necessary to create polymers that are soluble in solvents such as NMP and EC. As a minimum the polyamic acid precursor must possess such solubility, but the cured polyimide is also evaluated.

The effect that long chain alkyls have on the polyimide depend on the stage at which the material is added. When reacted as a monomer, the effect is substantial. However, when mixed with polyamic acid, no effect is seen on pretilt angle.

The temperature dependence of pretilt angle is also important. Normally, pretilt angle increases with curing temperature in the range 150-300°C. This occurs even when fluorine is added, although the pretilt angle is higher with fluorine. However, an improvement or change in the alkyl bond can reverse the temperature dependence, resulting in higher pretilt angles at lower curing temperatures. This is obviously very important for orientation films over other polymers such as color filters, which are adversely affected by a high temperature cure.

Depending on the polyimide backbone, the pretilt angle varies with rubbing pressure. For all materials tested, *highest pretilt angle occurs with the lowest rubbing pressure*. A series of polyimides was measured, and measured surface tension for the polymers ranged in surface tension values from 22 to 47 dyne/cm. The pretilt angle was highest for the molecule with the lowest surface tension. If the rubbing pressure is increased by a factor of four, the pretilt angle declines almost a factor of two. Similar behavior is observed for the other molecules, but

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pretilt angles are lower than this. One result is to show the importance of the surface tension measurement and its role in selecting materials with high pretilt.

The final pretilt angle depend on curing conditions. It is essential to cure without overbaking the material. Overbaking leads to changes in threshold voltage of devices due to a residual voltage on the orientation film. Table 3-14 shows results from four polymer types.

Material	Pretilt Angle (degrees)	Resistivity (Ω-cm)	Residual Voltage (mV)	Overbaked
PI-A	5	2x10 <sup>16</sup>	340	Yes
PI-E	5	$1 x 10^{16}$	210	Yes
PI-F	4	$2x10^{16}$	20	No
PI-G	8	$2x10^{16}$	280	Yes

**Table 3-14** Comparison of Polyimides for Orientation Film Applications

Different kinds of polyimide structures can generate different tilt angles in rubbed orientation films. Investigations by Spaulding and Estes compared polyimides' tilt angles using the magnetic-null method[11]. Experimental polyimides were deposited by spin coating on ITO covered glass and cured at 250°C. The 250Å films were rubbed using a NOMEX pile buffing wheel. Rubbing was verified for each cell by measuring the induced birefringence. Test cells were laminated with the rubbing directions antiparallel using DuPont WA-Acrylic adhesive, filled with Merck ZLI-2293, and cleared following data sheet information. The magnetic-null method employs an external magnetic field and measures the capacitance induced on the cell by the field. The angle of the magnetic field for which the capacitance is constant and equal to zero is obtained, and this angle is a function of the tilt angle. An extension of this method determined the slope of the reduced capacitance at the center of the cell. Tilt angles of 5.2-16° were measured for experimental polyimides. Such high tilt angles are needed for advanced STN and SBE (supertwisted birefringence) displays.

A recent report describes a process to stain and image the grooves formed in a polyimide film by the rubbing process [12]. Orientation films can be deposited by printing, with 1000Å-thick layers possible using flex-printing. Spin coating is also used. Orientation film suppliers include JSR, Hitachi Kasei, Toray, and Nissan Chemical.

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Most STN and TN materials are aligned homogeneously, which means that the liquid crystal director lies in the plane of the glass substrate. If the liquid crystal director is aligned vertically with respect to the substrate, some display advantages are realized. These have been described by Clerc[13] of Stanley Electric, and include full color capability, wide viewing angle, and fast switching time. Development of vertically aligned displays has manufacturing benefits compared to STN displays, including less severe cell gap control ( $\pm 0.2\mu$ m), ability to use standard sodalime glass substrates, and no need for a planarizing layer over color filters. Development work is underway on a 10" full color display for computer applications based on this new alignment scheme.

Vertical alignment of liquid crystals is possible using an orientation material that has alkyl (nonpolar) chains protruding at right angles to the substrate. These side chains have to be >200Å long, or about 12-14 carbon atoms in length. A lot of materials have this property, and the investigation by Stanley focused on choosing the most reliable and most easily manufactured material. Eventually, a material that could be offset printed was selected. This means that the same manufacturing equipment is still used when switching from STN to vertical alignment displays. A slight tilt of the liquid crystal molecules is necessary, or a special electrode design can compensate for 0° tilt.

Optical compensation was achieved using a ionomer single film compensator possessing an isotropic phase at high temperature. The film is pressed between two substrates, heated to the clearing point, then cooled to the birefringence phase under the external pressure. This locks in a vertical mechanical constraint, and orients the optical axis in the vertical direction as well. The extraordinary index of the film is lower than the ordinary, and the birefringent film has retardation zero, which is ideal for compensation of vertically aligned LCD.

## Spacers

Spacers are used to control the cell gap of liquid crystal displays by maintaining a separation between the two glass plates. They are constructed of plastic or glass. Plastic spacers are spherical while glass spacers are often rod-shaped, and long fibers can also be used.

Sekisui Fine Chemical's Micropearl; SP is a spherical particle of cross-linked



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polymer, primarily consisting of divinyl-benzene. It has specific gravity and thermal expansion coefficient close to those of liquid crystal materials and is used for in-cell spacers. Requirements on spacers include no degradation of liquid crystal resistivity, sufficient compressive strength, high temperature capability, and flexibility at low temperature. Plastic spacer materials have an advantage in being able to match thermal coefficient of expansion and specific gravity (SG=1.19) of liquid crystal.

For STN displays, tone and color may be affected by the accuracy of cell spacing. The higher accuracy required on cell spacing, the more spacers that are required. Plastic spacers with a high coefficient of thermal expansion can help maintain the spacing even as the temperature changes. Therefore, plastic is mainly used in STN displays, for which cell spacing tolerance is very low, and for automotive displays which may be exposed to a wide temperature range.

Inorganic spacers have a higher compressive strength and can provide dimensional stability at high applied loads. On the other hand, plastic spacers are deformed by high loads, leading to a change in cell gap.

Spacer thickness is determined from the design parameter  $\Delta$ nd. Cell spacing, d is determined to an accuracy of 0.1µm, and tolerance is specified at ±1% for displays that operate over a wide range of conditions. Spacer size ranges from 3.0µm to more than 10.0µm with standard increment of 0.25µm. Some further fine adjustment of spacing can be achieved by controlling the dispersion density of the spacers. The cell gap is not necessarily equal to the spacer dimension, since some spacer deformation will occur. This means that the proper spacer size is determined empirically by selecting several sizes and determining the cell gap each one produces. Typical sizes and standard deviation of size are shown in Table 3-15.

Nominal Size (µm)	Standard Deviation (µm)
$3.00 \pm 0.05$	$0.21 \pm 0.03$
$5.00 \pm 0.05$	$0.30 \pm 0.03$
$7.00 \pm 0.05$	$0.34 \pm 0.04$
$9.00 \pm 0.05$	$0.45 \pm 0.05$

<b>Table 3-15</b> <i>H</i>	Plastic Spacer	Size Va	riation
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Compressive strength of plastic spacers is temperature dependent, and is about 20% lower at 180°C than at room temperature. Thermal expansion coefficient is also temperature dependent, as shown in Table 3-16 below.

**Table 3-16** Plastic Spacer Thermal Expansion Coefficient

Temperature range	30-60°C	60-200°C	200-280°C
Thermal expansion	4.7	5.4	3.7
coefficient (x10 <sup>5</sup> /°C)			

Several methods can be used to apply spacers to the glass substrate. Spacer spray equipment using specially designed nozzles is most common, with spacers contained in a dispersion agent such as alcohol, Freon, or water/alcohol mixtures.

Precision silica fiber spacers are available from Tokuyama Soda and others. These are manufactured from high purity  $SiO_2$ , and are available in diameter distributions similar to plastic spacers. Fiber length varies from 50 $\mu$ m to 200 $\mu$ m. Figure 3-7 shows diameter distribution graphically.



## Figure 3-7 Glass fiber spacer size distribution.

## Sealing Materials



Generally, thermosetting or UV curable epoxy resins are used as sealant materials. It is essential that the material be inert after curing, so as not to degrade the resistivity or other properties of the liquid crystal due to constant contact. By themselves, epoxy resins won't usually degrade the liquid crystal material, but the amines present in thermosetting material dissolve in the liquid crystal. Therefore, after screen printing the thermosetting resin, the hardening temperature is

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approached in stages, using prebaking to evolve these amine groups. An alloy of phenoxy and epoxy resins, joined to a silicone rubber has also been proposed as a substitute for amine chemistry.

Instead of thermosetting epoxies, UV hardening epoxies are also available. However, it is difficult to harden the glue in the UV resin by exposure to light alone, so after UV hardening, a postbake treatment is used. The seal strength of UV resin is low compared to thermosets, so thermosetting resins are commonly used.

In case there is an orientation film covering the area where the seal is deposited, there will not be an intimate bond between seal, orientation film, and substrate, and the seal will not be hermetic. In order to avoid this, it is possible to mask the area to be sealed prior to orientation film deposition and rubbing. However, this results in a very complicated manufacturing process, and has not been implemented. More recently, where the orientation film covers the entire substrate, it is removed in the area where the seal material is to be deposited. Both hot etching and plasma etching have been employed for this step. For ease in removal of the orientation film in the seal area, photosensitive polyimide can be used as the orientation film material.

Seal materials are available from Hitachi, Nihon Kayaku, and Mitsui Toatsu.



## **Liquid Crystals**

Liquid crystal materials are rod-like molecules typified by the cyanobiphenyl compound shown in Figure 3-8. The director, n, of a liquid crystal is a unit vector parallel with the long axis of the molecule.

Figure 3-8 Typical liquid Crystal



For the Nematic Phase, molecules are oriented at random in the liquid, but the directors of the molecules are parallel, as in Figure 3-9. Thermal motions of individual molecules perturb the alignment, but, on the average, the bulk director is invariant.

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The Cholesteric Phase is also characterized by random molecular position, and parallel alignment of the director. However, in the cholesteric phase, the director rotates from layer to layer through the bulk, adopting a spiral structure as shown in Figure 3-10. The pitch, p, of a cholesteric liquid crystal is defined as the distance for which the director rotates through 360°, and is important especially for supertwist devices.



Figure 3-9 Nematic phase

Figure 3-10 (Center) Cholesteric phase





Figure 3-11 Smectic phase

Making a cholesteric phase requires the addition of chiral, or optically active molecules. The mixture of small amounts of chiral material with nematic liquid crystal material produces a cholesteric phase with a long pitch, the value of p depending on the amount of chiral mesogen added. In fact, the nematic phase can be considered as a special case of a cholesteric phase with infinite pitch.

Smectic A ( $S_A$ ) material is characterized by parallel alignment of the molecular director. However, there is also positional order, and the molecules form layers with the director parallel to the layer normal, Figure 3-11.

Chiral Smectic C ( $S_c^*$ ) phase has a similar layered structure, except that the molecular directors are tilted at a constant angle (the tilt angle) to the layer normal. In a chiral smectic C phase, the presence of chiral or optically active molecules cause the director to rotate from layer to layer, the tilt angle remaining constant.

All liquid crystals used for display manufacture are thermotropic - they are formed by melting mesogenic solids. Liquid crystals for displays are typically mixtures of several compounds aimed to optimize several physical properties for specific applications. A mixture may exhibit a number of different liquid crystal phases; a typical phase sequence is shown below.

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crystalline (K) -> smectic A ( $S_A$ ) -> smectic (N) -> isotropic (I)

The properties of the liquid crystal materials are often anisotropic, specifically the dielectric permittivity ( $\Sigma$ ), and the refractive index (n). Table 3-17 shows the physical properties specified in a liquid crystal formulation.

Designation	Property	
K -> N	Phase transition	Melting point, crystalline - nematic
K -> S <sub>A</sub>	Phase transition	Melting point, crystalline - smectic
	Α	
S <sub>A</sub> -> N	Phase transition	Transition point, smectic A - nematic
N -> I	Phase transition	clearing point, nematic - isotropic
$\Delta \Sigma$	Dielectric anisotropy	
Δn	Optical anisotropy	
$n_{_{20}}$	Kinematic viscosity at 20°C	
V(90,0,20)	Threshold voltage	Voltage at 90% of maximum
		transmission at perpendicular view
		ing angle and 20°C, crossed polarizers
V(10,0,20)	Saturation Voltage	Voltage at 10% of maximum
		transmission at perpendicular view
		ing angle and 20°C, crossed polarizers
V(90,45,20)		Voltage at 90% of maximum
		transmission, 45° viewing angle, and
		20°C, crossed polarizers
V(x,y,z)		Voltage at x% of maximum
		transmission, y° viewing angle, z°C
<b>M</b> <sub>20</sub>	Margin	$M_{20} = V(10,0,20)/V(90,45,20)$
M'_20	Margin	$M_{20}^{2} = V(50, 10, 20) / V(90, 45, 20)$
A <sub>11</sub> , A <sub>1</sub>	Absorbance	Absorbances in a dye solution paral-
		lel and perpendicular to the director
S	Order parameter (dye)	$S=(A_{11}-A_1)/(A_{11}+2A_1)$

 Table 3-17 Parameters Specified in Liquid Crystal Formulations

Material resistivity is another important parameter not listed in the table. In general, resistivity must be high, and for active matrix devices, as high as possible.

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Twisted Nematic (TN) liquid crystal displays are used for small displays, and homogeneous alignment is used in cells with a gap of about  $10\mu m$ . The orientation film is rubbed so that the director lies parallel to the surface of the glass with a small tilt angle of 2° or so. The rubbing directions of the two glass plates of the display are mutually perpendicular, and the nematic liquid crystal forms a twisted structure with a 90° rotation of the director from one plate to the other. A small amount of chiral material is added as an anti-reverse twist additive, to prevent a defect known as reverse twist. The liquid crystal is actually a long pitch cholesteric, rather than a true nematic.

Specifications for a liquid crystal mixture depend on the application. For example, automobile dashboard displays require a mixture with a broad operating temperature range, capable of switching in 1 second at -30°C, indicating a low viscosity fluid. On the other hand, a high information content display, normally used indoors, requires a low value of  $M_{20}$ .

Although simple matrix displays can be addressed by direct drive, higher information content displays require multiplexing. A matrix of NxM segments can be multiplex driven N ways using N+M connections. The drive scheme results in a voltage of V(off) or V(on) applied to OFF or ON segments respectively, where

$$V(off) = \frac{V}{S} \sqrt{\left[\frac{N = (S-2)^2 - I}{N}\right]} \qquad V(on) = \frac{V}{S} \sqrt{\left[\frac{N + S^2 - I}{N}\right]}$$

V = Supply Voltage I/S = Select Scheme  $S = I + [\sqrt{N}]$  (or nearest integer value)

Both OFF and ON segments have a voltage applied, requiring that the electro-optic response of the liquid crystal should be as sharp as possible, indicated by a low value of  $M_{20}$ . Because of variations in V, N, and S, the threshold voltage of the liquid crystal is critical. Ranges of V(90,0,20) from 1.01V to 4.03V are available.

The liquid crystal manufacturer can supply 2-bottle or 3-bottle systems which consist of identical formulations with either 1 or 2 variable components. Mixtures can be continuously adjusted to vary a single property of the formulation, such as V(90,0,20), while holding the other properties constant. This is useful in display development.

Supertwist (STN) devices are used where the level of multiplexing is high (N>100) and adequate contrast is difficult to achieve with TN material. Twist angles >90° allow the electro-optic threshold to be improved. Addition of a chiral

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dopant to the nematic mixture is necessary to ensure the correct twist angle, and a high tilt alignment is usually required for twist angles >220°. Commonly, twist angles range from 180-270° for STN displays, and the liquid crystal formulation contains more than 20 components.

Devices built with supertwist material include supertwisted birefringence (SBE) devices, with a twist angle of 270°. This requires a high tilt alignment layer to avoid an undesirable scattering texture in the ON state. Optical mode interference (OMI) devices offer a positive contrast, black and white display, where the optical performance is less susceptible to variations in cell thickness than STN or SBE devices. The brightness is lower than STN or SBE displays, and may be inadequate for reflective displays. Low birefringence is required.

Recent improvements in liquid crystal materials focus on the addition of fluorine or other functional groups which terminate the polymers and provide added performance. The response time of STN materials can be improved with fluorine terminations. In addition, the twisted nematic molecules suitable for active matrix displays require extremely high resistivity, on the order of  $10^{13} \Omega$ -cm, and the resistivity of the polymers is increased with the addition of fluorine. Figure 3-12 shows examples of high performance STN materials, and Figure 3-13 molecules for active matrix displays [14].

### **3.11.1 OTHER LIQUID CRYSTAL MATERIALS**

Guest-Host (GH) devices employ nematic mixtures containing a dichroic dye. A molecule of a positive dichroic dye will selectively absorb certain wavelengths of light, incident normal to its long axis. This absorption falls to a minimum for light incident parallel to the long axis. When the dye (guest) is mixed with a nematic liquid crystal (host), the dye molecules line up parallel to the bulk director of the liquid crystal, producing anisotropic absorption of light at certain wavelengths. The tendency of the dye molecules to align with the nematic director is measured by the dye order parameter, S. In general, S should be high, normally >0.7.

Certain chiral smectic liquid crystal phases exhibit ferroelectric properties, which can be used in electro-optic devices. The most commonly used ferroelectric phase is the chiral smectic  $C(S_c^*)$  phase. In the bulk, because the director spirals through the material, there is no net polarization. However, using suitable boundary conditions, the helical condition can be "unwound" and thin layers of  $S_c^*$  materials can show net electrical polarization.

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	t (°C)	ΔΣ ν	′(mm <sup>2</sup> *s <sup>-</sup>	<sup>-1</sup> ) ∆n
с₅н <sub>11</sub> - <b>(О)-(О)-</b> ос₂н₅ F F	K 105 S <sub>C</sub> 135 N 185 I	-4.2	49	0.27
	K 68 SA 87N 172 I	-4.1	46	0.18
	K 76 SB 79N 186 I	-4.4	39	0.13
C <sub>5</sub> H <sub>11</sub> -O-COO-O-OC <sub>2</sub> H <sub>5</sub>	K 51 N 63 I	-4.6	18	0.09
C <sub>5</sub> H <sub>11</sub> - <b>⊘</b> -C≡C- <b>⊘</b> -OC <sub>2</sub> H <sub>5</sub>	K 57 N 61 I	-4.4	17	0.25
	H5 K 84 N 229 I	-4.1	27	0.29
	$\Delta \Sigma, V$ a	and ∆n ext	rapolated	values

**Figure 3-12** *Molecular structure and physical properties of 1,4 - disubstituted - 2,3 - difluorobenzene derivatives.* 

Figure 3-13 Trans-4-n-pentylcyclohexyl (PCH-5) derivatives.

	Mesophase (°C)	ΔΣ	<i>V</i> (mm <sup>2</sup> /s)
с <sub>5</sub> н <sub>11</sub>	K 41 N (31) I	-0.5	8
с₅н₁₁-ᢕ_{()}- сн₃	K 25 N (-4) I	+0.3	7
<sup>C<sub>5</sub>H<sub>11</sub></sup>	K 34 I	+3	3
с <sub>5</sub> н <sub>11</sub> СF <sub>3</sub>	K 10 I	+11	9
C <sub>5</sub> H <sub>11</sub> - <b>√</b> → NCS	K 37 N 51 I	+11	12
C₅H <sub>11</sub> - <b>◯</b> - ⊂N	K 31 N 55 I	+13	22
<sup>С<sub>5</sub>H<sub>11</sub> - СМ</sup>	K 13 N (5) I	+18	28
C <sub>5</sub> H <sub>11</sub> -	K 14 I	+7	4

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The surface stabilized ferroelectric liquid crystal (SSFLC) described by Clark and Lagerwall is similar to a TN device except that the cell is much thinner, typically about 2µm, and the rubbing directions on the alignment layers are parallel[15]. The S<sub>c</sub><sup>\*</sup> material fills the cell, with layer normals parallel to the rubbing directions, and with the molecular directors in planes parallel to the glass plates, and at an angle  $\pm \emptyset$  (the tilt angle) to the layer normals. These states have opposite electrical polarity and the molecules can be switched between the  $+\emptyset$ and  $-\emptyset$  states by applying a DC voltage of the appropriate polarity. Crossed polarizers produce bright and dark states respectively, due to the birefringence of the liquid crystal.

The advantage of this type of display is that switching times of a few microseconds can be achieved, and high levels of multiplexing can be employed. Ferroelectric displays are being studied as an alternative to active matrix devices for high information content displays. Other, non-display applications for ferroelectric devices include printing heads and fast optical light valves and shutters.

## **3.11.2 POLYMER DISPERSED DISPLAYS**

Polymer dispersed liquid crystal (PDLC) materials have been discussed for a variety of applications including shutters for window glass, projection screens, signboards, and even projection TV shutters. Typically, the difference between the Off and On state of the material is a transition from light scattering to clear. This might discourage its application to direct view displays. However, researchers at Hughes have discovered a way around some of the difficulties of PDLC display manufacturing. Specifically, they have created spatially separated regions where liquid crystal polymer droplet sizes differ, providing regions of high scattering where address lines can be hidden [16].

By varying the liquid crystal droplet size in designated regions, direct view polymer dispersed liquid crystal displays are constructed with simple addressing schemes. A multiple droplet size PDLC is used to hide addressing line voltage effects in a segmented display which requires a clear background. Edge-lighting improves the contrast of the displays.

The PDLC material consists of droplets of the liquid crystal BDH-E7 (British Drug House Ltd.), dispersed in a matrix of NOA65 (Norland Optical Adhesives), where the PDLC is formed by the polymerization-induced phase separation technique. When exposed to UV light, NOA65 polymerizes, phase separation

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occurs, and liquid crystal droplets form. The droplets coalesce and grow until the polymer matrix becomes rigid. The intensity of the UV light determines the time available for droplet growth. High intensity UV produces small droplets by causing polymerization to occur rapidly. Conversely, for low intensity light, larger droplets are obtained.

With sufficient voltage drop, V, across the substrates of a PDLC of thickness d, the liquid crystal in the droplets aligns and the PDLC switches from scattering to clear. Whether or not a voltage is large enough to switch the PDLC is determined by the relative values of the free energies of the droplet with and without the voltage. With no voltage present, the free energy of the droplet is proportional to  $K/r_d^2$  where K is an effective elastic constant of the liquid crystal and  $r_d$  is the radius of the liquid crystal droplet. With a voltage applied to the substrates of the PDLC, the free energy of the droplet is proportional to  $(V/d)^2$ , where d is the polymer layer thickness. Relating these two proportionalities yields a droplet size dependent switching voltage for the PDLC,  $V \sim (d/r_d)K^{-1/2}$ . The relationship has been experimentally confirmed.

In order to create regions in the material with different droplet sizes, the UV exposure was conducted through a mask whose transparency varied from 8-39%. This created a droplet-size dependent turn on voltage as shown in Table 3-18.

UV Exposure Relative Intensity (%)	Turn On Voltage	
8	5	
11	10	
17	20	
27	39	
39	50	

**Table 3-18** Relation Between UV Exposure and Turn On Voltage

Displays were made with a continuous ITO coating on one substrate, with a patterned substrate on the other surface. For a  $20\mu$ m thick display and a voltage greater than 110V, the entire display is clear. If the voltage on one segment is between 45V and 110V, the segment scatters while the addressing line remains clear. Edge lighting of the display can enhance its contrast.

Other applications for PDLC materials have been discussed previously.

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## 3.11.3 POLYMER NETWORK DISPLAYS

A polymer network liquid crystal (PNLC) display differs from a polymer dispersed liquid crystal ((PDLC) display in several important ways [16]. The PDLC is well known from Fergason's work, and consists of dispersion of droplets of liquid crystals in a polymer matrix. Polymer network materials, PNLC, disperse a nematic liquid crystal as a random network of molecules. The networks are prepared using acrylate oligomers and/or monomers, and light-induced polymerization.

The light-scattering type of polymer films such as PDLC and PNLC have advantages such as high brightness, wide viewing angle, and simplicity of fabrication. Disadvantages of PDLC include high driving voltage, requirement for matching index of refraction of liquid crystal and polymer matrix, and temperature dependence of transmission-voltage characteristics. The first few disadvantages can be overcome using PNLC, for which index matching is not a requirement, and for which greatly reduced turn-on voltages have been achieved. Drive voltage has been reduced to below 5V, probably because of the weaker surface interaction on a polymer network than for the droplet of a PDLC. The sharpness  $\gamma (=V_{50}/V_{10})$  of the transmission-voltage characteristic is 1.3-2, and maximum number of multiplexible lines is therefore 2-15. This is much better than PDLC, but is inferior to TN displays. Other factors influencing the performance of the displays include viewing angle dependence and temperature dependence of transmission-voltage characteristic. The latter variation is higher than for TN displays, and needs improvement.



## **Polarizers/Compensation Films**

Polarizing films are applied to both sides of an LCD display. Any trapped air in the interface between the film and the LCD causes a reflection loss of about 4%. Therefore, uniform bonding of the film is critical. A multilayer structure has been developed to protect the polarizer both before and after application, to ensure good bonding, and maintain high transparency. Figure 3-14 shows the structure of transmissive and reflective polarizer films developed originally for watches. Transparent acrylic adhesive approximately 25µm in thickness is used in this film.

Persistent problems with air bubbles and delamination of the polarizer were solved by the introduction of vacuum bonding, applied as roller bonding combined with autoclaving in production. Conditions are:

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- General purpose (to  $80^{\circ}$ C),  $50^{\circ}$ C, 0.49 MPa (5kg/cm<sup>2</sup>), 15 min
- Hi-durability (to  $90^{\circ}$ C),  $70^{\circ}$ C, 0.49 MPa, 15 min

### Figure 3-14 Structure of polarizer film for LCD



Several types of protective layers, reflector materials and adhesives have been developed to suit special applications. For example, high durability polarizing film (Nitto type Q) had a newly developed dye polarizer between reinforcing cellulose triacetate (TAC)-acrylic protective layers. These polarizers are suitable for the conditions experienced by LCDs in automobiles and gasoline pump displays. Nitto type QE material employs iodine polarizer material in a similar structure. Types Q and QE are applied to the upper and lower parts of the display. Films of this type with added color are also available.

Improvements in materials performance resulted in newly designated polarizer materials Type F, with TAC support layers, and Type G, high contrast material. A summary of polarizer film designations is shown in Figure 3-15 and Table 3-19.



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Designation	Polarizer Material	Protective Layer	Product Application
Туре F	Iodine	TAC(cellulose triacetate)	Watches, calculator, general applications
Type G	Iodine	TAC	STN and AMLCD instrument displays
Туре Т	Iodine	Acrylic	Thin displays
Type QE	Iodine	TAC-acrylic 2 layer	Automotive, outdoor use
Type Q	Dye	TAC-acrylic 2 layer	Automotive, outdoor use

	<b>Table 3-19</b>	Polarizing	Film	Structure
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Other materials that can be added include aluminum reflector, high transmittance reflector, retardation films and antiglare films. The relation between polarizer transmittance and efficiency is shown in Figure 3-16.

A retardation film is a uniaxially stretched high molecular weight film which is formed by thermal stretching after film formation by a special T die extrusion method where polycarbonate resin is used as the raw material. The T die film





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formation method and uniaxial stretching are widely used for thin organic films. The optical performance of the retardation film for LCD applications must be equivalent to inorganic crystalline optical materials.

Nitto's new z-axis retarder, "NRZ" is a one component polycarbonate film, just announced in August, 1991. It represents an improvement over the 2-component film, which was composed of polycarbonate and styrene (for z-axis compensation).

Mounting the retardation film on the display requires maintaining the optical axis at a given relation to the polarizer, which increases the panel brightness by eliminating reflections. To ensure good adhesion to glass and to polarizer, special adhesives and laminating technology are used to provide an integrated retarder/ polarizer product. Display designers may require unique retarder arrangements for each new display.

Retardation films have light transmittance of 90% or greater including the adhesive layer. The retardation value  $\Delta$ nd can be set to any value from 250nm to 800 nm. Retardation value of standard product is 300, 400, 500, and 600nm. Dispersion is less than  $\pm 2\%$ . Under life test conditions for 500 hours at 70°C and 500 hours at 40°C/90% RH, retardation value was unchanged.

Elliptical polarizing film is obtained by bonding the retardation film to the polarizer at a specific angle, generally 45°.

Polarizers are supplied primarily by Nitto Denko and Sanritz. Arisawa also supplies polarizers. These companies also supply polarizers with compensation films attached, the usually embodiment of this product. Manufacturers of compensation films include Sumitomo Chemical and Kayapola.

## Die Attach/Connector Materials

Die attach methods were described in Chapter 2, and make use of chip on board, chip on film, and chip on glass mounting techniques. Many aspects of die attach are identical to those for semiconductors and will not be described here. One example is standard printed circuit boards used in chip on board construction. However, the heat seal used in connecting the display to the printed circuit board can be a unique product for this application. Figure 3-17 shows two embodiments of such a heat shield connector, in which the graphite thermal conductor is

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covered by silver electrical conductor in two different ways. The pitch that is possible using screen printing to form the conducting and insulating patterns is  $260\mu m$ . New kinds of heat shield connectors are being offered, constructed from etched copper foil combined with anisotropic conductive paste. In this case, patterns of 100 $\mu m$  pitch are possible.

When chip on board and heat seal assembly methods are used, it is possible to repair the module by disconnecting the heat seal and cleaning the liquid crystal terminal leads with solvents.

Chip on film methods make use of tape automated bonding (TAB) die attach. In this method the die is first mounted to a flexible tape containing the electrical leads (inner lead bonding). These leads are then bonded to the connectors on the film or flexible circuit board (outer lead bonding). In the past, it was standard to bond the inner and outer leads using a tool which simultaneously attached all the leads (gang bonding). However, for very complex chips with as many as hundreds of leads, the complexity has lead to a return to single point bonding, in which leads are connected one at a time.

TAB ICs are used mainly in liquid crystal display applications, where savings in packaged display size and weight are of great importance. Figure 3-18 shows a pie chart representation of TAB IC usage by product. Including consumer products such as the schedular (which uses a display), LCD related TAB usage is about 80% of the total.

Flexible circuit boards are connected to the display using anisotropic conductive film, which has been described in Chapter 2. This film is electrically conducting in the thin dimension between display and film, and insulating in the other two directions. Anisotropic conductive film is available in thermosetting and thermoplastic versions. Thermoplastic film can be removed for repair. Thermoplastic resins such as SBR and polyvinylbutylene can be used. Thermosetting resins include epoxies, urethanes and acrylics. Conductive particles dispersed in the resin are of a variety of types, including carbon, metal, and metal-plated plastic spheres. Particle size determines the final separation of ITO and copper, and can range from 5µm to 10µm. Anisotropic films allow connections as close as 10 electrodes/mm. Suppliers include Hitachi Chemical.

Direct connection of driver circuits to the glass substrate represents the ultimate reduction in size and weight of the display. A variety of techniques for chip on

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# Figure 3-17 Heat seal connector construction [17].

glass attachment have been developed[18]. Most of these make use of special bumps or protrusions on the IC chip instead of flat bonding pads used for wire bonding. These bumps are usually plated or formed by other means over the original bonding pads. The IC is aligned to the connections on the glass with a special tool. The bumps are then bonded to the ITO or metal on the glass substrate by solder, conductive adhesive or other means. Figure 3-19 summarizes the different chip on glass techniques including bonding parameters and whether or not faulty connections can be repaired. Repair is seen as an essential requirement for chip on glass manufacturing.

Figure 3-18 Usage ratio of TAB ICs



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Shown in Table 3-20 is the cost breakdown of an STN display. This display represents the minimum cost possible using standard 2 layer PC board construction with chip on board mounting and a heat shield connector from the board to the display. This display does not make use of retardation films, so it is a blue mode display suitable for a "heavy" laptop weighing 7-10 pounds. Total factory cost is \$180, and the selling price is below \$200. Higher quality displays with retardation films for true B/W display, lightweight TAB mounting of circuits on flexible boards command a premium of \$30-40 over this example.

Some industry observers expect the LCD driver IC market to reach \$770 million in 1995. LCD driver IC production is estimated at over \$200 million in 1991. Driver IC costs vary from \$2 each to \$6 each, depending on complexity andvolume required. Sharp has a monthly production capacity of 10 million units, mainly TAB (tape-automated bonding) packages. Oki Electric plans to boost its production capacity from the current 5 million units monthly to 7.5 million units. Hitachi's production capacity will reach 6 million units. Toshiba has increased LCD driver IC production to 2 million units per month, and NEC will double monthly production to 2 million units in 1992.



## **Display Backlighting**

Backlight technology is an important consideration in terms of portable computer performance. High brightness at low power consumption is essential for long battery life between recharging. Improvements in transmittance of liquid crystal displays themselves will be limited in the next few years. In fact, overall transmittance is going down as manufacturers add retardation films, color filter arrays, thin film transistors, and other performance enhancing layers. Therefore all improvements in the brightness/power ratio must come from backlight improvements.

At one time, electroluminescent panels were considered as backlight sources, and at some point in the future, these may constitute a viable option. At the present time, the industry standard is the cold cathode fluorescent lamp, supplied by Ushio, Mitsubishi Rayon and other Japanese firms. The lamp is incorporated in a diffuser housing to spread the light uniformly behind the liquid crystal display. The basic arrangement was shown in Chapter 2.

Recent improvements in backlighting technology were reported by Hathaway

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Bondir Config	ng uration	Au Bump IC Glass ITO Rubber Connector	Sn/Pb Bump	In Alloy	Cu Bump IC Glass ITO Paste	Au Ball
Bondi Metho	ng od	Rubber Connector	Solder	In Alloy	Conductive Paste	Conductive Paste
Driver	Pad	Au Bump	Sn/Pb Bump	Au/In Bump	Cu/Au Bump	Au Ball
IC	Pitch	100-300um	200-300um	50-150um	100-150um	60-130um
LC Pa	nel ITO	Au	ITO	ITO	ITO	ITO
Bond-	Temp	RT	300-350°C	120-150°C	100-120°C	100-120°C
ing	Pressure	<5 g/Pad		<20 g/Pad	1-2 g/Pad	<50 g/Pad
Repa R	Rability	0	X	0	0	0

# Figure 3-19 IC bonding methods in chip on glass packaging

Bonding Configuration		Au Bump ACF IC Glass ITO	Au Bump UV Resin IC Glass	Conductive Particle	Conductive Particle UV Resin IC Glass	
Bonding Method		AFC		Conductive Particle	Conductive Particle	
Driver	Pad	Au Bump	Au Bump	Al Pad	Au Pattern	
IC	Pitch	150-200um	<50um	60-130um	50-300um	
LC Panel ITO		ITO	ITO	ITO		
Bond.	Temp	160-180°C	RT	150-200°C	RT	
ing	Pressure	<50g/Pad	10-20 g/Pad	10-20 g/Pad		
_			UV Light	******	UV Light	
Repa Rability		Δ	0	Δ	0	

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and coworkers at Display Engineering, San Mateo, CA [19]. One such improvement involves the use of a wedge-shaped plastic light pipe which spreads light from a single lamp over the display area in a uniform fashion. Figure 3-20 show the construction of this device.

The wedgelight construction allows a single lamp to illuminate the display. The plastic molded light pipe contains prismatic specular reflectors which spread the light uniformly across the front plane of the device. Figure 3-21 shows the spatial brightness uniformity measurement.

In addition to improvements in conventional cold cathode lamp, a flat fluorescent lamp that directly illuminates the display is under development. Figure 3-22 shows the construction of the display, which measures only 3mm thick. Diagonal lengths from 25mm to 350mm should be possible using conventional cold cathode technology. The envelope of the lamp is constructed using one flat plate and one formed plate. A typical lamp consists of a serpentine channel of 4 intervals and an electrode on each end. This creates an effective lamp length of 800mm. Design of the flat lamp includes phosphor coating on both plates, with a reflective coating on the bottom plate. Currently, high voltages of 2,000-3,000 volts are required to operate the lamp. Table 3-21 provides a comparison of current backlight technologies.





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Item	Total Cost (\$)	Unit Cost
Control Circuits	12	
Driver ICs	44	\$2
Printed circuit board	13	6x11" @ \$.20/sq in
Frame	4	-
Elastomer connector	3	
Liquid crystal display	45	
(incl. polarizer)		
(polarizer)		\$3 each w/o retarder
Backlight	(5-7)	\$2.40 lamp + \$2.30 diffuser
Total materials	126	*
Assembly cost	24	
Standard cost	150	
Overhead	30	
Total cost	180	

 Table 3-20
 STN Display Cost

Figure 3-21 Spatial brightness uniformity of Wedgelight TM



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Parameter	Light Curtain	Conventional Lightpipe	Flat Fluorescent	Wedgelight Lightpipe
Total Length (mm)	280	225	235	220
Total Width (mm)	180	173	138	165
Display Length (mm)	188	188	200	188
Display Width (mm)	142	142	132	142
Thickness (mm)	18	6	3	5
Weight gm/cm <sup>2</sup> display area	0.9	0.63	1.00	0.31
Brightness (ft-L @ 2.5 watts)	114.5	112	90.4	175
Efficiency (lm/watt)	19	18.6	15	23
Uniformity (%)	±20	±10	±20	±10
Life (hours)	20000	20000	20000	20000

 Table 3-21 Comparison of Backlight Technologies



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# **Manufacturing Equipment**

Some of the characteristics of flat panel display manufacturing equipment are described in this section. For some equipment, such as substrate flatness measuring equipment, the outstanding feature is the similarity to IC manufacturing equipment in terms of equipment function and specifications. On the other hand, other kinds of equipment, like laser deposition, are found only in the flat panel manufacturing line. Even when the equipment function is the same as for IC's, the substrate size is much greater for a flat panel display, on the order of 1-2 ft<sup>2</sup> in area. Then too, the substrate is glass, which is more brittle and more liable to static charge buildup than a silicon wafer. Automation of process equipment is a question at every level, from cassette to cassette transfer of substrates in and out of process equipment, to automated transfer of cassettes from one station to another. Questions of cleanliness and particle generation in the equipment area are an issue only for certain kinds of equipment like plasma-enhanced CVD and orientation film rubbing. Otherwise, the same considerations and level of performance as for semiconductor manufacturing are required.

## **Substrate Cleaning**

4.1

Substrate cleaning is a repetitive process performed in long in-line systems that feed the glass plates one sheet at a time through the process chemicals and rinse stations. Batch-type tank systems can also be used. The kinds of chemicals, rinses, drying and baking methods have been described previously.

SPC (Shimada Riken) is a prominent supplier of substrate cleaning equipment. Equipment for LCD processing includes batch-type substrate cleaning, with ultrasonic agitation at 28KHz, 40KHz, and 850KHz using solvent or water, brush scrubbing, high pressure jet or shower. Hot water drying is available. Post polishing cleaning equipment is also available, with detergent, solvent, and ultrasonics.

Sheet fed, horizontal process equipment is used for developing, etching, and flaking. Flaking consists of removal of photoresist flakes by chemicals and water shower. Water and solvent removal processes make use of an air knife, IR heating, and UV illumination.

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## **Photoresist Application/Baking**

Both passive and active matrix displays make use of photolithographic processing, and the photoresist process equipment is very similar to that used in integrated circuit manufacturing. The exposure systems vary from relatively simple proximity aligners for passive matrix electrode definition to sophisticated step and repeat or mirror projection systems for TFT definition.

Photoresist coating and baking equipment for flat panel manufacturing is available from a number of suppliers, including Dainippon Screen, Chuo Riken, and Hamatech.

### **4.2.1 SPIN COATING**

Photoresist application consists of spin coating, with the appropriate modifications for substrate size and shape. Just a few percent of the photoresist remains on the substrate after coating. Concern about the materials consumption has led to evaluation of roll coating equipment.

## **4.2.2 ROLL COATING**

Experimental roll coating equipment is being developed by Dainippon Screen and Chou Riken. This equipment allows deposition of up to 70% of the dispensed photoresist, but so far, film thickness uniformity is lower than for spin coating.

#### **4.2.3 CONVEYOR OVENS**

Dainippon Screen and Chuo Riken manufacture tunnel ovens for soft and hard baking of photoresist. These are either hot plate or infrared heated units that work in tandem with coating, developing, and stripping systems. Complete units may exceed 30 meters in length.



## Photolithography

Photolithography equipment includes proximity, step and repeat, and mirror projection units.

A novel approach to imaging employing a "view camera" type of projector is available from Nippon Seiko K. K. [1]. This is a 1x projection unit, with a large camera resembling a bellows type camera used for professional portrait phoLIQUID CRYSTAL FLAT PANEL DISPLAYS

tography. Mask sizes up to 17" (432mm) can be used on the 26"x26" stage. A mercury arc source is used, and  $8\mu$ m resolution is currently achieved. Price for this unit is 15 million yen, which is approximately \$100,000.

### **4.3.1 STEPPERS**

Step and repeat units are typically used for thin film transistor manufacturing. These units are adapted from semiconductor production equipment, and are available from Nikon and MRS Technology.

The Nikon 1:1 step and repeat system is capable of  $3\mu$ m isolated lines, and  $4\mu$ m lines and spaces over large substrates. Alignment accuracy is 0.6 $\mu$ m or better. The model FX-210B can process 35 substrates per hour, and substrates of up to 550x500mm size can be handled. These substrates are large enough for six 10" displays per panel. Fields as large as 100mm can be exposed in one shot. Stitching of patterns is performed with an accuracy of 1.5 $\mu$ m or better. 6" reticles with pellicles are employed, so that the same maskmaking equipment and materials can be used as for IC manufacturing. Reticle storage library capacity is 13 reticles.

Special compensation is made for the glass compaction or shrinkage during TFT processing [2]. The scaling factor for correction of dimensions varies linearly from the center of the glass substrate to the edge. That is, the maximum process temperature of the center of the substrate is slightly higher than the edge, resulting in a linear change in compensation from center to edge. For example, a 20ppm decrease in dimension in the center would decrease by perhaps 0.02ppm for each 1mm distance from the center, resulting in a decrease in dimension of 15.6 $\mu$ m at a point 250mm away from the center. Design rules for TFT linewidths range from 4-10 $\mu$ m, and the overlay tolerance required is about 1/3-1/5 of the linewidth, or ±1.3-±0.8 $\mu$ m. This means that substrate compaction is a very serious problem for lithography.

Two approaches can be used for correcting glass shrinkage. The first compensates by adjusting the step pitch of the stepper. For the example above, when a 100m shot is printed at a distance of 200mm from the center, displacement of the center can be reduced to zero by adjusting the pitch of the stepper. However, errors will still remain at the edge of the pattern. In order to correct these errors, the lens magnification is adjusted, reducing the error due to glass scaling to less than 0.1 $\mu$ m when both methods are used together. Alignment marks on the panel are measured in order to determine the shrinkage and calculate the optimum position of each shot. These marks can be place between the TFT arrays or in the connector areas. LIQUID CRYSTAL FLAT PANEL DISPLAYS

The MRS Technology 5000 Panelprinter is similar in many respects to an IC stepper. It uses a 2X reduction lens with a resolution of  $3.0\mu m$  or better, critical dimension control to  $\pm 10\%$  or better, and depth of focus of  $15\mu m$ . Substrates of 450x500mm size can be processed at rates of up to 80 substrates per hour. Two 10" displays per panel are possible, depending on layout. Automatic adjustment to substrate size variation is achieved for scale adjustments of up to 100ppm in x and y axes. This allows butting accuracy of 0.75 $\mu m$  and overlay accuracy of 0.5 $\mu m$  or better.

A dual camera optical system with 0.15 numerical aperture lens is used. With dual cameras, 38 reticles can be accommodated, while 19 reticles are stored in the single camera system. Laser interferometry is employed for alignment.

The two camera system consists of a projection lens, mirror, focusing system, g-line illuminator, reticle chuck and reticle changer. Each camera focuses independently to compensate for substrate flatness. After stepping to the exposure location, it is possible to open both shutters simultaneously, exposing a 50mm square. For example, a 400x400mm substrate can be imaged with 64 subfields of 50mm each, enhancing throughput compared to a single lens system.

The laser interferometer controls x-y stage position, and also controls stage rotation to correct yaw.

A 3500 watt high pressure mercury arc lamp is used for each lens, delivering 200 mW/cm<sup>2</sup> of g-line illumination at the image plane, resulting in exposure times of 0.5-1.5 seconds with 1.5 $\mu$ m of positive photoresist.

System stability is achieved using stable optical columns, atmospheric pressure feedback to calibrate projection lens magnification, and substrate compaction correction by reticle chuck alignment. Measured system stability over 20 hours resulted in compensation within 2ppm of the desired value.

## **4.3.2 MIRROR PROJECTION**

The new MPA-2000 unit was described recently [3]. Figure 4-1 shows the optical schematic. Claims include a 480mm field illumination width without stitching, and 160 panel per hour throughput. A pair of concave and convex mirrors and a flat mirror make up the 1:1 projection system. The mask pattern is formed on a curved area which is 20mm wide. The area is 280mm long, and the radius of

LIQUID CRYSTAL FLAT PANEL DISPLAYS



Table 4-1	. Canon	MPA-2000	<b>Specifications</b>
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	<b>`</b>	4	
Resolution (µm)	3	4	6
Depth of Field (µm)	±20	±30	±40
Slit Width (mm)	9	14	20
Overlay Accuracy	10µm, 3 sigma		

In mirror projection, resolution and exposure time depend on slit width. If the slit is narrowed, higher resolution and longer exposure time will result. For wider slit width, lower resolution and shorter exposure time will result.

Display manufacturers are exposing 2 10" panels on a single 300x400mm plate. With a conventional aligner, four masks are used, and are stitched together, which might cause some inaccurate alignment. But the projection system can expose two 10" panels at once, and doesn't have a stitching problem.

High throughput of 160 panels per hour is achieved because the waiting time for changing masks is not required. This time amounts to 20 seconds, and limits throughput to 80 panels per hour for steppers.

A glass shrinkage rate of 5ppm is typical of thin film deposition, e.g.,  $1\mu$ m per 200mm span. Two alignment marks are measured at a time to align the mask and the plate. The error range on the plate against the mask is measured by magnified compensation marks set at the top and bottom of both the mask and the plate. Both laser alignment and TV camera alignment are used.

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## **Etching/Stripping**

Photoresist developing, etching, and stripping can be performed in continuous process lines available from Dainippon Screen and Chuo Riken. These lines incorporate a post bake step after developing. Where the etching process is well understood, it can be automatically included as the next step in the process track.

### **4.4.1 WET ETCH EQUIPMENT**

Wet etch equipment is therefore usually one module in a process line, in which preceding units develop and bake the photoresist, and subsequent ones strip it off after the etching step.

Batch etching can be used for processing flat panels, but is less common than the continuous track system. Wet etching will be used where possible in flat panel display manufacturing, due to its low cost, and effectiveness in removing particles and contaminants. However, for critical thin film transistor features, dry etching will be employed.

## 4.4.2 PLASMA ETCHING/ASHING

Dry etching or reactive ion etching equipment is made specifically for LCD applications by Plasma Systems, Plasma Therm, and Tokuda. Fine control of etched figures is one benefit from dry etching, at the expense of throughput and equipment cost. In some cases, it may be possible to combine wet and dry etching, as previously mentioned for ITO patterning. The speed and low cost of wet etching are employed for most of the material removal, while the control of linewidth and profile come from the final, dry etch step.

Tokuda's TPE-700A L/L reactive ion etch system is a cassette/cassette load lock system for etching a-Si, aluminum, molybdenum, tantalum, SiO<sub>2</sub>, Si<sub>3</sub>N<sub>4</sub>, and other films. It is possible to load 12 substrates into the feed cassette, and maximum size is 350x450mm. The etcher can be bulkhead mounted, and beltless substrate feeding is employed.

Tokuda's CDE-700A L/L chemical dry etch system is a cassette to cassette, load lock system for etching a-Si, silicon nitride, polysilicon, and metals such as molybdenum and tantalum. It features a 12 substrate send cassette, 350x450mm substrate size, and end point monitor for a-Si etching.

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Nextral, a French subsidiary of Alcatel, has designed a batch RIE system for TFT applications. The stainless steel cathode is covered with a quartz plate to minimize metal contamination. Substrates up to 14"x14" can be accepted. In addition to deposited inorganic films like a-Si, polymer films for tri-level systems can also be etched. System specifications are shown in Table 4-2.

Material	Thickness (µm)	Etch Rate (Å/min)	Uniformity (%0)	Throughput (panels/hr)
Amorphous Silicon	0.5	800	±5	6
Silicon Nitride	0.3	500	±3	6
Silicon Dioxide	0.2	500	±3	8
Polymer Film	1.5	1500	±5	3

Table 4-2 Nextral NE550	RIE System S	pecifications
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Table 4-3 summarizes currently available dry etching systems. Where available, price and throughput are noted.

# **Thin Film Deposition**

Thin film deposition includes sputtering for ITO and metal deposition, chemical vapor deposition, CVD, for polysilicon, and plasma-enhanced CVD, PECVD, for amorphous silicon and silicon nitride. Insulators such as silicon dioxide can be deposited by any of these techniques. Some thin films require thermal treatment and impurity doping. This applies especially to polysilicon, in order to produce films with high mobility and good transistor performance characteristics.

### **4.5.1 SPUTTERING**

Ulvac manufactures in-line sputtering and CVD equipment. Sputtering equipment is available in four substrate sizes, 350x360mm, 450x450mm, 550x600mm, and 650x750mm. Typical systems consist of four chambers; loading, heating, sputtering, and unloading. A full system has the loading station positioned in a clean room, with the rest of the system in a semiclean adjoining room. Total length of the system is about 12 meters. A return conveyor sends substrate holders back to the loading station in the cleanroom. Typical parameters for ITO deposition in

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Firm /Model	Max Substrate Size (mm)	Etch Chambers	Throughput (panel/hr)	Features /Price
Plasma System	IS			\$300-750K
DES-A125	600	1	10	cassette/cassette
DES-A324	450	1	30	beltless arm
DES-A525	450	2	30	
<b>DES-A725</b>	450	1-4	60	
Anelva				~\$1.6M
ILD-4802	700	1	8	
ILD-4803	700	1	20	
ILD-4804	700	2	20	
Tokuda				
TPE-700AL		1	-	through the wall
CDE-700AL	4	1	-	e
TEL				~\$1-1.5M
MEA-450SA	A 450	2	-	dual chamber
MEA-450SF	R 450	2	-	PE, dry ashing
MEA-450SF	<b>2</b> 450	2	-	RIE
Thermco Int'l	297x209	1	-	10000000000000000000000000000000000000
Ulvac	350	1	-	in-line
Nextral NE550	350	1	6-8	2 panel chamber

#### Table 4-3 Dry Etch Systems

a pass-by mode of operation are shown in Table 4-4. A system is also available for horizontal upward sputtering. This method may allow fewer adhering particles.

Leybold Heraeus in-line sputtering systems are available for two sided deposition, continuous operation with substrate heating up to 400°C on substrate areas as large as 900x1500mm. Load-lock introduction of substrate carriers is accomplished in two stages, with the second stage also containing a preheater. The sputtering module also contains an infrared heater positioned between the two panels, and DC magnetron sputtering units are mounted outboard on both sides. Three sputtering cathodes are mounted side by side. These targets measure approximately 19.5"x3.5".

Tokuda's sputtering System 522 is designed for in-line DC magnetron
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Substrate Size	350x360mm, 450x450mm, 550x600mm, 650x750mm
Sputtering Method	DC magnetron, both sides, pass-by
Film Thickness Uniformity	±5% or better
Deposition Temperature	200°C±15°C (typical)
Throughput	25,000 substrates/month, 2.5 min. cycle, 24 hour/day, 22 days/month
Ultimate Pressure	5x10 <sup>-6</sup> Torr (sputter chamber)
Carrier Transfer	Bottom rack and pinion gears
Main Pump	Turbomolecular

 Table 4-4 Ulvac SDT-VT In-line Sputtering Systems

sputter-deposition of metals such as molybdenum, tantalum, chromium, and aluminum. ITO deposition is also possible. Maximum substrate size is 350x450mm, and a 16 sheet substrate loader is available.

## **4.5.2 CHEMICAL VAPOR DEPOSITION**

Chemical vapor deposition of thin films is well developed for IC manufacturing, and the equipment cost and performance are extremely favorable compared to other wafer fab equipment. In contrast, thin film CVD equipment for flat panel manufacturing is expensive and inefficient, compared to other equipment in the manufacturing line. The primary thin film is the semiconductor silicon. Right now, amorphous silicon is the standard material, but polysilicon is also used, and may become even more important in the future. These two kinds of silicon are deposited in different ways.

Other kinds of thin films deposited by CVD include silicon nitride and occasionally silicon dioxide. Plasma-enhanced CVD is standard for silicon nitride, and silicon dioxide can also be deposited by sputtering.

The various methods of deposition for amorphous silicon and polysilicon are described below. Polysilicon can be obtained from amorphous material by a sequence of heat treatments, or a deposited poly-Si source can be used; usually the grain size of deposited poly-Si must be enlarged by thermal processing. Polysilicon can also be deposited by sputtering. Some of the companies making relevant equipment are shown in Table 4-5.

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Thin Film Type	<b>Equipment Supplier</b>	
PECVD for Amorphous-Si	Anelva, Ulvac, Shimadzu, Elletrorava,	
(20% hydrogen content)	Nextral	
LPCVD, poly-Si	ASM Japan, Leybold/Rytrac	
APCVD, poly-Si	Watkins-Johnson	
Sputtering, poly-Si	any sputter equipment	

The critical process of PECVD for a-Si is described further on. Generally the equipment manufacturer does not guarantee a process. Hydrogen content of the film is determined during deposition and subsequent heat treating; hydrogen content is critical to thin film properties. While polysilicon deposition is well understood from its development for IC applications, the high temperature process, too high for a glass substrate, produces the best transistors. A good low temperature process is required.

Polysilicon films require annealing to enhance grain growth. Performance of TFTs made from polysilicon depend on the number, size and other characteristics of grain boundaries between grains. The carrier mobility of the films is low when the extent of grain boundaries is large compared to the area of single crystal grains. Annealing methods that create large grains produce films with higher mobilities. There are a number of compromises involved in recrystallizing material on either a glass or quartz substrate. Of course, the temperature capability of the substrate is paramount. The high temperature poly-Si deposition techniques for either LPCVD or APCVD require quartz, limiting applications to small displays for video cameras, about 1" on a side, or for projection displays, where 3" LCD shutters are typical. Direct view displays require a low temperature process and a glass substrate. The temperature capability of typical glasses has been discussed in a previous section of the report.

Source material for recrystallized polysilicon includes amorphous silicon deposited by PECVD at low temperatures, 350°C or less. This material contains hydrogen that must be removed by annealing prior to recrystallization. Low temperature CVD of polysilicon is also possible, but control of materials properties is more difficult for low temperature deposition. Sputtering is a potentially low cost, low temperature deposition method, and one example has been mentioned previously. LIQUID CRYSTAL FLAT PANEL DISPLAYS

Recrystallization techniques, already investigated for integrated circuit processing, include the following:

• Rapid Thermal Annealing, focused or unfocused beam (a-Si or poly-Si)

Rapid thermal annealing is a commercial process for annealing of implant damage, and can be applied to recrystallization of a-Si with at least 700°C annealing. In order to reach this temperature yet stay below the strain point of the glass substrate, the annealing must be limited in physical area, and must be very short in time, less than 1 second. Unfocused lamp annealing, used for implant activation in silicon wafers, may not be directly applicable. Instead, some kind of focusing will be required, to limit the physical extent of the high temperature region. Aktis Corporation is researching the applications for lamp annealing in TFT manufacturing.

- Zone Melting Recrystallization (poly-Si)
- Solid State Recrystallization (a-Si or poly-Si)

Solid state recrystallization requires very long times of 5-75 hours at temperatures between 500°C and 625°C. Commercial furnaces are employed.

• Laser Recrystallization (a-Si or poly-Si)

An XeCl excimer laser has been used to recrystallize a-Si films at temperatures as low as 150°C [4]. The films were first raised in temperature to release hydrogen, then lowered in temperature to induce recrystallization. The glass substrate reached a temperature no greater than 200°C at 600nm below the surface during this annealing. Very thin films of 15-120nm were deposited, and complete melting of the films occurred. It may be possible to use laser recrystallization for polysilicon devices at the edge of the display, converting a-Si to poly-Si, then building driver circuits on-board the glass substrate. A commercial system from XMR for annealing has been described by Chu and Chen [5]. This system was used to recrystallize a-si films deposited by PECVD, and poly-Si films deposited by LPCVD. For a-Si material, grain size ranged from 10-90nm, depending on laser energy density. For poly-Si, much larger grains of 200-400nm were obtained.

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## 4.5.3 PLASMA CVD

Anelva is a major supplier of both plasma-enhanced chemical vapor deposition, PECVD, and physical vapor deposition, PVD equipment. In-line vertical both-sided deposition systems have been described recently [6]. These systems have several vacuum chambers connected with gate valves. Degassing is performed in the loading chamber. Heating prior to deposition may be done in a dedicated heating chamber, after which the substrates are moved to the deposition chamber. A sequence of depositions can be performed one after the other without removing the substrates from the system. After deposition processes, trays which hold the substrates are removed and returned to the loading chamber. Three or four substrates, 300x400mm can be loaded onto each side of the tray.

A typical PECVD sequence involves silicon nitride followed by a-Si, then  $n^+a$ -Si. Each material is deposited in a dedicated deposition chamber. The interface between the nitride and the a-Si must be free of any contaminants. In addition, the SiN film is deposited at high temperatures, 300-350°C, and a cooling chamber is usually set up between the SiN and a-Si deposition chambers.

Figure 4-2 shows a schematic of an in-line system for depositing the sequence of thin films mentioned above. Substrates pass through each chamber on racks in a fashion shown in Figure 4-3, a schematic outline of chamber construction for TFT fabrication. Figure 4-4 shows the cross-section of the deposition electrode. Substrates are on both sides of a central heater, usually an infrared heater. The RF electrodes face the substrates on both sides, and reactive gases are introduced through the electrode surfaces. Baffles are placed between the chamber and the pump exhaust port to minimize particle generation during initial pumping.





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Figure 4-4 Cross section of PEVD electrode

Table 4-6 shows the specifications for the various models.

	ILV-9100	ILV-9300	ILV-9300L	ILV-9300E
Chamber Size (HxWxD)	900x800x350	1200x1100x350	•	1200x1450x430
Electrode Size (HxW)	570x570	800x800	800x900	800x1080
Tray Size (HxW)	625x600	920x910	920x1000	930x1200
Deposition Area	450x450	650x650	650x750	650x900

 Table 4-6 Anelva In-Line Plasma CVD Systems (dimensions in millimeters)

Typical deposition conditions and results are shown in Table 4-7.

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	ILV 9100	ILV 9300
Deposition Temperature	250°C	300°C
Gas Flow		
SiH₄	200 SCCM	300 SCCM
H <sub>2</sub>	800 SCCM	1200 SCCM
Electrode Power	100 W	148 W
Total Pressure	110 Pa	110 Pa
Electrode Gap	45mm	45mm
Deposition Rate	240Å/min	154Å/min
Deposition Uniformity	±20Å/min over substrate	±15Å/min over substrate

 Table 4-7 Amorphous Silicon Deposition

Shimadzu, another supplier of plasma CVD equipment, recently introduced a new vertical, dual surface PECVD machine, which can accept eight 300x400mm substrates in a single run. The system includes lower particle generation and deposition than' earlier units.

Elettrorava in Italy manufactures a multichamber PECVD unit which allows deposition of multiple films in up to 7 process chambers arrayed around a central isolation chamber which includes a robotic arm for movement of substrates from one chamber to the other. Elettrorava is a Turin, Italy based company with experience in vacuum components and semiconductor deposition systems. The system is designed by MV Systems in Golden, CO, USA. MV Systems is a small company whose founder, Aron Madan, has considerable experience in thin film deposition. Systems have been sold to the University of Utrecht, the Netherlands and to CNRL-Lamel (Italy).

Nextral has developed a PECVD system based on a-Si deposition technology from Solems, the French solar cell manufacturer. The system is designed for process development and pilot production of sequential thin films for TFTs. Substrates up to 14"x14" size can be accommodated. Process specifications are shown in Table 4-8.

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Material	Deposition Rate (Å per minute)	Uniformity (%)	Throughput (panels/hr)
a-Si 0.4µm thick	120	±3	2
$Si_{1}N_{1}$ 0.3µm thick	100	±5	2
$SiO_2^4 0.2 \mu m$ thick	250	±3	4

 Table 4-8 Nextral ND 400 PECVD System Specifications

Applied Materials has announced its entry into the flat panel display equipment business, although an actual product does not yet exist. Their plasma CVD and etch equipment is likely to be a single substrate cluster tool type of arrangement, similar to that used for CVD and etching in some advanced semiconductor processing operations. Equipment is expected to be available at the end of 1992.

## 4.5.4 LPCVD AND APCVD

Leybold Heraeus provides a low pressure CVD deposition system for polysilicon which can be used in AMLCD applications. This equipment was previously manufactured by Rytrack, Liverpool, UK. A similar system is supplied by ASM Japan. Polysilicon films can be deposited as low as 580°C, while amorphous silicon can be deposited as low as 550°C. (This amorphous material is not suitable for devices in the as-deposited form. It must be recrystallized to produce large grain polysilicon.) The furnace is a hot wall batch type bell jar system that can accommodate 30 substrates per run. Substrate sizes of up to 300mmx300mm can be accommodated. Table 4-9 shows typical process specifications for a-Si and poly-Si films.

Atmospheric CVD allows very high throughput of material, ranging from 3-6 square meters per hour. In one case, a belt furnace design is semicontinuous in operation. Applications for LCD panel manufacturing include  $SiO_2$  deposition systems, and AMCVD deposition of polysilicon on quartz for viewfinder displays.

The silicon dioxide system can coat substrates up to 12.5" wide, and CVD is performed in 3 chambers. Specifications on film properties include  $\pm 10\%$  film thickness uniformity,  $\pm 10\%$  dopant concentration uniformity, 10MV/cm dielectric film breakdown strength, and particle counts of <0.1/cm<sup>2</sup> (0.5µm or larger). Table 4-10 shows the relation between belt speed, film thickness, and throughput.

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	a-Si	poly-Si
Deposition Temperature	570°C	630°C
Growth Rate	25Å/min	50Å/min
Uniformity		
Within Plate	±5%	±5%
(300x300mm)		
Plate to plate	±5%	±4%
(30 plates)		
Run to run	±3%	$\pm 3\%$
(10 runs)		
Throughput	9 plates/hr	8 plates/hr
Film Properties	recrystallizes at low temperature	grain size = 1000Å, no twinning

# Table 4-9 LPCVD Silicon Films (Leybold LC350 Reactor)

 Table 4-10 Watkins-Johnson SiO2 Deposition System

Belt Speed (inches/min)	Max. Film Thickness (1000Å)	Throughput (m²/hr)
6	10	2.74
8	7.5	3.66
10	6	4.57
12	5	5.49
14	4.2	. 6.4

Applications for the high quality oxides produced in this system include glass substrate initial coating, transistor gate oxide, crossover dielectric, and final passivation.

## **4.5.5 THERMAL PROCESSING**

Thermal processing refers to recrystallization of polysilicon by some sort of heating after deposition. If transistors are made from polysilicon, the source and drain regions will probably be implanted, which means another heating step is required to activate the implant, therefore more thermal processing is required. In

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order to achieve low cost, polysilicon thermal processing should be done on glass, which greatly restricts the possible heating schemes.

Aktis is a California company formed as a joint effort of Peak Systems and Mitsubishi. Peak is a manufacturer of lamp annealing equipment used in IC processing, and Aktis' focus is on application of lamp annealing for polysilicon recrystallization. This kind of annealing is one of the only ways to bring the temperature of the thin film to the melting point without heating the underlying glass. One alternative is an extremely long anneal in a standard furnace to induce solid state recrystallization. Since the latter is a time consuming batch process, lamp annealing is more attractive for its long term productivity potential. Laser annealing, mentioned previously, is also an alternative for recrystallization, at least for selective areas. For example, recrystallization may be restricted to the area around the outside of the display where on-board ICs are fabricated. The as-deposited polysilicon may be good enough for TFT switches at each pixel.

A low thermal budget process for poly-Si TFTs on 7059 glass was described by Liu and Fonash[7]. This process combines several technologies for material processing and low temperature including

• Rapid thermal annealing to obtain recrystallized polysilicon from a-Si:H films. a-Si films were deposited at 250°C. Thickness of the deposited amorphous silicon layer was 2000Å. Polysilicon films were formed by annealing at 650-700°C for 50-5 minutes, with grain size of about 1 $\mu$ m. Source/drain regions had been implanted, and recrystallization also served to activate the implants.

• Magnetron sputtering at 220°C for deposition of the gate oxide from a SiO<sub>2</sub> target. Oxide etch rate was 40Å/sec in dilute HF, comparable to oxides deposited in other ways

• Electron cyclotron resonance generation of hydrogen to passivate the gate oxide. TFTs were passivated at 300°C for 5 or 15 minutes. Total pressure in the system was  $1.2 \times 10^{-4}$  Torr, and power was 600W. TFT mobility was found to be in the 60 cm<sup>2</sup>/Vs range

## 4.5.6 ION IMPLANT/DOPING

Polysilicon transistors source and drain regions have to be doped with conventional doping methods, unlike amorphous silicon devices for which the doped layer is deposited by CVD. For small substrates, such as the quartz substrates now

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being used for projection TV displays, standard IC equipment can be used, including a normal ion implanter. The situation will be quite different if a low temperature polysilicon process is developed for large substrates; standard ion implanters will be difficult to use. Two different approaches have been adopted to large area, high throughput implantation of dopants.

## **Phased Linear Scanner**

The phase linear scanner from Superion is designed to permit ion implantation of large area substrates without the use of a conventional rotating disc substrate holder[8]. Ion implanters for silicon wafer integrated circuit processing make use of batch processing, and wafers are placed on a rotating substrate holder. For large substrates such as 300x400mm glass substrates for liquid crystal displays, the rotating substrate approach is inefficient.

Ion implantation must be accomplished holding the beam fixed, and moving the substrate underneath. If a single substrate is scanned back and forth under the beam, a significant amount of time is required to reverse the scanning direction at each end of the traverse, which limits the productivity of the implanter. The phased linear scanner moves two substrates past the ion beam in a synchronized motion so that one of them is always under the beam, and the dead time due to reversing the scan is accommodated by implantation of the second substrate. The concept can be applied to any number of substrates.

An end station using the phased linear scanner is shown in Figures 4-5 and 4-6, in plan and side view cross-sections. The substrates are supported on two target carriages which are scanned along the track as determined by the position of the followers in the racetrack driver. The carriages are driven by wire drives from pulleys driven by two oscillatory rotary drives, labelled X1 and X2. The scan frequency is in the range 1-3 Hz, that is, 2-6 passes through the beam per second. The end station is only 75mm deep, and can accommodate secondary electron collector plates. An external magnet controls the secondary electron trajectories and an electron flood gun can be installed in order to prevent substrate charging.

A typical implantation requirement might be  $1-3 \times 10^{15}$ /cm<sup>2</sup> of phosphorus ions at 100keV and 5% uniformity, substrate size of 300x400mm, and a maximum temperature rise of 200°C. A 2-substrate system operating at 3Hz would achieve a throughput of 10-20 substrates per hour, assuming the beamline can deliver the required beam current.

## LIQUID CRYSTAL FLAT PANEL DISPLAYS



**Figure 4-5** *Plan view of phased linear scanner showing two substrates* 



**Figure 4-6** Cross-section view of linear scanner end station

### **Ion Flux Doping**

Part of the expense of an ion implanter comes from the magnetic focusing to separate ions from each other as they travel toward the substrate. In some cases, isotopes of an element are separated from each other and only one is selected. On the other hand, a non-selective implantation might be used, as long as the ions that hit the substrate contribute to doping, or at least don't interfere with it. Ion flux doping is the way to do this, and is already in industrial use in other industries for the coating of metal parts with wear resistant thin films and other applications.

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A low temperature poly-Si process combined with ion-flux doping was reported by Asahi Glass[9]. The polysilicon was recrystallized after deposition by CW argon laser scanning at 13.0 m/sec. An average grain size of 30nm was obtained, and mobility was 40 cm<sup>2</sup>/Vs.

One difference between TFT fabrication on amorphous and polysilicon materials is in the doping for transistor source and drain formation. N-type doping can be accomplished in the deposition of amorphous silicon, and typically an undoped a-Si layer is followed with the  $n^+$  a-Si layer deposition in sequence in the same in-line PECVD system. Polysilicon needs some kind of recrystallization process, which would diffuse the dopant throughout the layer, so some kind of doping process must be used. Ion implantation of the kind used for IC manufacturing can be used, but less expensive alternatives are attractive. One of these is non-mass-separated ion flux doping, in which gaseous sources are ionized and accelerated onto the substrate.

In the study reported here, the source gas was either pure phosphine, or 5% phosphine in hydrogen. The ion flux was created by a bucket type ion source using RF discharge and a magnetic field. The flux was extracted and accelerated by 2.5-10.0kV onto samples that were neither heated nor cooled. For pure phosphine source gas accelerated at 5.0kV, the phosphorus concentration peak is at 10nm. Sheet resistance of the doped layer is a function of the subsequent annealing temperature. At 300°C, a sheet resistance of  $10^4\Omega$ /square was obtained for 5kV acceleration. With 10kV acceleration, a higher annealing temperature is required, possibly due to more extensive implantation damage. Functional transistors were obtained, and the highest process temperature for transistor formation, including polysilicon deposition and several annealing operations was less than 450°C.

A bucket ion source for doping polysilicon was described by Kawachi and coworkers at Hitachi[10]. The ion source arrangement consists of a cylindrical plasma chamber, 250 mm diameter. 24 permanent magnets surround the chamber, which contains ion extraction electrodes and a hot filament cathode. Figure 4-7 shows the chamber schematic. The 150mm ion beam was extracted from the arc discharge plasma and irradiated the sample directly, without mass separation. The discharge gas was 1% phosphine, diluted with either hydrogen or helium. Ion acceleration voltage was 500V, and ion current density was varied from 0.125mA/ cm<sup>2</sup> to 0.5mA/cm<sup>2</sup>.

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A 100mmx100mm sample was irradiated by the ion source, and uniformity of irradiation was  $\pm 5\%$  at 0.125mA/cm<sup>2</sup>. Activation of implanted samples was performed with a XeCl excimer laser using a fly's eye lens integrator to achieve  $\pm 6\%$  uniformity of laser beam intensity over a 8x8mm area. The sheet resistance of doped films was less than 1000 $\Omega$ /square after an irradiation time of only 10 seconds!

## Test Equipment



## 4.6.1 VISUAL AND FUNCTIONAL TEST

Examples of equipment for flat panel display measurement include the Nanometrics critical dimension (CD) equipment, model 210LCW/SP400. Optical inspection



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systems based on modified optical microscopes include the Olympus MHL100 for up to 450x400mm substrates, soon to include an automatic substrate transfer system. Nikon also supplies macroscopic and microscopic optical inspection systems for flat panels. The macroscopic system is used for visual inspection for particles, scratches, and surface irregularities.

## **4.6.2 OPTICAL IMAGING**

Automatic, high speed imaging and cataloging of defects requires complex hardware and software, originally developed for applications like integrated circuit photomask inspection, and for image processing in satellite photographs. Two types of equipment that have been adapted for flat panel display inspection are described here.

There are many similarities between optical inspection for IC mask or wafer manufacturing and for flat panel displays. However, some key differences exist as well. Common practices for masks and wafers are compared to the flat panel display inspection requirements by Hendricks and Kawamura of KLA Acrotec[11].

For IC mask shops, one function of optical inspection is to serve as a "Pass/Fail Gate". Automated inspection is performed immediately after the last cleaning process and if defects are detected, their coordinates are transferred to a repair station, the mask is repaired, then recleaned. Finally, the mask is re-inspected to verify that all defects have been repaired. The corresponding function at the wafer manufacturer is "Mask Qualification", where optical inspection is used to verify the perfection of incoming mask shipments. These functions are identical for IC masks and reticles for optical steppers.

Many mask shops and wafer fabs use optical inspection for "Engineering Analysis." Many papers on defect source analysis have been presented, in which optical inspection is used to inspect the wafer at different points in the process, to determine where defects are occurring. The object is to identify a faulty process, rather than to identify and correct specific defects on a given wafer.

A companion function of optical inspection is "Process Audit". For this function, optical inspection serves to monitor and compare defect levels, to give early warning of manufacturing problems.

These functions of optical inspection can be applied to flat panel manufacturing as well. For example, a "Pass/Fail Gate" can be established using optical

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inspection. However, in a photomask, every defect greater than a certain size is a fatal one. This may not be the case for defects on a TFT substrate. The automated inspection routines many be able to distinguish fatal and non-fatal defects. Engineering analysis will be the most important function of optical inspection during the early phase of flat panel manufacturing. For example, to distinguish between a fatal and non-fatal defect for pass/fail inspection, an engineering analysis has to be performed first.

For the initial stages of TFT manufacturing, the inspection methods are similar to those for photomasks, and only the substrate size is different. Later in the process, TFT construction and geometries become very complicated. These patterns closely resemble those on IC wafers, and appropriate inspection technologies can be used.

**Optical image processing** has been used in non-semiconductor applications, for example in filtering noise from electronic images. For optical image processing, a Fourier-plane filter blocks out repetitive patterns and leaves the non-repeating features. Defect identification should be simple threshold detection of the filtered imaging. Advantages of this method are:

 $\bullet$  High inspection speed can be achieved with simple electronics, since the complicated part of the image processing is done by the optical filter.

• Relatively large depth of field can be achieved and it is possible to detect defects with relatively low resolution. This latter benefit may not be too important in TFT array inspection, since design rules are large compared to integrated circuits.

Disadvantages of optical image processing include the following.

• False defects can arise from the use of coherent (laser) illumination. Very small changes in film thickness and refractive indices of thin films will lead to false defect detection.

• It is difficult to distinguish a fatal from a non-fatal defect.

 $\bullet$  Because the Fourier transform limits the inspection to repetitive patterns, a border area exists at the edge of the array that cannot be inspected.

• Long term stability of laser intensity may be a problem.

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## **Optical Image Processing Equipment**

Inspection of panels using optical image processing was described by Lin and Carroll of Insystems[12]. In optical pattern filtering, collimated, coherent laser light shines on a repetitively patterned substrate. Light reflected from the patterned surface diffracts in specific directions determined by the pattern layout. An objective lens collects the light and produces a pattern of bright spots in its back focal plane. This pattern of bright spots is the "optical Fourier Transform" of the pattern on the substrate. A spatial filter (hologram) placed in the backplane can selectively suppress light corresponding to specific pattern elements. The light which remains can then be imaged or further processed.

If all the repetitive information is suppressed, the spatial filter would have opaque dots corresponding to the bright spots of the optical Fourier Transform. A defect-free substrate would therefore show no image at all, since the diffracted light would be exactly canceled by the spatial filter. Where defects are present on the substrate, diffracted light passes through the filter, and can be imaged either optically or electronically. Typically, a video camera is used. Since the field of view of the camera is small relative to the substrate size, the substrate must be scanned. During the scan, the spatial filter is stationary because the pattern of dots is independent of substrate position. Figure 4-8 shows a conceptual diagram of the method.

The speed and accuracy of inspection of LCD substrates is dependent on the intrinsic noise level of the sensor and other system components. Some intuition



Figure 4-8 Optical pattern filtering for defect imaging

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about the number, spacing, and size of defects is necessary in order to achieve sensitive detection at high scanning speeds. The practical limit on the coarseness of resolution of the sensor might be taken as twice the expected spacing of the defects. For example, if we expect no more than one defect per  $100 \times 100 \mu m$  area, and wish to know the defect location with a precision of  $20 \mu m$ , the picture elements on the sensor might correspond to  $20 \times 20 \mu m$  area. Such a sensor would have a wide field of view and correspondingly high throughput, up to  $400 \times 400 \text{cm/sec}$ .

Other factors which reduce this theoretical scanning rate include the irregularities of the substrate, which create a dim residual background noise pattern with a periodicity similar to that of the device pattern. Textured surfaces such as metal patterns exhibit such noise prominently. Other noise sources include scattering and reflection in lens elements of the inspection optics, and diffractive effects in the spatial filter itself. A critical signal to noise ratio of 5 to 7 is needed to distinguish defects from this background noise. For detection of a 1 $\mu$ m sized defect on a substrate, which might be typical of TFT processing, the imager pixel size is about 4x4 $\mu$ m. Assuming that information can be processed at a rate of 10<sup>8</sup> pixels/sec, then the substrate can be scanned at a rate of 16x16cm/sec. This means that a 320x350mm substrate with two 10" TFT panels could be inspected in less than one minute.

Analog image processing employs two inspection heads that scan identical parts of an image in parallel. The output of the two channels is compared by analog electronics. These systems are useful for mask inspection, but not for complex patterns on wafers. The advantage of analog optical inspection is

• High speed inspection can be achieved with simple electronics

Disadvantages include

- Restricted image processing capability
- Analog filtering limits flexibility

**Digital image processing** takes the output from a camera or other sensor, digitizes it, stores it in memory, and then applies any one of a number of algorithms (procedures) in order to locate the defects. Both the electronics and the algorithms are complicated, and the optical subsystems have to be designed

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together with the design of the defect detection procedures. This results in a complex, expensive system. Its advantages are

• Flexibility in distinguishing between kinds of defects, fatal vs non-fatal and so forth

High sensitivity even on complicated images

• Repeatable and predictable defect detection due to the digital nature of the procedures.

#### Disadvantages include

 $\bullet$  A very large engineering effort is required to develop the electronics, algorithms, and optics

• The resulting systems are very expensive

### **Digital Image Processing Equipment**

The KLA Acrotec 6000 series inspection systems employ digital image processing to identify defects on flat panel display during the manufacturing process. The technology is an extension of that used for IC wafer inspection. KLA Acrotec is a joint venture of KLA Instruments (San Jose) and Nippon Mining (Tokyo). The company was founded in October of 1990 with the charter to produce equipment for inspection of flat panel displays.

Panel size of up 500x500mm can be accommodated. The optical system is set up in two modes, for low magnification to locate defects, and high magnification to identify them. The currently available system is a manual load system that inspects the repeating pattern only, and does not locate defects on the periphery of the panel. Table 4-11 shows the operating parameters of the system in the two magnification modes.

#### **4.6.3 ELECTRICAL EVALUATION**

Electrical evaluation includes standard measurements of film resistivity and mobility, performed using the same equipment as for semiconductor manufacturing. On the other hand, parametric testing of partially completed TFT panels requires substantial modification of the test procedures used for integrated circuits. Two approaches have been recently reported.

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	<b>High Magnification</b>	Low Magnification
Objective Lens		4x
Depth of Field	>50µm	>100µm
Pixel Size	3.25µm	6.50µm
Size of Smallest Defect	4µm	7μm
Scan Speed	5cm <sup>2</sup> /sec	20cm <sup>2</sup> /sec
Stage Speed	120mm/sec	240mm/sec
Scan Time	140 sec	35 sec

## Table 4-11 KLA Acrotec 6000 Parameters

## **Transfer Admittance**

The transfer admittance method has been adapted from other circuit testing applications to TFT arrays, as described by Hall and coworkers at GenRad[13]. An electrical prober makes contact with gate and drain lines. Figure 4-9 shows the test method for the case where storage capacitors are connected together using a separate (common) bus. A combined AC and DC test signal is applied to each gate line, and currents are measured simultaneously by detectors connected to many drain lines. The transfer ratio is admittance whose phase components give conductance, G, and capacitance, C. Conductance and capacitance differences are sensitive measures of faults because they vary only slightly over the area of a panel.

Substrate guard rings are often used to protect the TFTs from high electrostatic voltages during panel manufacture. These rings are removed prior to completing the manufacturing process, but their presence can complicate the electrical measurements performed by the admittance method. Basically, the guard ring must be designed with such testing in mind, as well as the electrostatic protection function.

Most common electrical defects are detectable by this test method. These include most open circuits and shorts, as well as TFTs with high on resistance and leakage of the storage capacitor. Many of these defects can be located and identified as well as simply detected. A typical test setup might employ a probe array to contact all 480 gate lines of a 10" display. A second set of probes would contact 240 of the 1920 drain lines. This second set would be stepped to make the other drain line connections. A defect-free panel could be tested in 3-4 minutes, depending on the number of detectors used. Identifying and recording any faults would require extra measurement time.

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### **IBM Test Set**

An electrical test system has been built by IBM to test in-process TFT arrays[14]. The set consists of a probe contact assembly to contact the gate and data lines of the active matrix, circuitry to perform the test, and a PC to control test operation and interpret test results. Software control of testing procedures allows the hardware to perform a variety of different tests.

The test circuit can write charge on any cell in the active array, hold the charge on the cell for a predetermined length of time, and then read the charge from the cell and measure it. This sequence of events is called a basic test. By varying the parameters of the test, such as gate pulse height and width, hold time and so on, it is possible to extract the gate threshold voltage, cell charging time constant, cell OFF current, and other cell parameters.

The first step in a single charge test is to stabilize the data voltage at the value desired for the test. At this point the gate voltage is in the off state, switch S1 is open to disconnect the data line from the data voltage source, and switch S2 is closed to reset the integrator to the preselected level. Next, S1 is closed, connecting the data voltage to the data line. The gate voltage is then turned on. At the end of the gate pulse the tester enters a hold time, and during this period the

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charge that has been transferred to the cell is stored on the cell capacitance. This emulates the display, where charge is stored on the cell capacitance for a frame time. During the hold time the data line is disconnected from the data voltage source by opening switch S1. The data line is then connected only to the inverting input of the operational amplifier, which is used as a virtual ground, and the voltage on the data line must then relax to ground.

After the data line voltage has relaxed to ground, the integrator capacitor (C1) is released from the reset voltage level. The integrator will now begin to integrate the negative of the current into the inverting input of the operational amplifier.

At the end of the hold time, the gate voltage is turned on to connect the cell capacitance to the data line. The gate voltage is held on for several cell discharge time constants to insure that all of the charge on the cell capacitance can return to ground through the operational amplifier input.

After the gate voltage is turned off, the system waits for at least a gate line time constant, and then takes a reading using the analog to digital converter that is connected to the output of the operational amplifier. The difference in voltage between the reset voltage of the integrator  $V_{ref}$  and the reading of the analog to digital converter is proportional to the charge that was stored on the cell capacitance ( $Q_{cell} = (V_{A/D} - V_{ref})C_1$ ). The reset voltage of the integrator can be externally adjusted to keep the integrator output voltage within the range of the analog to digital converter.

The output voltage of the integrator can be measured as a function of time during the test. The output voltage shows an initial decrease as the gate voltage is raised to remove the stored charge from the cell. Previously, the output voltage of the integrator had been held constant by the reset circuitry. The increase in the gate voltage is capacitively coupled to the data line by the total capacitance between gate and data line. The thin film transistor is turned on long enough to ensure complete discharging of the cell capacitance to the virtual ground of the operational amplifier. When the gate voltage is turned off, the integrator output voltage shifts, and now represents the charge that had been stored on the cell.

Because the shift in the integrator output voltage depends on the total capacitance, the total capacitance of the cell between gate line and cell can be determined. If there is a discontinuity in the channel of the transistor, the capacitance due to the

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channel and the source of the transistor will be reduced. This will be seen as a reduction in size of the initial decrease of the integrator output voltage. The test can ensure that crossover and transistor capacitances are correct. It is also possible to determined low resistance between the gate line and the data line or pixel flag. If a low resistance exists, current will flow to the virtual ground of the transistor when the gate line is biased ON, and the current will continue to flow as long as the gate is biased ON, saturating the output of the integrator.

A quick scan through every cell can be made, writing and reading charge in each cell. Cells that do not store enough charge, and cells that store too much charge are marked as suspect cells for detailed analysis using other tests. This constitutes a rapid GO/NOGO test.

Cells that do not store enough charge may have a charge leakage path, which can be checked by using the leakage current test, or the cells may have a transistor which is not providing sufficient ON current. The transistor performance can be tested using the dynamic threshold test and the charging time constant test.

To estimate the value of the dynamic threshold voltage, the data voltage is scanned at fixed gate voltages. The charge transferred to the cell capacitance saturates a certain charge value in each scan. The data voltage at the saturation point determines the threshold voltage of the thin film transistor since the saturation is due to the transistor being cut off. Dynamic threshold voltages of about 3 volts have been observed.

By varying the write gate pulse width, the charge on the cell will saturate at a certain width. This is the minimum gate pulse width that will ensure good image quality. Experimental data indicate a value of 5 microseconds in the tests performed here.

Leakage current can be measured on each cell. The source of leakage current can be the transistor channel, insulating films, or the liquid crystal material. Experimentally, the charge on the cell decreases by about 5% over a frame time of 15ms.

The testing procedure allows only good transistor arrays to continue processing. This can be a significant cost savings. An acceptable defect level is expected to be only 1 in 50,000 cells to 1 in 100,000 cells. It will be impossible to determine whether an array meets this requirement without individual cell testing.

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### **4.6.4 VOLTAGE IMAGING**

Photon Dynamics has developed a unique form of testing in which TFT arrays can be electrically addressed, and the voltage patterns imaged visually[15]. This allows both point and line defects to be displayed.

Voltage or capacitance imaging is used, and a two dimensional map of an area under inspection is imaged on a monitor. The inspection equipment configuration, shown in Figure 4-10, includes an electro-optical transducer element which is placed over the TFT array to be sampled. The spacing between the element and sample is a few tens of microns.



Figure 4-10 Schematic diagram of voltage imaging of a TFT array

The transducer is an optically transparent piezoelectric material. The TFT array is electrically addressed by probes at the edges of the display, and the voltages present on the devices are spatially detected by the transducer with a spatial resolution of  $30\mu m$  and voltage resolution of 100mV. The transducer is modulated with circularly polarized light whose reflected properties are affected by the transducer's detection of TFT voltages.

An image of the substrate is obtained, and false color presentation shows both point and line defects. The transducer is stepped over the panel, and a complete scan can be made in a few minutes. Defective sites are registered in computer memory, and the information can be used to repair defective sites prior to completing the TFT array.

# **TFT Repair**



Strategies for achieving a high yield in TFT manufacturing include a redundant design, with two transistors per pixel. Repair of transistors is also part of the strategy, and a combination of laser cutting and redundancy is also sometimes

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used. High yield manufacturing will probably incorporate some kind of redundancy and repair scheme for the near term.

## **4.7.1 LASER CUTTING**

Laser repair can be made on a redundant TFT array[16]. The application described here is for a polysilicon shift register, which is located at the periphery of the display.

A serious problem for AMLCD circuits is defects in the peripheral drive circuits, because they often cause area defects in the displays, while defects in pixel arrays with TFT switches cause point or line defects. Therefore, it is essential to have repair capability on the peripheral drive circuits. Redundant TFT circuits are not sufficient for repairing open defects in the circuits. A laser connection and disconnection scheme was therefore implemented by NEC researchers.

Figure 4-11 shows the redundant shift register blocks, and the laser connection and disconnection methods. The faulty shift registor can be exchanged for a spare by disconnecting the input/output (I/O) lines of the faulty circuit, and connecting the I/O lines of the spare.

Laser repair is made using a pulsed YAG laser, operating at 1.06µm with a pulse duration of 8nsec. Figure 4-12 shows the laser connection and disconnection methods using doped polysilicon as the conduction layer. Several metal layers





**Figure 4-12** Laser connect and disconnect using polysilicon



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were evaluated for the laser connection method, but these cannot always be applied to the polysilicon TFTs. Laser connections are formed in this method between existing Al(3000Å) and n<sup>+</sup> polysilicon (2000Å) lines. Initially, the Al and poly are separated by silicon nitride. Ohmic contact is made through the SiN<sub>x</sub> layer by irradiating with the YAG laser at the overlap site. The illustration shows how the spare line is connected by irradiation. YAG laser pulses of 20-60 W/ $\mu$ m<sup>2</sup> power density are used in an air ambient, and the pattern is 4 $\mu$ mx4 $\mu$ m in size. When the laser irradiation was performed from the front side (Al side), a diode connection was obtained.

To avoid the problems which resulted from the irradiation of the aluminum side, the irradiation was performed through the glass, forming ohmic contacts between the polysilicon and aluminum. No diode behavior was observed, and current passed freely in either direction. The contact resistance was about  $100\Omega$ . Through-the-glass repair techniques can be used even on finished displays if the repair has to be made on a drive circuit. The low temperature of the laser connect/ disconnect process is fully compatible with displays where the liquid crystal material has already been introduced into the cell.

## 4.7.2 LASER-ASSISTED DEPOSITION

The Micrion laser repair system is used to repair both open and short line defects, and to implement redundancy schemes using laser cutting and laser induced deposition[17]. The L-1 system is automated, and compatible with several data transfer protocols from inspection systems. A localized vacuum system enables repairs on 400x400mm substrates without vacuum chamber redesign as substrate size increases. The reaction chamber for deposition maintains a 50 $\mu$ m gap above the substrate, and vacuum is maintained by differential pumping. Substrate position is controlled with an x-y-z stage which moves the defect location under the vacuum chamber.

Visible laser radiation is used for both deposition and cutting. A continuous argon ion laser (514nm) deposits metal and metal oxide lines, while a frequency doubled (530nm) YLF laser provides pulsed energy for material removal. Typical panels are repaired in a 5 minute period, which includes substrate loading, moving to defect locations, imaging the defects, and performing the operator-selected repair.

Laser induced deposition of cobalt lines is a patented process licensed by Micrion from MIT Lincoln Lab. Deposition from cobalt carbonyl gas is enhanced by a

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photolyic mechanism, and cobalt can be deposited without thermal damage to the substrate on a wide variety of underlying materials, including ITO on glass. Other than surface-absorbed oxygen and carbon, the cobalt is contamination free. Electrical resistivity of the cobalt lines is  $20-50 \ \mu\Omega$ -cm. The cobalt lines can be deposited at selectable rates of 5-25 $\mu$ m per second (linear rate). Line widths and line heights range from 5-20 $\mu$ m and 0.05-1 $\mu$ m respectively.

Other materials are being investigated for deposition in the system. These include metallic platinum and high resistance cobalt oxide. Platinum deposition of 15-20 $\mu\Omega$ -cm lines is achieved (bulk value is 10.6  $\mu\Omega$ -cm). Cobalt oxide can be used as a passivating oxide layer on repaired areas for protection prior to the orientation layer deposition. Resistivities of 10<sup>5</sup>  $\mu\Omega$ -cm have been measured.

Another approach to laser deposition has been adopted by Photon Dynamics, which is using palladium metal as the connector. A liquid solution of metal organic is applied by local spray or drop dispense, air dried, and annealed with an argon laser where metal conduction is required. The laser converts the compound to metal, and remaining compound is removed by IPA cleaning.



## Assembly

This section summarizes the equipment available for liquid crystal display assembly. Completed TFT and color filter panels are processed, joined, and filled with the magic liquid crystal material, polarizers are attached, and the completed display is formed by adding a backlight and display driver circuits.

Equipment for flat panel display assembly is often very unlike anything found in IC assembly. For some processes it is adapted from equipment designed for completely unrelated industries, such as food or drug processing. Examples include the equipment for attaching polarizers and other films, and printing equipment adapted for polyimide orientation film deposition.

## **4.8.1 POLYMER PRINTING**

The polyimide orientation film is applied to finished TFT and color filter panels. The film, which is just 300-1000Å thick, is applied primarily by flexographic printing. Polyimide printers are available from Nissha and Hitachi; the Hitachi unit is described below. Cleaning equipment for pre- and post-rubbing is manufactured by SPC.

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Figure 4-13 is an outline of Hitachi's thin film coating equipment based on flexo-printing method[18]. The illustration shows a material dispensed from a source tube onto an anilox roll, thickness of coating controlled by a doctor roll, then transferred to a printing plate. The plate can rotate onto the substrate, while the substrate is moved in under the printing cylinder. A comparison of this method to coating by spinner is shown in Table 4-12. Comparison figures include throughput which is higher by a factor of two or three for print coating, consumption of material, which is lower for print coating. In addition, the authors point out that spin coating is best suited only for round or disc shaped substrates. Square panels such as those for LCD manufacturing can have a buildup of coating in the center of the panel compared to the edges. Print coating machine is combined with an automatic loader, multiple chamber drying zone, and unloader to form a semi-automatic coating module.

Rubbing equipment is available from Kyoei Semiconductor. The model L-400 accepts up to 400x400mm substrates, and the following specifications for rubbing apply, Table 4-13.



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	Spin Coat	Print Coat
Throughput	1-2 sheets/min	5-6 sheets/min
Coating Solution	100%	20%
Consumption		
Substrate Shape	Disc (optimum) diameter	Disc, square, large
Film Thickness	3000Å-a few microns	300Å- a few microns

## Table 4-12 Spin Coating vs Print Coating

Post rubbing cleaning equipment serves to remove the charged particles of polyimide, which remain on the panel surface after rubbing. Ultrasonic cleaning with 850KHz, air knife, IR drying and spin drying are available from SPC.

 Table 4-13
 L-400 Rubbing Machine

Substrate Size	400x400mm
Roller Revolution	0-900 RPM
Substrate Stage	0-200mm/sec
Travel Speed	
Rubbing Pressure	Contact pressure adjusted by setting clearance
	between roller and substrate, increments of 0.01mm
Rubbing Direction	forward/backward/back and forth
Static Eliminator	prevents static electricity and dust buildup

## 4.8.2 ASSEMBLY/FINAL TEST

One step prior to assembly is spacer spraying. Spacers are uniformly-sized spheres or rods made of glass and plastic that maintain the cell spacing to the specified value,  $5-10\mu$ m thick. Equipment for deposition is made by Sekisui, the company that supplies the spacers. Spacer deposition is performed in a spraying operation in which static electricity assists the bonding of the spacers to the substrate. After deposition, spacers are maintained in position for sealing.

Screen printing of the seal epoxy is possible using screen printing equipment from New Long. Alternatively, an automated tube dispense may be preferable for large displays, to avoid the effects of physical contact from the screen surface.

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The assembly process and examples of assembly equipment have been discussed in a previous section of the report. Equipment for rubbing, assembly, sealing and curing is manufactured by Kyoei Semiconductor and Ketek. Glass scribers are available from Kawaguchiko Seimitsu, Joyo Engineering, and Villa Precision. The S451A from Kawaguchiko accepts 450x450mm substrates, and is controlled by preselected scribe instructions stored on the control computer's floppy disc.

Villa Precision offers scribers with alignment stages accepting 16" and 24" maximum substrate sizes. Up to 100 scribing programs can be stored in the microprocessor-based electronics control system. Video imaging allows verification of scribe location. Specifications for the 16" (400x400mm) model are shown in Table 4-14.

Substrate Size	400x400mm
Cell Thickness	0.29-3mm
Scribes/Substrate	99 lines
Scriber	Tungsten carbide or diamond cutter
Scribing Speed	0-508mm/sec
Resolution of Pitch Feed	25µm
Scribing Accuracy	±50µm
Scribing Speed Resolution of Pitch Feed Scribing Accuracy	0-508mm/sec 25μm ±50μm

 Table 4-14
 Villa Precision GS 110 16 L Scriber Specifications

Panels are scribed so that one side of the display (often the front side) is smaller than the other. This is to allow access for attaching the connectors to conducting lines on the inner side of the glass plate. For AMLCD displays, all the electrical connections are made to the rear or TFT glass plate. Scribed glass can be broken by applying pressure to one side of the scribe line, and the amount of pressure determines the rate of break propagation. The lines on one side of a panel can be broken before turning the panel over and breaking the other lines.

Post liquid crystal sealing cleaning is a batch process, performed in a walking beam tank sequence. Recent restrictions on fluorocarbons led SPC to the use of a petrochemical solvent, S-34, together with ultrasonic agitation. The sequence consists of ultrasonic with solvent, IPA rinse, and hot DI dry.

Retardation films are applied at the correct angle to the polarizer by the polarizer supplier, and are made to specification for each customer. For example, Sanritsu uses Suntec machines to apply retardation films. The operation is performed in

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a clean room. Polarizers are precut, then stacked and loaded onto the Suntec attachment machines where retardation films are added. A Thompson die cutter removes the final 1/16" of material. Polarizers are applied to the finished display using similar machines, which are adaptations of labelling equipment used in other industries.

Final testing includes verifying the performance of the completed display. This may be performed on a display alone, using probe testers from Tokyo Cathode or TEL, or may be done after the die attach process, which allows complete electrical operation. The procedure differs from manufacturer to manufacturer.

LCDs for military avionics require final test procedures that may differ from those for commercial applications[19]. Important parameters for military avionics displays include mechanical electrical, environmental, and optical test. Mechanical tests include dimensional measurements, cell flatness, dimensions and integrity of the contact fingers. Electrical measurements include row and column line impedances and the backplane crossover impedances. Environmental tests include altitude, operating temperature, temperature-humidity, and environmental storage stress tests. Altitude and temperature-humidity tests are spot tested on incoming cells. The environmental stress test is a 6 cycle -40°C-75°C test.

Optical tests measure pixel defect counts, cell brightness uniformity, grey-scale and contrast ratio measurements at different viewing angles, and color tests. Cell brightness at 9 points is measured by a photometer with a 1-cm spot size in ON, OFF, and grey-scale conditions. When brightness nonuniformities are observed, large-area, small-area or periodic measurements are performed, depending on the anomaly. The large area measurement is made by scanning the 1-cm photometer spot across the problem area to detect brightness variations caused by such things as liquid crystal contamination. The small area measurement is conducted with a 1-mm diameter photometer spot scanned across the defect to measure small spot brightness variations, perhaps due to a high spot from a particle. It can also detect brightness variations near the edge of the cell. The periodic measurement is similar to the small area one, and is used to test defects occurring at regular intervals, such as those caused by a stepper.

A pixel is labeled defective if the brightness deviates from the average brightness by 30% in both the ON and OFF conditions. The total number of defective pixels in both ON and OFF conditions are counted and measured against a standard.

LIQUID CRYSTAL FLAT PANEL DISPLAYS

Defective pixels next to each other are called clusters. A very small number of clusters are allowed on a panel.

Contrast ratio between the ON and OFF condition are measured at 90°, left-right 55°, and top 45°. The area colorimetries of the center of the cell are measured under conditions of ON, OFF, red, blue, and green. The cell typically has an AR coating on both the cell surface and the front polarizer surface. The specular reflectance of the panel is measured using MIL-C-14806A.

An optical bench is used, with the panel mounted on a stage with a specially designed RGB fluorescent backlight. The stage has two rotational axes with 90° relative motions. The photometer has two translational motions. Pixel defects are measured with a 512x512 CCD black and white camera, analyzing a 50x36 pixel area on the display. The full display measures 6.25"x6.25", with 1024x1024 pixels. Each LC pixel is covered by about 145 CCD pixels in the test, and only signals from the central CCD cells are used for average brightness calculations. Testing of the whole cell is accomplished by mounting the cell on an x-y movement table under the camera and stepping the cell in a serpentine route. At each step, the brightness data of each pixel and its location are calculated and stored in a computer. At the end of the test, maximum, minimum, and average brightness, pixel defect and cluster defect locations are calculated and printed out.

Major cause for cell rejection during the development phase of the program were pixel defect, pixel cluster defect, window frame effect, variations in the grey scale operation, and fill-hole contamination. Pixel defects could be either permanently ON or OFF. Typical causes of these defects were metal bridging or through-insulator shorts. Pixel cluster defects were typically due to metal bridging in the TFT array, color filter damage, or loss of liquid crystal surface alignment in either the TFT array or the color filter.

Measuring brightness in the OFF state was difficult. A slight variation in cell thickness ( $<0.1\mu$ m) could cause a large variation in OFF-state brightness, especially at high temperatures. The window frame effect resulted from a slight increase in cell thickness near the edges of the panel. Trapped particles in the cell with a diameter greater than the cell thickness cause high spots with resulting brightness variations in the OFF state. Localized contamination of the liquid crystal resulted in a localized variation in the cell brightness in the grey scale test. Optical bench equipment for performing tests of this sort is available from Otsuka Electronics and other suppliers.

LIQUID CRYSTAL FLAT PANEL DISPLAYS

## 4.8.3 DIE/PCB ATTACH

Integrated circuits are attached to the flexible circuits described in the previous section. ICs can be bare chips, TAB chips, or even surface-mount devices. The most common arrangement at present is TAB packaging, for which specialized lead attach equipment is employed.

TAB attach equipment is manufactured by Shinkawa and other firms. TAB refers to tape automated bonding, in which the integrated circuit chip is connected to a flexible tape, usually a composite of polyimide support material and copper as an electrical conductor, patterned according to the contacts required to the IC. Two distinct steps are employed, referred to as inner lead bonding and outer lead bonding. Inner lead bonding is the attachment of the IC chip to the tape, and outer lead bonding is the attachment of the IC chip to the tape, and outer lead bonding is the attachment of the PC board or flexible circuit.

In order to apply TAB attach methods, the integrated circuit die must be prepared for attachment by creating raised metal "bumps" where contact to the chip is required. The bumps can be either gold or tin solder. Two types of connecting methods are used for inner lead bonding, attaching the bumped chip to the tape. The first involves melting and reflow of the solder, where solder bumps are employed. A matching area of solder has to be present on the leads of the tape. The upside down (flip chip) is aligned to the substrate, and all joints made simultaneously by solder reflow. Another alternative is pressure contacts. In this case, gold bumps on the chip are glued to the substrate. The shrinkage of the glue causes a compression force on the gold bump and substrate metal pattern.

In some cases, the gang bonding approach for inner lead bonding is giving way to single point bonding, in which the leads are connected rapidly one at a time. For a complex chip with several hundred pins, gang bonding of all the contacts at one time is too difficult, since it is hard to apply pressure evenly around the chip. Single point bonders can attach the leads rapidly, although they require more time than the few seconds for gang bonding. Outer lead bonding is somewhat easier to perform than inner lead attach, since lead pitch is greater, and bonding materials are copper on both sides.

In addition to Shinkawa, TAB bonding equipment is available from Kaigyo Denki, Anarad, and NEC. Single point bonders for TAB are made by Orthodyne and K&S.

LIQUID CRYSTAL FLAT PANEL DISPLAYS

#### REFERENCES

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**2.** J. Hazama, "Large-Plate Exposure System", Technical Proceedings, Semicon Kansai 1990, SEMI Japan, 1990, p412.

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**4.** T. Sameshima et al., "XeCl Excimer Laser-Induced Amorphization and Crystallization of Silicon Films", Extended Abstracts, Solid State Devices and Materials, Sendai, 1990, p967

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**6.** H. Takagi, "Thin Film Deposition System for TFT/LCD Fabrication", Technical Proceedings, Semicon Kansai 1991, SEMI Japan, 1991, p64

7. G. Liu and S. J. Fonash, "Low Thermal Budget Poly-Si Thin Film Transistors on Glass", Extended Abstracts, Solid State Devices and Materials, Sendai, 1990, p963

8. Derek Aitken, "The Phased Linear Scanner", Society for Information Display Technical Digest 1991, p850

9. K. Masumo et al., "Low Temperature Polysilicon TFTs by Non-Mass-Separated Ion Flux Doping Technique", Extended Abstracts, Solid State Devices and Materials Sendai, 1990, p975

**10.** G. Kawachi et al., "Large Area Doping Process for Fabrication of p-Si TFTs Using Bucket Ion Source and XeCl Excimer Laser Annealing", Extended Abstracts, Solid State Devices and Materials, Sendai, 1990, p971

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**12.** L. H. Lin and A. M. Carroll, "High Speed Inspection of LCD Panels", Technical Proceedings, Semicon Kansai 1991, SEMI Japan 1991, p78

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14. R. L. Wisnieff et al., "In-Process Testing of Thin Film Transistor Arrays", Society for Information Display Technical Proceedings 1990, p 190

**15.** F. J. Henley and G. Addiego, "In-Line Functional Inspection and Repair Methodology During LCD Panel Fabrication", Society for Information Display Technical Digest 1991, p686

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19. F. C. Luo, G. A. Melnik, and M. F. Strong, "Testing and Qualifications of a a-Si TFT-LC Color Cells

## **CHAPTER FIVE: SUPPLIER PROFILES**

LIQUID CRYSTAL FLAT PANEL DISPLAYS

# **Materials Suppliers**

This section contains a list of suppliers of materials to the flat panel industry. Suppliers are listed alphabetically with indication of product category. Section 6.4 provides a listing of supplier address and phone numbers for reference.

Suppliers' products are organized into the following categories

1. Liquid Crystals

4. Photoresist 5. Gases/Chemicals

2. Glass Substrates 3. ITO

- 6. Color Filters
- 7. Photomasks 10. Tab, IC 8. Polarizers

11. Other

9. Backlight

Materials Suppliers	1	2	3	4	5	6	7	8	9	10	11	Remarks
Arisawa		Ì						*				
Asahi Glass		*	*									
BKL						1			*			
Bokusui											*	Carrier,Coater
Brewer Science		1				*		1				Color filter materials
Casio	_									*		
Central Glass		*	*		*							
Chatany Sanyo									*			
Chisso	*											Color filter & orienta-
												tion film materials
Clean Surface			*				*					
Technology												
Cookson		*										ITO targets
Copal									*			
Corning Japan		*										
Courtaulds		*										Coated substrates
Dainippon Printing						*	*			_		
Daisei						_	_				*	Seal materials
Dana Enterprises				_	*			*		_	*	Spacers
Denshitron											*	Interface board
Densitron		_				<u> </u>			*			
Display Engineering							_		*			
Displays Inc.			1								*	Sealants

### **CHAPTER FIVE: SUPPLIER PROFILES**

LIQUID CRYSTAL FLAT PANEL DISPLAYS

Materials	1	2	3	4	5	6	7	8	9	10	11	Remarks
Suppliers												
Enplas						1			*			· · · · · · · · · · · · · · · · · · ·
Elix									*		<u> </u>	
Endicott Research				1					*			
Erebamu									*			
Flat Candle			1						*			
Flex Products		*										Coated films
Foster-Grant								*				
Fuji Rubber											*	Connector
Fuji-Hunt				*		*						
Fujitsu Kasei									*			
Hamlin LCD									*			
Harrison									*			
Hitachi Chemical				*	*					*	*	Printing & conductor
												matls, topcoat
Hoechst Japan	*			*								
Hoffman LaRoche	*											
Ноуа		*	*			*	*					
Irie		*				1						
JSR				*	*						*	Orient. film,
												passivation
Kayapola					*							
Kokusai Denki	*											
Komatsu Elec. Metals					*							
Коуо		*										
LCD Lighting									*			
Lamplighter Indus.									*			
Libbey Owens Ford		*	*									
MRC					*							Sputtering Targets
Matsusaki Shinku		*	*									
Merck Japan	*					1	1					
Metak Systems	1								*			
Micro Technology						*				*	1	
Mikase									*			
Mitsubishi Rayon									*			
Mitsui Mining			*									ITO Targets

1. Liquid Crystals 2. Glass Substrates 3. ITO 4. Photoresists 5. Gases/Chemicals 6. Color Filters 7. Photomasks 8. Polarizers 9. Backlight 10. Tab,IC 11. Other

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## **CHAPTER FIVE: SUPPLIER PROFILES**

LIQUID CRYSTAL FLAT PANEL DISPLAYS

Materials Suppliers	1	2	3	4	5	6	7	8	9	10	11	Remarks
Mitsui Toatsu					*						*	Seal Materials
Modutec									*			·····
Moroboshi Ink						*						
Nagase					*							······································
Nagase Sanyo											*	Seal Materials
Nihon Denyo									*			
Nihon Shokubai											*	Spacer Materials
Nippon Electric Glass		*										
Nippon Ita Glass		*	*			*						
Nippon Kanko Shikiso								ļ			*	2 color system
Nippon Philips										*		
Nippon Polaroid								*				
Nippon Sekiyu Kagaku				Ι							*	assembly boards
Nippon Kayaku											*	Seal materials
Nippon Mining			*									
Nissan Kagaku					*							Orientation Film
Nitto Denko		*										
Okaya									*			
Oki										*	_	
Ono									*			
Plikington		*										
Polytronix					*	_		ļ	<u> </u>	ļ	*	Sealants
Rayonics									*			
Rodik	*											
Rolm										*		
Sanritz								*				
Sansei Diamond										ļ	*	Scribe tools
Sanyo Shinku		*	*									
Shashin Kagaku							*					
Schott		*										
Sekisui Fine					1						*	Spacers, color
Chemicals												filter material
Shashin Kagaku							*					
ShinEtsu Polymer					ľ						*	Interconnect
												products

Liquid Crystals 2. Glass Substrates 3. ITO 4. Photoresists 5. Gases/Chemicals
 Color Filters 7. Photomasks 8. Polarizers 9. Backlight 10. Tab,IC 11. Other
LIQUID CRYSTAL FLAT PANEL DISPLAYS

Materials Suppliers	1	2	3	4	5	6	7	8	9	10	11	Remarks
Suppliers						ļ	ļ					
Shindo Denshi Kogyo	ļ		 					<u> </u>		*		TAB tape
Shinto Chemitron						*				ļ		
Shipley				*			ļ	ļ				
Shokubai Kasei						ļ		ļ		<u> </u>	*	Spacer Materials
Sonocom							*					
Sony Chemical										*		Anisotropic
												conductor
Stanley Denki									*			
Sumitomo 3M										*		
Sumitomo Bakelite										*	*	Transp. film,
												orient. film
Sumitomo Chemical				*	*			*			*	Assembly film
Tamara											*	Backlight inverter
Tanaka											*	Conducting pastes
Teijin			*								*	Plastic LCD
												conduc. film
Teisan					*							
Texas Instruments										*		
3M/Optical Sys.									*			
Tokuyama Soda											*	Silica spacers
Tokyo Cosmos									*			· · · · · · · · · · · · · · · · · · ·
Tokyo Kagaku					*							
Tokyo Ohka				*							*	Color filter overcoat
Tomoegawa										*		TAB material
Toppan Printing						*	*					
Toray						*				*		
Toshbia Lightec									*	*		
Toshiba									·	*		
Toshiba Ceramic							*					
Tosoh	<u>├</u>				*							Sputtering Targets
Toyo Shigyo						*						-puttering rungeto
Ushio									*			
VMC					*							Sputtering Targets
Viratec		*										Coated substrates
West Denki		*							*			

Liquid Crystals 2. Glass Substrates 3. ITO 4. Photoresists 5. Gases/Chemicals
 Color Filters 7. Photomasks 8. Polarizers 9. Backlight 10. Tab,IC 11. Other

LIQUID CRYSTAL FLAT PANEL DISPLAYS

# **Materials Supplier Listing**

# 5.2

Materials Supplier Alphabetical Listing Address, phone, fax, and product type are provided. Phone number is shown first, then fax number.

### ASAHI GLASS CO. LTD.

Chiyoda Bldg. 2-1-2 Marunouchi Chiyoda-ku, Tokyo 100 Japan 03-3218-5774 03-3213-5486 Glass substrates

### BOKUSUI CORP.

1-2-2 Uchisaiwaicho, Chiyoda-ku Tokyo 100 Japan 03-3506-7604 03-3506-7623 Manufacturers Rep.

**BREWER SCIENCE INC.** PO Box GG

Rolla, MO 65401 314-364-0300 314-364-7150 Color filter materials

CASIO KEISANKI

2951-5 Ishikawa-cho Hachioji-shi Tokyo 192 Japan 0426-44-6113 0426-42-0118 Driver IC

CENTRAL GLASS CO. LTD. Kowa-Hitotsubashi Bldg 3-7-1 Kanda-Nishikicho Chiyoda-ku, Tokyo 101 Japan 03-3259-7326 03-3293-2145 Glass substrates

# CHISSO CORPORATION

Tokyo Blg. 7-3, Marunouchi 2-chome Chiyoda-ku, Tokyo 100 Japan 03-3284-8580 03-3215-3692 Liquid crystal materials CLEAN SURFACE TECHNOLOGY 378 Ohmagari Samukawa-machi Koza-Gun, Kanagawa-ken 253-01 Japan 81-467-741935 81-467-751131

COOKSON PLASMATERIALS 3223 Crow Canyon Road Suite 290 San Ramon, CA 94583 510-277-0440 510-277-0469 ITO sputtering targets

CORNING JAPAN No. 35 Kowa Bldg 14-14 1-chome Akasaka Minato-ku Tokyo 107 Japan 03-3586-1053 03-3582-5150 Glass substrates

COURTAULDS PERF. FILMS 21034 Osborne Street Canoga Park, CA 91304 818-882-5744 818-882-6519 ITO coating service

DANA ENTERPRISES 1440 S. Saratoga-Sunnyvale Rd San Jose CA 95129 408-257-6686 408-973-9620 Manfacturers Rep.

DENSITRON CORP. 2540 W. 237 St.

Torrance, CA 90505 213-530-3530 213-534-8419 Backlight

### **DAINIPPON PRINTING**

1-1 1-chome Ichigaya Kagacho Shinjuku-ku Tokyo 162-01 Japan 03-3266-7211 03-3266-2678 Color filters, photomasks

**DISPLAY ENGINEERING** 

480 Tesconi Circle Santa Rosa, CA 95401 707-571-8700 707-571-8787 Backlight

ENDICOTT RESEARCH GROUP PO Box 269 2601 Wayne Street Endicott, NY 13760 607-754-9187 607-754-9255 Backlight

ENPLAS CORP. 2-30-1 Namiki, Kawaguchi Saitama 332 Japan 0482-53-3131 0482-57-0191 Backlight

F. HOFFMANN-LA ROCHE LTD. Bldg 49/325 Postfach CH-4002 Basel, Switzerland 41-61-688-6468 41-61-691-3856 Liquid crystal material

FLAT CANDLE COMPANY PO Box 49174 Colorado Springs, CO 80949 719-260-8088 719-260-8089 Backlight

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## LIQUID CRYSTAL FLAT PANEL DISPLAYS

### FLEX PRODUCTS INC.

2793 Northpoint Parkway Santa Rosa, CA 95407-7350 707-525-9200 707-525-7725 Coated flexible substrates

FUJI-HUNT ELECTRONICS 38th Kowa-Bldg 4-12-24 Nishiazabu Minato-ku, Tokyo 106 Japan 03-3406-6911 03-3498-0567 Photoresist, color filter material

# HAMLIN LCD

W7514 CTHV Lake Mills, WI 53551 414-648-1000 414-648-1001 LCDs, LCD backlight assemblies

HITACHI CHEMICAL CO. LTD. Shinjuku Mitsui Bldg, 2-1-1 Nishi-shinjuku, Shinjuku-ku Tokyo 163 Japan 03-3346-3111 03-3346-3475 Anisotropic conductor, orientation

# HOECHST JAPAN LTD. 8-10-6 Akasaka, Minato-ku Tokyo 107 Japan 03-3479-5120 03-3479-4770

HOYA CORP. 2-7-5 Naka-ochiai, Shinjuku-ku Tokyo 161 Japan 03-3952-1151 03-3952-7854

Photomask blanks, color filters

Ferroelectric liquid crystal material

IRIE KOKEN CO. LTD. 4-11-7 Ginza Chuo-ku Tokyo 104 Japan 03-3542-4692 03-5565-7064 Vaccuum components for coating

JAPAN SYNTHETIC RUBBER CO 2-11-24, Tsukiji, Chuo-ku Tokyo 104 Japan 81-3-5565-6600 81-3-5565-6641 Orientation film, photoresist

# KOKUSAI DENKI Dai 100 Seimei Osaka Bldg 4-8 2-chome Minamisenba Chuo-ku 542 Japan 06-271-6771 06-264-7084 Glass substrate

KOMATSU ELECTRONIC METALS 2612 Shinomiya, Hiratsuka, Kanagawa 254 Japan 0463-23-1301 0463-24-0071 Process chemicals

KOYO LINDBERG LTD. 229 Kabata-cho, Tenri Nara Prefecture 632 Japan 81-7436-40981 81-7436-40989

LCD LIGHTING INC. PO Box 3070 11 Cascade Blvd. Milford, CT 06460-0870 203-876-1520 203-877-7212 Backlight

LAMPLIGHTER INDUSTRIES 96 Lamplighter Street Oak Hill, WV 25901 304-469-2474 304-469-3380 Backlight

### LIBBEY OWENS FORD

(Pilkington subsidiary) 811 Madison Avenue PO Box 799 Toledo, OH 43695-0799 419-247-3931 Glass substrates

### MRC

Route 303 Orangeburg, NY 10962 914-359-4200 914-425-6075 Sputtering targets and equipment

### MATSUSAKI SHINKU

45-6 1-chome Ohi Shinagawa-ku Tokyo 140 Japan 03-3774-6006 03-3771-6005 ITO coated glass

MERCK JAPAN LIMITED

No. 11 Mori Building 6-4, Toranomon 2-chome Tokyo 105 Japan 03-3591-7884 03-3508-77408 Liquid crystal materials

MICRO TECHNOLOGY 1-33-14 Tomigaya Shibuya-ku Tokyo 151 Japan 03-3469-1133 03-3469-1557 Color filters, glass TAB

MITSUBISHI KASEI CORP. Mitsubishi Bldg. 2-5-2 Marunouchi Chiyoda-ku Tokyo 100 Japan 03-3283-6451 03-3283-6461

MITSUI MINING CO. LTD. Mitsui Main Bldg 2-1-1 Nihonbashi Muromachi, Chuo-ku Tokyo 103 Japan 03-3241-1339 03-3241-1365 ITO sputtering targets

MITSUI TOATSU CHEMICALS 8F Kasumigaseki Bldg 3-2-5

Kasumigaseki Ditg 5-2-5 Kasumigaseki, Chiyoda-ku Tokyo 100 Japan 03-3592-4715 03-3592-4255 Seal materials

MODUTEC, INC.

920 Candia Road Manchester, NH 03103 603-669-5121 603-622-2690 Backlight

# LIQUID CRYSTAL FLAT PANEL DISPLAYS

NAGASE & CO. 5-1 Nihonbashi Kobunecho Chuo-ku Tokyo 103 Japan 03-3665-3306 03-3665-3980 Process chemicals

### NIHON ITA GLASS

8-1 5-chome Nishi Hashimoto Sagamihara 229 Japan 0427-74-0920 0427-73-4851 Glass substrates

### NIPPON ELECTRIC GLASS

10F Sumitomo Seimei Kita Bldg.1-14 4-chome MiyaharaYodogawa-ku 532 Japan06-399-271106-399-2731Glass substrates

### NIPPON MINING

2-10-1 Toranamon Minato-ku Tokyo 105 Japan 03-3505-8762 03-3505-8691 ITO sputtering targets

### NIPPON POLAROID

No. 30 Mori Bldg. 3-2-2 Toranomon Minato-ku Tokyo 105 Japan 03-3438-8811 03-3433-3537 Polarizing films

### NITTO DENKO CORP.

3F Mori Bldg 31, 5-7-2 Kojimachi Chiyoda-ku Tokyo 102 Japan 03-3264-2101 03-3222-4459 Polarizing and retardation films

# PHILIPS JAPAN LTD.

Philips Bldg. 2-13-37 Kohnan Minato-ku Tokyo 108 Japan 03-3740-5172 03-3740-5190 Driver IC

# PILKINGTON MICRONICS LTD. 811 Madison Avenue PO Box 799 Toledo, OH 43695-0799 419-247-4787 419-247-4912 Glass substrate

SANRITZ 1-30-13, Narimasu Itabashi-ku Tokyo 175 Japan 03-3930-1101 03-3930-1167 Polarizing and retardation films

# SCHOTT AMERICA 3 Odell Plaza Yonkers, NY 10701 914-968-8900 914-968-4422 Glass substrate

SEKISUI FINE CHEMICALS Dojima Kanden Blg. 2-4-4 Nishitemma Kita-ku, Osaka 530 Japan Plastic spacers, color filter mater

# SHASHIN KAGAKU 436D5 Tatetomita-cho 1-jo Noboru Horikawa-dori Kamikyo-ku Kyoto 602 Japan 075-432-1152 075-414-1539 Photomasks

SHINETSU POLYMER Togin Bldg. 1-4-2 Marunouchi Chiyoda-ku Tokyo 100 Japan 03-3212-4141 03-3212-4144 Interconnect

# SHINDO DESHI KOGYO 1027 Washinoya, Shonan-machi, Higashi Katsushika-gun, Chiba 270-14 Japan 0425-60-1231 0425-60-7322 TAB tape

# SHIPLEY COMPANY 2300 Washington Street Newton, MA 02162-1440 617-969-5500 617-969-1735 Photoresists

STANLEY ELECTRIC CO. LTD. 1-3-1 Eda Nishi, Midori-ku Yokohama 225 Japan 81-45-911-1111 81-45-911-0089 Backlight

# **TEISAN K.K.** 1-9-1 Shinonome, Koto-ku Tokyo 135 Japan 03-3536-2313 03-3536-2341 Process gases

**TEXAS INSTRUMENTS** PO Box 655303 MS 8209 Dallas, TX 75265 214-997-3050 Driver ICs

# **3M OPTICAL SYSTEMS** 3M Center 225-4N-14 St. Paul, MN 55144 800-328-7098 612-736-3305 Films for backlighting LCDs

# TOKUYAMA SODA CO. LTD.

1-4-5 Nishi-shinbashi Minato-ku Tokyo 105 Japan 03-3597-5120 03-3597-5168 Silica spacers

### Токуо Онка

Shinosaka Marusho Bldg 3-24-chome Nishinakajima Yodogawa-ku Osaka 532 Japan 06-303-8772 Photoresists, overcoat

# LIQUID CRYSTAL FLAT PANEL DISPLAYS

TOMOEGAWA PA	PER CO. LTD.
5-15 Kyobashi 1-c	home
Chuo-ku	
Tokyo 104 Japan	
81-3-3272-4117	81-3-3274-4739
Adhesive tape for	TAB

### **TOPPAN PRINTING**

1101-20 Myohoji-cho, Yokkaichi-shi TOSOH CORP. Shiga 527 Japan 0748-24-3501 0748-24-3555 Color filters, photomasks

# **TORAY INDUSTRIES**

1-8-1 Mihama, Urayasu Chiba 279 Japan 0473-50-6041 0473-50-6070 Color filter materials, orientation

### TOSHIBA CERAMICS Shinjuku-Nomura Bldg 26-2 14-6 5-chome Utsukushigaoka 1-chome Nishi-shinjuku Shinjuku-ku Tokyo 163 Japan 03-3348-7411 03-3345-8648 Photomask blanks

1-7-7 Akasaka Minato-ku Tokyo 107 Japan 81-3-585-3311 81-3-582-7846 Sputtering targets

Τογο Shigyo Nakayoki Matsushige-cho Itano-gun Tokushima 771-02 Japan 0886-99-7511 0886-99-6565 Color filter

USHIO ELECTRIC

Midori-ku Yokohama 225 Japan 045-901-2572 045-901-0883 Backlight

### VIRATEC THIN FILMS

2150 Airport Drive Faribault, MN 55021 507-334-0051 507-334-0059 Coated substrates



# **Equipment Suppliers**

This section contains a list of suppliers of equipment to the flat panel display industry. The following two sections present suppliers organized to indicate what kind of equipment they supply. In the first section, suppliers of manufacturing equipment are segmented into ten product categories. In the second section, the suppliers of test, inspection and repair equipment are segemented into ten other categories appropriate to that classification. The final section is a listing of company addresses and phone numbers for reference.

# 5.3.1 MANUFACTURING EQUIPMENT SUPPLIERS

Suppliers' products are organized into the following categories:

4. Etch

- 1. Lithography
- 2. CVD
- 3. Sputter

5. Clean 6. Photoprocessing 7. Asher 8. Ion Implant 9. Assembly 10.Other

LIQUID CRYSTAL FLAT PANEL DISPLAYS

Equipment Suppliers	1	2	3	4	5	6	7	8	9	10	Remarks
ASM Japan		· *									
Abel				*	*	*					
Advanced Energy										*	power supply
Japan											
Anelva		*	*	*							
Applied Materials		*		*							CVD/etch in 1992
Billco					*						
Bokusui					*				*		alignment film printer, rubbing equip., seal & encapsulation dispenser, spacer disseminator, tester, alinger, LC injection, press, scriber, end seal, polarizer
											attach equip.
Chuo Riken				*	*	*				*	baking oven
Daiko Dainingan Gaman					*	*					
Dainippon Screen				<b>*</b>		Ļ					
Daimissnoji Daimissnoji											carrier
Daiwa Shinku		*		<u> </u>		<u> </u>			*		LC injection equipment
Denko Systems		<u>^</u>							*		
EHC Eagle Kegne											hallows another staher
Lagie Kugyu	<u> </u>										alastrada abawar baada
Elattroroug		*									electrode shower heads
Eleutorava				*		<u> </u>			<u> </u>		
Fujioka Seisakusho									*	•	rubbing equip., screen printer, spacer disseminator substrate aligner, seal drying, US cleaning equip.
General Signal Japan	*							1			
Hakuto	*	1				*					
Hamatech					*	*					
Harada Sangyo Kaisha										*	antistatic equipment
Hirayama										*	Autoclave
Hitachi Chemical					*	*			*		anisotropic conductive film
											thermocompression equipment
Honda Denshi					*						
Hugle Electronics					*					*	non-contact US substrate cleaner

LIQUID CRYSTAL FLAT PANEL DISPLAYS

Equipment Suppliers	1	2	3	4	5	6	7	8	9	10	Remarks
Ihara High Pressure	Γ						Ι			*	couplings for pipes
Fittings			ļ				ļ	ļ			and valves
Iriye Corp.		<u> </u>		*	*						
JBA	*										
JEOL	*	*	*								
Joyo Engineering Lab									*		rubbing, alignment, seal printing, glass scriber, spacer disseminator
Kashiyama Ind.										*	vacuum exhaust equip.
Kawaguchiko Seimitsu									*		
Ketek									*		
Kokusai Electric		*		*							
Koyo Lindberg		*								*	prebake drying equip. for
						•				<u> </u>	alignment film
Kusumoto Chemicals										*	vacuum oven for drying
											and foam expelling, heat/
		ļ								ļ	pressure/hardening oven
Kuwata Technical					*					*	ultra pure water mfg.equip.,
Service										ļ	waste water treatment equip.
Kyoei Semiconductor	*			*	*	*	<u> </u>	ļ	*		rubbing equipment
Lapmaster SFT Corp.			ļ	ļ	*		ļ				
Leonix		*	*	ļ			ļ				
Liquid Concerned										*	electrostatic filter for cleaning
											fluids, vacuum pump lubricant,
······································		<u> </u>	ļ					ļ	ļ		processing fluids, cooling water
M Setek					*	*					
MBK Microtech		*			•*			ļ			excimer laser
MKS Japan										*	vacuum measuremnt, mass flow
											controller, pressure/flow
······		ļ			ļ			ļ		L	volume controller
MV Systems		*					 				cluster PECVD
Mabuchi	1					*					
Marubeni Hitech		*									
Corp.											
Mecs										*	substrate transport robot

Lithography 2. CVD 3. Sputter 4. Etch 5. Clean
 Photoprocessing 7. Asher 8. Ion Implant 9. Assembly 10. Other

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LIQUID CRYSTAL FLAT PANEL DISPLAYS

Equipment Suppliers	1	2	3	4	5	6	7	8	9	10	Remarks
Mikasa	*					*					
Mistuboshi Diamond										*	substrate analyzer,
Ind.											substrate polisher
Mitsui Toatsu										*	waste silane
	<b></b>										decomposition equip.
Mitsui Trading										*	annealing equip.
Motoyama					*				*		insertion equip., adhesion
											assembly equip., hardening
											furnace
Musashi Engineering					*						
Nagase & Co.					*	*	*				
New Long	1								*		
Newlong Seimitsu						1			*		automated screen printing
Кодуо											forLCD sealing, rubbing
Nextral		*		*							batch PECVD/Etch
Nikon	*				*					*	reticle stocker, pellicle
											attach equip.
Nippon Pillar										*	fluorine resin coupler, pump,
Paacking											valve, heat converter
Nippon Plate Glass										*	SiO2 coating equip.
Nippon S. T. Johnson										*	high precision screen printer
Sales Co.											
Nippon Seiko	*										
Nippon Tylan										*	mass flow controller, baking
	ļ						<u> </u>				system
Nissha	ļ								*		•
Nissin Electric	·		ļ		1			*		*	ion doping, ion shower equip.
Nomura Micro Science					ļ				<u> </u>	*	ultra pure water mfg. equip.
Ogino Seiki									*		
Okura Electronics				*	*	*					
Optical Radiation	*										
Orion Machinery										*	water cooler, air conditioner
Osaka Shinku Kikai			*								
Plasma System				*							
Plasma-Therm				*							

1. Lithography 2. CVD 3. Sputter 4. Etch 5. Clean

6. Photoprocessing 7. Asher 8. Ion Implant 9. Assembly 10. Other

LIQUID CRYSTAL FLAT PANEL DISPLAYS

Equipment Suppliers	1	2	3	4	5	6	7	8	9	10	Remarks
Protek					*						
RKC Instrument										*	temperature control unit
Rix Corp.					*						
Rorze Corp.										*	clean robot for vacuum,
											LCD conveyor system
Rubmaster SFT									*		
Samco International		*		*							
Sanyo Vacuum Indus.			*								
Semicon Created					*						
Semiconductor Energy		*									
Research											
Shimada Riken Kogyo				*	*	*					
Shimadzu		*	*								
Shin-Etsu Engineering										*	automated plate assembly equip.
Shinko					*					*	antistatic equip.
Shinko Pantec										*	ultra pure water mfg. equip.
Sigma										*	anode oxidation equip.,
											substrate drying equip.
Sonic Fellow					*						,
Sonocom									*		dry spacer dissemination equip.
Sumitomo Eaton Nova								*			
Sun-Tec									*		
Tabai Espec									*		fully automated clean
											curing system
Taiyo Serv. Ctr.										*	heat conversion, cooling
(Taitec)											water, circulation equip.
Tazmo					*	*					
Tegal				*							
Tokuda			*	*							
Tokuyama Soda					*						
Tokyo Cosmos		*									a a construction of the second s
Electric											
Tokyo Electron				*							
Tokyo Ohka Kogyo				*		*	*				
Topcon	*										

1. Lithography 2. CVD 3. Sputter 4. Etch 5. Clean

6. Photoprocessing 7. Asher 8. Ion Implant 9. Assembly 10. Other

LIQUID CRYSTAL FLAT PANEL DISPLAYS

Equipment Suppliers	1	2	3	4	5	6	7	8	9	10	Remarks
Toray							*				
Toshiba Lightec	*								*	*	optical cleaning equip., UV
											adhesive and hardening equip.
Toto										*	air slide, precision x-y table
Toyoko Kagaku		*		*	*					*	rinser dryer, pipe components
Ulvac Cryogenics		*	*	*				*			cryopump
Ulvac Japan		*	*	*			*	*			
Ulvac Service										*	pure waterstatic electricity
											control, pure water mfg. equip.
Unit Instr. Japan										*	mass flow controller
Villa Precision									*		
Watkins Johnson		*									· · · · · · · · · · · · · · · · · · ·
Yamada Corp.										*	teflon pump
Yutaka Engineering										*	gas control equip., pressure
											ensor, pressure reduction valve

# Test, Inspection & Repair Equipment Suppliers

Suppliers' products are categorized by the following classifications:

- 1. Electrical Test
- 2. Optical Test
- 3. Electrical Prober
- 4. Mask Inspection
- 5. Substrate Inspection
- 6. Microscope
- 7. Mask Repair
- 8. Substrate Repair
- 9. Burn-in
- 10. Other

Firm	1	2	3	4	5	6	7	8	9	10	Remarks
Advantest	*										
Astrodesign			*							*	signal genrator
Chuo Riken									*		
Chuo Seiki										*	alignment equipment
Dainippon Screen										*	film thickness measurement
Elionix						*					
GenRad	*										
Hakuto			*	*	*		*	*			

LIQUID CRYSTAL FLAT PANEL DISPLAYS

Firm	1	2	3	4	5	6	7	8	9	10	Remarks
Innotech			*							*	LCD probe card
Insystems/JSR					*						
Irie					*						
Japan Hitech										*	microscope heating &
cooling											
JEOL				*	*	*					
KLA/Acrotec					*						
Kusumoto Chemicals									*	*	temp/humidity test
Kyoei Semiconductor		*	*								
Lapmaster SFT				*	*						
Lasertec				*		*					
Lehighton Electron.										*	film resistivity
Leonix				*			*				
MBK Microtech	*	*			*			*			begin sales 1991
Mikasa					*	*					
Minato	*	*	*								
Electronics											
Micrion								*			
Mitsui Trading	*										
Motoyama	*	*				*			*		
Nagase Sanyo					*						
Nakamura Precision	*		*							*	sheet resistance
Nanometrics Japan										*	film thickness, line width
Napson					*						
NEC							*	*			laser repair
Nidek					*	*		*			
Nihon Micronics			*		*						
Nikon				*	*	*					
Nippon Seiko				*	*						
Nippon Shashin									*		
Insatsu											
Okatani Electric	*										
Olympus			1			*					
Ono Technology Lab.										*	inspection light source
Orion Machinery										*	environmental testing
Otsuka Electronics		*				1					final optical inspec.

1. Electrical Test 2. Optical Test 3. Electrical Prober 4. Mask Inspection 5. Substrate Inspection 6. Microscope 7. Mask Repair 8. Substrate Repair 9. Burn-In 10. Other

LIQUID CRYSTAL FLAT PANEL DISPLAYS

Firm	1	2	3	4	5	6	7	8	9	10	Remarks
Oyama			*								
Photon Dynamics					*			*			
Rika Kogyo										*	temperature control
Rix					*					*	x-ray inspection
Sankei						*					
Soei Tsushi										*	Autronic LC eval. equip.
Sonic Fellow										*	cleaning
Sononcom										*	spacer particle analyzer
Tabai Espec									*		
Tencor Japan										*	film thickness, particle
											and defect
Tokyo Cathode Lab	*		*		*			*		*	inspection
Tokyo Denshoku			*					*			
Tokyo Semitsu					*					*	film thickness
Ulvac PHI				*	*					*	panel surface inspection
Ulvac		*			*					*	surface roughness
XMR								*			
Yasunaga					*						
Yokogawa HP	*				*						test systems

# **Equipment Supplier Listing**



Equipment Supplier Alphabetical Listing Address, phone, fax, and product type are provided. Phone number is shown first, then fax number.

# ASM JAPAN KK

6-23-1 Nagayama, Tama Tokyo 206 Japan 81-423-37-6312 81-423-37-6320 81-3342-7500 Low pressure CVD reactors

**ADVANCED ENERGY JAPAN KK** 1F, Daishinkyo Bldg. 1-5-8 Fujimi 5-8-1 Yotsuya, Fuchu Chiyoda-ku Tokyo 102 Japan 81-3222-1311 81-3222-1315 Power supplies

# ADVANTEST Shinjuku NS Blg 4-1 Nishi-shijuku, 2-chome Shinjuku-ku, Tokyo 163 Japan

81-3342-7510 Electrical test systems

ANVELA CORP.

Tokyo 183 Japan 81-423-34-0220 81-423-60-2277 412-452-7390 PECVD, PVD equipment

# **APPLIED MATERIALS JAPAN** 2-7-1 Nishi-shinjuku Shinjuku-ku

Tokyo 163 Japan 81-3348-3881 81-3348-3442 CVD, etch equip in 1992

BILLCO Grandview Blvd. Zelienople, PA 16063 USA 412-452-0217

# LIQUID CRYSTAL FLAT PANEL DISPLAYS

# BOKUSUI CORP.

1-2-2 Uchisaiwaicho Chiyoda-ku Tokyo 100 Japan 81-3506-7604 81-3506-7623 Assembly equipment

### CHUO RIKEN CO. LTD.

8-5-1 Higashisuna, Koto-ku Tokyo 136 Japan 81-3646-3511 81-3646-3573 Photo process equipment

# DAINIPPON SCREEN MFG. CO.

4 Teranouchi Agaru Horikawadori, Kamikyo-ku Kyoto 602 Japan 81-75-414-7128 Photolith., photoprocess, cleaning

### DENKO SYSTEMS INC.

6-1 Sakae-cho, Tachikawa Tokyo 190 Japan 81-425-37-3552 81-425-37-1399 LPCVD

### ELIONIX INC.

3-7-6 Motoyokoyama-cho Hachioji Tokyo 192 Japan 81-426-26-0611 Ion shower

### **GEN RAD**

300 Baker Avenue Concord, MA 01742 USA 508-369-4400 508-369-6974 TFT electrical parametric testers

**GENERAL SIGNAL JAPAN CORP** 4-17-13 Kamitoda, Toda Saitama 335 Japan 81-484-41-1134 81-484-41-1142 6F C. Itoh Bldg. 2-5-1 Kita-Prober

### HAKUTO CO. LTD.

1-1-13 Shinjuku Shinjuku-ku Tokyo 160 Japan 81-3225-8910 81-3354-8608 Mfgr. Rep.

# HAMATECH GMBH

Talweg 8 D-7130 Muhlacker-Lomersheim Germany 49-7041-8 81-0 49-7041-8 8133 Photoprocessing

### HARADA SANGYO KAISHA LTD

Tokyo Kajio Bldg. Shinkan 1-2-1 Marunouchi, Chiyoda-ku Tokyo 100 Japan 81-3213-8391 81-3213-8399 Clean room supplies

# HIRAYAMA MFG. CORP.

2-16-16 Yushima, Bunkyo-ku 81-75-431-3410 Tokyo 113 Japan 81-3813-5572 81-3813-5576 Pure water systems

### HITACHI CHEMICAL CO. LTD. Shinjuku Mitsui Bldg. 2-1-1 Nishi-shinjuku Shinjuku-ku Tokyo 163 Japan 81-3346-3111 81-3346-2836 Polymer printing equip.

# HUGLE ELECTRONICS, INC.

81-426-26-9081 4-5-7 Iidabashi, Chiyoda-ku Tokyo 102 Japan 81-3263-6661 81-3263-6668 Electrostatic discharge control equ

### **IHARA HIGH PRESSURE FIT.**

6-17-20 Shinbashi, Minato-ku Tokyo 105 Japan 81-3434-1480 81-3434-3431 High pressure valves and fittings

## **INNOTECH CORP.**

Aoyama, Minato-ku Tokyo 107 Japan 81-3297-4400 81-3497-4425 Mfgr. Rep.

# IRIE SEISAKUSHO CO. LTD. 4-5-14 Nihonbashi Honcho, Chuo-ku

Tokyo 103 Japan 81-3241-7671 81-3241-7659 Spin drier

# JBA (J. BACHUR ASSOC.)

6280 San Ignacio Ave, Suite M San Jose CA 95119 USA 408-225-0865 408-225-0868 Mask alignment and exposure systems

### JEOL LTD.

3-1-2 Musashio, Akishima Tokyo 196 Japan 81-425-43-1111 81-425-46-3533 Electron microscope, lithography

### JAPAN HIGH TECH CO. LTD.

8-6 Shimo-Gofukumachi, Hakata-ku Fukuoka 812 Japan 81-92-281-7055 81-92-281-7056 Microscope stage

JOYO ENGINEERING LAB. CO. 1-23 Kajigaya, Miyamae-ku Kawasaki, Kanagawa 213 Japan 81-44-855-0558 81-44-854-6579 Assembly, glass scriber

### KLA/ACROTEC

12-1 Fujimi 1-chome Chiyoda-ku Tokyo 102 Japan Substrate defect inspection

KASHIYAMA IND. CO. LTD. 1-32 Koenjiminami Suginami-ku Tokyo 166 Japan 81-3314-5521 81-3314-5526 Vacuum pumps

KOKUSAI ELECTRIC CO. LTD. 2-3-13 Toranomon, Minato-ku Tokyo 105 Japan 81-3591-2261 81-3508-2178 Ultrasonic cleaner

### LIQUID CRYSTAL FLAT PANEL DISPLAYS

KOYO LINDBERG LTD. 229 Kabata-cho, Tenri Nara Prefecture 632 Japan 81-7436-4-0981 81-7436-4-0989 Clean ovens

# KUSUMOTO CHEMICALS CO.

No. 1 Kusumoto Bldg 1-11-13 Uchikanda, Chiyoda-ku Tokyo 101 Japan 81-3295-8681 81-3233-0217 Temp/humidity chamber

### LASERTEC

4-10-4 Tsunashima-higashi Kohoku-ku Yokohama Kanagawa 223 Japan 81-45-544-4111 81-45-543-7764 Laser microscope

### LEHIGHTON ELECTRONICS

PO Box 328 Lehighton, PA 18235 USA 215-377-5990 215-377-6820 Thin film resistivity, mobility mon

### LEYBOLD AG

Siemenstr. 100, PO Box 1145 D-8755 Alzenau, Germany 49-6023-39-0 49-6023-39-3690 Sputter, LPCVD equipment

### LIQUID CONCERNED

Dai 6 Chisan Bldg. 4-3-4 Nishi-Nakajima, Yodogawa-ku Osaka 532 Japan 81-6-301-0759 81-6-304-5488 Electrostatic filters

### M. SETEK CO. LTD.

Daiwa Bldg. 3-6-16 Yanaka Taito-ku Tokyo 110 Japan 81-3824-3241 81-3824-0939 Mfgr. Rep.

### **MBK MICROTEK**

Ninomiya Bldg 18-4 Sakuraoka-cho Shibuya-ku Tokyo 150 Japan 81-3770-6661 81-3770-5360 Mfgr. Rep.

### MKS JAPAN

Dai-ichi Shinkoh Bldg 4-28 Yotsuya Shinjuku-ku Tokyo 160 Japan 81-3352-5791 81-3352-5790 Vacuum gauges

### MARUBENI HYTECH CORP.

 Ima
 3-9 Moriya-cho Kanagawa-ku
 Tokyo 108-f

 in
 Yokohama, Kanagawa 221 Japan
 81-3798-61

 81-45-543-7764
 81-45-459-2462
 81-45-461-2248
 Laser repair

 Mfgr. Rep.
 Mfgr. Rep.
 81-45-461-2248
 Laser repair

# MECS CORP. 5-1 Nihonb 28 Jono, Kitaima, Bisai Chuo-ku Te Aichi 494 Japan 81-3665-36 81-586-62-4848 81-586-62-3566 Mfgr. Rep. Transfer robot

MIKASA CO. LTD. 2-8-1 Shibakouen, Minato-ku Tokyo 105 Japan 81-3433-8216 81-3433-8229 Photoprocess equip.

MINATO ELECTRONICS INC. 4105 Minamiyamada-cho Kohoku-ku Yokohama Kanagawa 223 Japan 81-45-591-5611 81-45-591-5618 Electrical tester

# MITSUBOSHI DIAMOND IND.

 14-7 Koroen, Settsu

 Osaka 566 Japan

 81-726-32-5131
 81-726-33-9361

 Substrate polisher

# MITSUI TOATSU CHEMICALS

8F Kasumigaseki Bldg 3-2-5 Kasumigaseki, Chiyoda-ku Tokyo 100 Japan 81-3592-4715 81-3592-4255 Silane decomposition equip.

### MUSASHI ENGINEERING

1-11-6 Iguchi, Mitaka Tokyo 181 Japan 81-422-33-8111 81-422-33-8177 Liquid dispensing equip.

# NEC CORP.

5-7-1 Shiba, Minato-ku Tokyo 108-01 Japan 81-3798-6116 81-3798-6153 Lagar rapair

NAGASE & CO. 5-1 Nihonbashi, Kobunecho Chuo-ku Tokyo 103 Japan 81-3665-3662 81-3665-3950 Mfgr. Rep.

# NAKAMURA PRECISION

Kujiraoka No. 1 Bldg 1-16-8 Kameido Koto-ku Tokyo 136 Japan 81-3684-2548 81-3684-2287 Mfgr. Rep.

### NANOMETRICS JAPAN

34 Shin-izumi, Narita
Chiba 286 Japan
81-476-36-1831 81-476-36-1866
Film thickness & CD measurement

### NAPSON CORP.

2-2-11 Kameido, Koto-ku Tokyo 136 Japan 81-3636-0286 81-3636-0976 Resistivity monitor

NIDEK CO. LTD. 34-14 Maehama, Hiroishi-cho Gamagori Aichi 443 Japan 81-533-67-6611 81-533-67-6650 Inspection microscopes

# LIQUID CRYSTAL FLAT PANEL DISPLAYS

### NIHON MICRONICS

6-8 2-chome Hon-machi Kichijoji, Musashino-shi 180 Japan Shinjuku-ku 81-422-21-0155 Probers

### NIKON CORP.

Fuji Bldg 3-2-3 Marunouchi Chiyoda-ku, Tokyo 100 Japan 81-3214-5311 81-3214-2836 Steppers

### NIPPON PILLAR PACKING CO.

2-11-48 Nonakaminami, Yodogawa-ku ORION MACHINERY Osaka 532 Japan 81-6305-1941 81-6305-0606 Pumps, heat exchangers

### NIPPON SEIKO

Nissei Bldg 1-6-2 Ohsaki Shinagawa-ku Tokyo 141 Japan 81-3779-7218 81-3779-7432 Projection exposure system

### NIPPON SEIKO

Nissei Bldg, 1-6-3 Ohsaki Shinagawa-ku, Tokyo 141 Japan 81-3-779-7218 81-3-779-7432 Pattern inspection system

### NIPPON TYLAN CORP.

4-29-15 Kamiogi, Suginami-ku Tokyo 167 Japan 81-3395-9141 81-3397-1015 Mass flow controller

### NISSIN ELECTRIC CO. LTD.

47 Umezu Takase-cho, Ukyo-ku Kyoto 615 Japan 81-75-922-4611 Ion shower

### NOMURA MICRO SCIENCE CO.

1697-1 Okada Nishinomae, Atsugi Kanagawa 243 Japan 81-462-28-3944 Pure water systems

# OLYMPUS OPTICAL CO. LTD.

San-Ei Bldg 1-22-2 Nishi-shinjuku 81-422-21-0141 Tokyo 163-91 Japan 81-3340-2181 81-3346-8380 Microscopes

# **OPTICAL RADIATION CORP.**

1300 Optical Drive Asusa, CA 91702 USA 818-969-3344 818-969-3681 UV exposure systems

3-35-15 Kamiikebukuro, Toshima-ku Tokyo 170 Japan 81-3576-6117 81-3576-6359 Water cooler, air conditioner

### **OTSUKA ELECTRONICS CO.**

3-26-3 Shodai-Tajika, Hirakata Osaka 573 Japan 81-720-55-8550 Optical final inspection

### OYAMA CO.

Koshiyama Bldg 1-15-2 Minamiaoyama SEMICON CREATED CORP. Minato-ku Tokyo 107 Japan 81-3403-0771 81-3403-0813 Prober

# **PHOTON DYNAMICS**

641 River Oaks Parkway San Jose, CA 95134 USA 408-433-3922 408-433-3925 TFT inspection and repair

### PLASMA SYSTEM CORP.

992 Yaho, Kunitachi 81-75-922-4615 Tokyo 186 Japan 81-425-74-2111 81-425-74-2112 Plasma etching equipment

**RKC INSTRUMENTS** 5-16-6 Kugahara, Ohta-ku 81-462-28-3506 Tokyo 146 Japan 81-3751-8111 81-3754-3316 Temperature control

### RORZE CORP.

1118 Nishichujo, Kannabe-cho Fukayasu-gun Hiroshima 720-23 Japan 81-849-67-1955 81-849-67-1956 Robot, conveyor system

### SPC ELECTRONICS

2-1-3, shibasaki, Chofu-shi Tokyo 182 Japan 81-424-81-8518 81-424-81-9696 Substrate cleaning equipment

### SAMCO INTERNATIONAL

33 Tanakamiya-cho Takeda Fushimi-ku Kyoto 612 Japan 81-75-621-7841 81-75-621-0936 Plasma CVD, RIE, ashing systems

### SANKEI CO. LTD.

2-25-7 Yushima, Bunkyo-ku 81-720-55-8557 Tokyo 113 Japan 81-3839-7354 81-3839-7359 Slicing equipment

Yamato Bldg 5-1-6 Ueno, Taito-ku Tokyo 110 Japan 81-3831-4117 81-3836-9390 Carrier transfer

# SHIMADA RIKEN KOGYO see SPC Electronics

### SHIMADZU CORP.

1 Nishinokyo-Kuwabaracho Nakagyo-ku Kyoto 604 Japan 81-75-823-1111 81-75-811-3188 Plasma CVD system

### **SHINKO CO.**

5-8-84 Minamiokajima, Taisho-ku Osaka 551 Japan 81-6552-3170 81-6552-3371 Antistatic equipment

# LIQUID CRYSTAL FLAT PANEL DISPLAYS

### SIGMA CORP.

45-2 Shimoasao, Asao-ku Kawasaki, Kanagawa 215 Japan 81-44-987-9381 Metal etch system

### SOEI TSUSHO CO.

2-7 Bakuro-machi 4-chome Chuo-ku Osaka 541 Japan 81-6-262-0710 81-6-262-0709 Mfgr. Rep.

### SONIC FELLOW CO.

3039-15 Tana, Sagamihara Kanagawa 229 Japan 81-427-63-2305 81-3597-5120 81-427-63-2300 Cleaning equipment

# SUMITOMO EATON NOVA CORP

10F Mita 43 Mori Bldg 3-13-16 Mita Minato-ku Tokyo 108 Japan 81-3452-9022 81-3452-9025 Ion implanter

### TABAI ESPEC CORP.

3-5-6 Tenjinbashi, Kita-ku Osaka 530 Japan 81-6358-4741 81-6358-5500 Curing system

### TAITEC CORP.

2693-1 Nishikata-Kamite Koshigaya, Saitama 343 Japan 81-489-88-3267 Cooling pump

### TAZMO CO. LTD.

6186 Kinoko-cho, Ibara Okayama 715 Japan 81-866-62-0923 81-866-63-1944 81-422-48-1011 Clean transfer modules

### **TEGAL JAPAN**

Tamahan Bldg 1-1 Kugenuma, Higashi 75-1 Hasunuma-cho, Itabashi-ku Fujisawa, Kanagawa 251 Japan 81-466-27-7351 81-466-22-5982 **RIE** system

# **TENCOR INSTRUMENTS JAPAN** 35-4 Ibukino Midori-ku Yokohama-shi Kanagawa 227 Japan 81-44-987-1417 81-45-985-7500 Particle and flatness testers

TOKUDA SEISAKUSHO CO. LTD 6-25-22 Sagamigaoka, Zama, Kanagawa 228 Japan 81-3783-2301 81-3783-5507 **RIE** systems

# TOKUYAMA SODA CO. 1-4-5 Nishi-shinbashi, Minato-ku Tokyo 105 Japan 81-3597-5168 **IPA** cleaning

TOKYO CATHODE LAB. 1-10-14 Itabashi, Itabashi-ku Tokyo 173 Japan 81-3962-8311 81-3962-8316 Probers, probe cards

TOKYO ELECTRON LTD. 2-3-1 Nishi-Shinjuku, Shinjuku-ku Tokyo 163 Japan 81-3340-8111 81-3340-8400 Etcher, inspection

# TOKYO OHKA KOGYO CO. LTD. 1-403 Kosugi-cho Nakahara-ku Kawasaki 211 Japan 81-489-88-8350 81-44-722-7191 Photo processing

TOKYO SEIMITSU CO. LTD. 9-7-1 Shimorenjaku, Mitaka Tokyo 181 Japan Flatness testers

TOPCON CORP. Tokyo 174Japan 81-3966-3141 81-3965-6821 Radiometer

### TORAY INDUSTRIES 1-8-1 Mihama, Urayasu Chiba 279 Japan 81-45-983-7234 81-473-50-6041 81-473-50-6070 Asher

TOTO LTD. 1-1-28 Toranomon, Minato-ku Tokyo 105 Japan 81-3595-9415 81-3595-9400 X-Y table

TOYOKO KAGAKU CO. LTD. 370 Ichinotsubo, Nakahara-ku Kawasaki, Kanagawa 211 Japan 81-44-422-0151 81-44-433-5332 Rinser dryer, clean fittings

**ULVAC CRYOGENICS, INC.** 1222-1 Yabata, Chigasaki Kanagawa 253 Japan 81-467-85-0303 81-467-85-9356 Cryopump

**ULVAC JAPAN** Hattori Bldg. 1-10-3 Kyobashi Chuo-ku Tokyo 104 Japan 81-3535-6381 81-3535-2569 Vacuum components, surface profiler

# **ULVAC PHI**

2500 Hagisono, Shigasaki-city Kanagawa 253 Japan 81-44-733-7948 81-467-85-6522 81-467-85-4411 **Evaluation** equipment

> ULVAC SERVICE CORP. 9F Hattori Bldg 1-10-3 Kyobashi Chuo-ku Tokyo 104 Japan

81-422-42-3816 81-3567-4431 81-3567-4434 Antistatic system for pure water

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